

(19) World Intellectual Property Organization
International Bureau



(43) International Publication Date
8 November 2001 (08.11.2001)

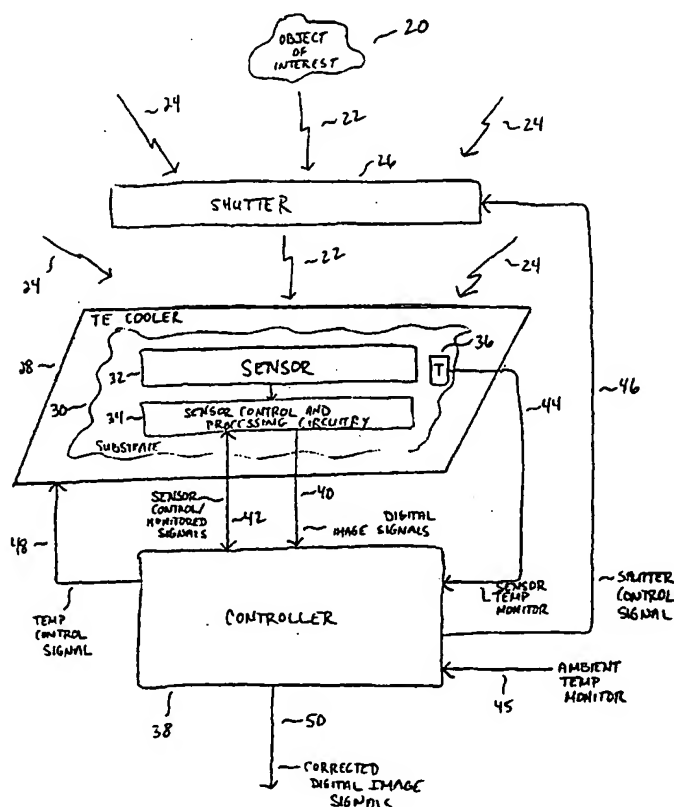
PCT

(10) International Publication Number
WO 01/84118 A2

- (51) International Patent Classification⁷: **G01N 21/00** (74) Agent: **MORRIS, James, H.**; Wolf, Greenfield & Sacks, P.C., 600 Atlantic Avenue, Boston, MA 02210 (US).
- (21) International Application Number: **PCT/US01/13612**
- (22) International Filing Date: **27 April 2001 (27.04.2001)** (81) Designated States (*national*): **IL, JP.**
- (25) Filing Language: **English** (84) Designated States (*regional*): **European patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, TR).**
- (26) Publication Language: **English**
- (30) Priority Data:
60/201,577 **1 May 2000 (01.05.2000)** **US** Published:
— *without international search report and to be republished upon receipt of that report*
- (71) Applicant: **BAE, INC.** [US/US]; Two Forbes Road, Lexington, MA 02173 (US).
- (72) Inventor: **BUTLER, Neal, R.**; 144 School Street, Acton, MA 01710 (US).

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

(54) Title: **METHODS AND APPARATUS FOR COMPENSATING A RADIATION SENSOR FOR TEMPERATURE VARIATIONS OF THE SENSOR**



(57) Abstract: In one example, the radiation sensor is a thermal sensor having at least one property that varies as a function of temperature. The thermal sensor outputs signals based on thermal radiation of interest from a particular radiating body in its view. These signals may contain significant undesirable components due in part to changes in temperature of the sensor itself. Methods and apparatus of the invention compensate the sensor for temperature variations of the sensor that are not due to the radiation of interest, so as to significantly reduce undesirable components in the instantaneous signals output by the sensor. In one example, this is accomplished without thermally stabilizing the sensor itself (i.e., dynamic temperature compensation). In another example, the sensor is thermally stabilized selectively at various predetermined temperatures as a function of the ambient temperature in the proximity of the sensor.

WO 01/84118 A2

METHODS AND APPARATUS FOR COMPENSATING A RADIATION SENSOR FOR TEMPERATURE VARIATIONS OF THE SENSOR

Cross Reference to Related Application

5 This application claims the benefit of U.S. Provisional Application Serial No. 60/201,577, filed May 1, 2000, entitled AMBIENT TEMPERATURE OPERATION OF MICROBOLOMETER FOCAL PLANE ARRAYS, which application is hereby incorporated herein by reference.

10 Background of the Invention

1. Field Of The Invention

The present invention generally relates to radiation sensors, and in particular, to compensating operating parameters and/or output signals of radiation sensors for changes in temperature of the sensors.

15

2. Discussion of the Related Art

A radiation detector is a device that produces an output signal which is a function of an amount of radiation that is incident upon an active region of the radiation detector. Radiation detectors may be designed and constructed to be sensitive to particular regions of the electromagnetic spectrum. For example, infrared detectors are radiation detectors that are sensitive to radiation in the infrared region of the electromagnetic spectrum. One example of an infrared detector includes a thermal detector, which detects radiation based upon a change in the temperature of an active region of the detector due to absorption of radiation incident to the detector.

A variety of imaging sensors may be constructed using an array of radiation detectors. Such sensors may be used in an imaging system that produces an image (e.g., on a display) based on radiation impinging on the imaging sensor. Based on the type of detectors used, the imaging sensor may be responsive to a particular region of spectrum. For example, an infrared or thermal imaging sensor may include a number of thermal detectors that detect a representation of an object by the objects' thermal emissions. In particular, energy emitted by an object may depend on numerous quantities such as, for example, the emissivity and the temperature of the object. Infrared thermal sensors typically detect one or both of these quantities and use the detected information to produce an object image that may be viewed, for example, on a display.

- 2 -

One issue in connection with at least some types of radiation detectors is that often it may be challenging to separate those signals output by the detector that are actually due to radiation of interest incident to the detector from various undesirable components which may be present in the detector output signals. For example, detector
5 output signals may include various undesirable components due to variations in temperature of the detector itself that are not necessarily due to the radiation of interest.

In particular, temperature changes in the vicinity of the detector that may affect the temperature of the detector, sometimes referred to as ambient temperature variations (e.g., changes in temperature of a substrate on which the detector is fabricated, changes
10 in temperature of a package in which the detector is housed, average temperature changes in a scene of interest itself), in turn may cause undesirable components to be present in the detector output signals. In some cases, these undesirable components may be hundreds of times larger than the instantaneous signals resulting from the radiation of interest, thereby detrimentally reducing the dynamic range of the detector and/or
15 processing circuitry associated with the detector with respect to the radiation of interest.

In view of the foregoing, some conventional imaging systems employing imaging sensors comprising a number (e.g., array) of radiation detectors require some type of temperature stabilization of the detectors to reduce such undesirable components in the detector output signals. In particular, with respect to conventional thermal imaging
20 systems, it is generally thought to be impractical to operate such systems without active stabilization of the temperature of the detectors. In some cases, thermal stabilization components may include a thermoelectric cooler (hereinafter, "TE cooler") which is thermally coupled to the detectors (e.g., the substrate on which the detectors are fabricated is mounted on the TE cooler) to hold the detectors at a predetermined
25 temperature. Depending on the difference between the predetermined stabilization temperature and the actual ambient temperature in the vicinity of the detectors, the TE cooler may consume appreciable power resources of the imaging system.

30

Summary of the Invention

- 3 -

One embodiment of the invention is directed to a method of compensating a radiation sensor for changes in at least one operational characteristic of the sensor due to a temperature variation of the sensor. The method comprises an act of dynamically adjusting at least one operating parameter associated with the radiation sensor and/or at least one calibration parameter associated with the radiation sensor based on the temperature variation of the sensor.

According to one aspect of this embodiment, the at least one operational characteristic of the sensor that changes due to the temperature variation of the sensor includes a resistance of the sensor.

According to another aspect of this embodiment, the at least one operating parameter associated with the sensor includes at least one of a DC bias voltage applied to the sensor, a DC bias current applied to the sensor, and an AC bias waveform applied to the sensor.

According to another aspect of this embodiment, the sensor includes a plurality of radiation detectors, and the at least one calibration parameter associated with the sensor includes at least one of an offset error value for each radiation detector and a gain value for each radiation detector.

According to another aspect of this embodiment, the sensor includes a plurality of radiation detectors, and the at least one operational characteristic of the sensor that changes due to the temperature variation of the sensor includes at least one of an offset error variation and a gain variation.

Another embodiment of the invention is directed to an apparatus, comprising a controller to compensate a radiation sensor for changes in at least one operational characteristic of the sensor due to a temperature variation of the sensor. The controller dynamically adjusts at least one operating parameter associated with the radiation sensor and/or at least one calibration parameter associated with the radiation sensor based on the temperature variation of the sensor.

Brief Description of the Drawings

Fig. 1 is a diagram showing a portion of an imaging system according to one embodiment of the invention;

- 4 -

Fig. 2 is a diagram showing a portion of an integrated sensor array and some associated signal processing circuitry used in the imaging system of Fig. 1, according to one embodiment of the invention;

Fig. 3 is a diagram showing a more detailed view of a portion of the sensor array
5 illustrated in Fig. 2, according to one embodiment of the invention;

Fig. 4 is a diagram showing one example of a digital-to-analog converter used in the processing circuitry shown in Figs. 2 and 3, according to one embodiment of the invention;

Fig. 5 is a diagram showing one example of a preamplifier/integrator used in the
10 processing circuitry shown in Figs. 2 and 3, according to one embodiment of the invention;

Fig. 6 is a diagram showing a more detailed view of the portion of the imaging system shown in Fig. 3, illustrating one possible implementation of various temperature compensation features, according to one embodiment of the invention;

Fig. 7 is a diagram showing examples of a current sampler/DC global offset
15 adjust circuit and a global bias adjust circuit as analog circuit implementations of the temperature compensation features shown in Fig. 6, according to one embodiment of the invention;

Fig. 8 is a diagram showing an example of a current sampler/AC global offset
20 adjust circuit as an analog circuit implementation of a sensor self-heating temperature compensation feature shown in Fig. 6, according to one embodiment of the invention;

Fig. 9 is a diagram showing a more detailed view of the portion of the imaging system shown in Fig. 3, illustrating another implementation of various temperature compensation features, according to one embodiment of the invention;

Fig. 10 is a block-diagram showing one example of a portion of a compensation
25 algorithm implemented by a controller of the imaging system of Fig. 1, according to one embodiment of the invention; and

Fig. 11 is a diagram of a portion of a controller of the imaging system of Fig. 1, showing various components of a temperature stabilization feedback loop according to
30 one embodiment of the invention.

Detailed Description

As discussed above, a radiation sensor outputs signals based on radiation that impinges on the sensor. Such a sensor may be used in an imaging system that produces images (e.g., on a display) based on radiation incident to the sensor from a scene of interest. The sensor output signals, however, may contain significant undesirable components due in part to changes in temperature of the sensor itself that are not necessarily due to the radiation of interest. In some cases, these undesirable signal components may be hundreds of times larger than the instantaneous signals resulting from the radiation of interest in the scene being imaged, thereby detrimentally reducing the dynamic range of the sensor and/or processing circuitry associated with the sensor with respect to the radiation of interest.

With respect to undesirable signal components, changes in temperature of the sensor that are not related to the radiation of interest may have an average effect over time (i.e., a DC drift in the sensor output signals). Such changes in temperature may be related to ambient temperature variations, such as a change in temperature of a substrate on which the sensor is fabricated, a change in temperature of a package in which the sensor is housed, or a change in the average temperature of the scene of interest around the sensor. Additionally, Applicants have recognized that essentially instantaneous (i.e., AC) undesirable signal components may be observed due to "self-heating" of the sensor, for example, when a bias voltage initially is applied to the sensor and current begins to flow through the sensor, producing heat. Furthermore, individual detectors of a detector array constituting an imaging sensor each may respond differently to temperature variations, creating undesirable signal components due to detector non-uniformities.

In view of the foregoing, the present invention is directed generally to methods and apparatus for compensating operating parameters and/or output signals of a radiation sensor for temperature variations of the sensor that are not due to radiation of interest. The compensation provided by various embodiments of methods and apparatus of the invention significantly reduces undesirable components in the instantaneous signals output by the sensor. In one aspect of the present invention, the radiation sensor is an infrared thermal imaging sensor including an array of thermal detectors, such as bolometers. It should be appreciated, however, that the invention is not limited in this

- 6 -

respect, as various compensation methods, apparatus, and concepts discussed herein may be applied generally to a variety of sensors and detection devices.

In one embodiment, methods and apparatus of the invention provide compensation for temperature variations of a sensor without thermally stabilizing the sensor itself; in particular, the sensor is allowed to freely vary in temperature and is dynamically compensated for temperature variations. In one aspect of this embodiment, one or more operating and/or calibration parameters associated with the sensor are dynamically determined or updated based on temperature variations of the sensor, and used to dynamically compensate for changes in operational characteristics of the sensor due to the temperature variations of the sensor. Essentially, in one aspect, the methods and apparatus of this embodiment provide continuous thermal compensation feedback without thermal stabilization of the sensor through dynamic operating and/or calibration parameter adjustments.

Some examples of operating parameters associated with the sensor that may be dynamically adjusted based on sensor temperature variations according to one embodiment of the invention include, but are not limited to, an average (i.e., DC) bias current of the sensor, a bias voltage of the sensor, and a waveform and amplitude of an AC signal used to compensate for sensor self-heating. Additionally, for imaging sensors including an array of detectors, examples of calibration parameters that may be dynamically adjusted based on sensor temperature variations include individual detector offset and response (gain) coefficients that account for differences in operating characteristics from detector to detector.

The foregoing approach of temperature compensation without thermal stabilization constitutes a significant departure from conventional thermal imaging techniques, which generally require active stabilization of sensor temperature. Thus, methods and apparatus of the invention according to one embodiment facilitate the design of a thermal imaging system that does not necessarily require thermal stabilization components (e.g., a thermoelectric cooler), thereby providing for reduced system power consumption and potential production cost savings.

In another embodiment of the present invention, thermal stabilization components are employed to thermally stabilize a radiation sensor selectively at various predetermined temperatures as a function of the ambient temperature in the proximity of

the sensor. Although thermal stabilization components are employed in this embodiment, power consumption of these components is nonetheless significantly reduced according to the invention by dynamically selecting one of several predetermined stabilization temperatures that is in the vicinity of the measured ambient temperature. In one aspect of this embodiment, various operating and calibration parameters associated with the sensor (e.g., as discussed above) initially are measured or determined at each of the different predetermined stabilization temperatures. During subsequent operation, these operating and calibration parameters are dynamically selected and utilized to compensate the sensor based on the corresponding stabilization temperature in use.

Following below are more detailed descriptions of various concepts related to, and embodiments of, methods and apparatus according to the present invention for compensating a radiation sensor for temperature variations of the sensor. It should be appreciated that various aspects of the invention, as discussed above and outlined further below, may be implemented in any of numerous ways, as the invention is not limited to any particular manner of implementation. Examples of specific implementations are provided for illustrative purposes only.

Fig. 1 is a diagram showing a portion of an imaging system according to one embodiment of the invention. Some of the basic components of the imaging system shown in Fig. 1 include a shutter 26, a sensor 32, sensor control and processing circuitry 34, and a controller 38. In one aspect of the system of Fig. 1, the sensor 32 may comprise a thermal imaging sensor that responds primarily to infrared radiation, wherein the sensor includes an array of thermal detectors, such as bolometers. At least one operational characteristic of a bolometer that may be affected by temperature variations of the bolometer itself include a resistance of the bolometer, as discussed in greater detail below.

According to yet another aspect of the imaging system shown in Fig. 1, the sensor 32 and the circuitry 34 may be monolithically integrated on a semiconductor substrate 30 along with a temperature sensor 36, which outputs a sensor temperature signal 44 corresponding to the temperature of the sensor 32. Fig. 1 also shows that in one embodiment, the substrate 30 may be thermally coupled to (e.g., mounted on) a TE cooler 28 which provides thermal stabilization for the sensor 32. It should be

- 8 -

appreciated, however, that the invention is not limited in this respect, as other embodiments of the invention discussed further below do not necessarily require the TE cooler 28.

While not shown explicitly in Fig. 1, the substrate 30 including the sensor 32 and the circuitry 34, along with the TE cooler 28, may be housed together in a vacuum package having a window that allows radiation to pass through to the sensor 32. In embodiments of the invention that do not require the TE cooler 28, the vacuum package merely may house the substrate 30 including the sensor 32 and the circuitry 34.

In the system of Fig. 1, according to one embodiment, the controller 38 monitors the sensor temperature signal 44 output by the temperature sensor 36, receives digitized signals 40 output by the circuitry 34 (which represent signals output by the sensor 32), and exchanges various other sensor control and monitor signals 42 with the circuitry 34. Additionally, according to one embodiment, the controller 38 also may monitor an ambient temperature signal 45 corresponding to an ambient temperature outside the package housing the sensor 32. In various embodiments of the invention employing the TE cooler 28, the controller 38 also may output a temperature control signal 48 to the TE cooler 28 in response to one or more of the sensor temperature signal 44, the ambient temperature signal 45, or a sensor temperature as calculated based on an average value of the digitized output signals 40. Finally, as shown in Fig. 1, the controller 38 outputs a shutter control signal 46 to control the operation of the shutter 26, as discussed further below.

With respect to various functions of the controller 38, as well as other components of imaging systems according to various embodiments of the invention, it should be appreciated that the invention is not limited to any particular manner of implementation. For example, methods and apparatus for compensating a radiation sensor for temperature variations of the sensor as discussed herein may be implemented in hardware, software, or various combinations thereof. In particular, the controller 38 may include dedicated hardware to perform various functions and/or may include one or more processors programmed using microcode or software to execute various algorithms to perform various functions discussed herein. In this respect, it should be appreciated that the controller 38 also may include a variety of digital logic circuits and memory or storage circuits or devices, including volatile, programmable, and permanent memory

- 9 -

circuits or devices (e.g., RAM, ROM, EPROM, EEPROM). Such components are not necessarily explicitly indicated in each of the figures showing the controller 38.

As illustrated in Fig. 1, an object of interest 20 in a scene to be imaged emanates radiation 22. The radiation 22 constitutes the radiation of interest from which an image of the object of interest 20 is generated by the imaging system. Fig. 1 also illustrates background radiation 24, which may be related to an average temperature of the scene to be imaged, and in some cases also may be related to the ambient temperature in the vicinity of the package housing the sensor 32. For thermal imaging systems in particular, at a given temperature of the sensor 32, this background radiation 24 may contribute to an average (i.e., DC) component of signals from the sensor 32, and hence may be compensated for (e.g., subtracted out of the signals) by the imaging system. Accordingly, it should be appreciated that the instantaneous signals of interest output by the sensor 32 typically may be considered as essentially time-varying (i.e., essentially AC components) with respect to an average DC signal component. More specifically, in thermal imaging systems, the signals of interest output by the sensor 32 correspond to the radiation 22 from one or more objects having a temperature different than that of the average scene temperature.

Fig. 2 is a diagram showing a portion of an integrated sensor including an array of detectors and some associated signal processing circuitry used in the imaging system of Fig. 1, according to one embodiment of the invention. In particular, Fig. 2 illustrates a portion of the sensor 32, showing a four-by-four array of detector unit cells arranged in rows and columns. In Fig. 2, a first column 56 of detector unit cells is particularly identified, including four detector unit cells 56A, 56B, 56C, and 56D. According to one embodiment, each row of the sensor 32 may be selected by a corresponding row select signal 52, and each column of unit cells is associated with a common column bus 54, on which each of the unit cells of the column outputs a signal.

From Fig. 2, it may be appreciated that for each row of the sensor 32 that is selected via the row select signals 52, each column bus 54 carries one signal corresponding to a respective detector unit cell of the selected row. In particular, according to one embodiment of the invention, each row of the sensor 32 is sequentially selected (e.g., the row select signals may be derived from control signals output by the controller 38 shown in Fig. 1), and the respective detector unit cells of the selected row

- 10 -

output a signal on a corresponding column bus 54. Additionally, the column busses 54 may be "enabled" or activated with a particular timing to pass the output signals from the selected row of unit cells onto the processing circuitry 34 (e.g., again via control signals output by the controller 38). In this manner, rows of detector unit cells may be scanned
5 in a manner similar to that of a television video signal (i.e., a raster scan). For simplicity, various row select and column bus enable circuitry is not illustrated in Fig. 2, and it should be appreciated that such circuitry may be implemented in a variety of manners.

Fig. 2 also shows a portion of the sensor control and processing circuitry 34 that is integrated with the sensor 32. In particular, Fig. 2 shows that each column bus 54 of
10 the sensor 32 is coupled to a preamplifier/integrator 58 (labeled in Fig. 2 as "PA"). Each of the PAs 58 also receives as an input a global detector bias 62, which provides a common DC bias voltage for all of the detector unit cells of the sensor 32, as discussed further below. Additionally, Fig. 2 shows that the PAs 58 are each coupled to a common
15 supply voltage 70 (labeled in Fig. 2 as " V_R "), which provides a common source of current for the PAs 58 to drive respective selected detector unit cells of the sensor 32. The instantaneous current drawn from the voltage V_R by a given preamplifier/integrator 58 and supplied to a selected detector unit cell when a scene is actively being viewed preferably constitutes the instantaneous signal of interest from the selected detector, as also discussed further below.

20 In Fig. 2, each column bus 54 of the sensor 32 is also coupled to a digital-to-analog converter 60 (labeled in Fig. 2 as "DAC") included in the sensor control and processing circuitry 34. Each DAC 60 is in turn coupled to a common or "global" offset 66. The global offset 66 may be a voltage or current applied to all of the DACs 60 to ultimately provide a bias current to each selected detector unit cell via the column busses
25 54. As discussed further below in connection with Figs. 3 and 4, each DAC 60 is controlled by the controller 38 to provide a coarse offset adjustment to the bias current supplied to each selected detector unit cell, to compensate for detector non-uniformities (i.e., non-uniform responses from detector to detector).

Additionally, Fig. 2 shows that the output of each PA 58 is coupled to an analog-
30 to-digital converter 62 (labeled in Fig. 2 as "A/D"), which converts the analog signal output by each PA to a digital signal 40. At least one example of an analog-to-digital converter implementation for the A/Ds 62 suitable for purposes of the present invention

- 11 -

is provided in U.S. Patent No. 6,225,937, issued May 1, 2001, and entitled "METASTABILITY RESOLVED MONOLITHIC ANALOG-TO-DIGITAL CONVERTER," which patent is hereby incorporated herein by reference. It should be appreciated, however, that the present invention is not limited to the analog-to-digital converter implementations discussed in this patent, as other implementations are possible.

While not explicitly shown in Fig. 2 (again for purposes of simplicity), the A/Ds 62 are sequentially enabled via control signals output by the controller 38 shown in Fig. 1, so that each digital signal may be individually output from a corresponding A/D as the signal 40, and thereafter individually processed and/or stored in memory by the controller 38. Accordingly, it should be appreciated that each row of the sensor is sequentially enabled to obtain a set of "parallel" signals corresponding to the unit cells of the selected row, these signals are converted by the A/Ds 62 to a set of parallel digital signals, and then each signal from the set of digital signals is sequentially passed onto the controller 38 for individual processing and/or storage.

Fig. 3 is a diagram showing a more detailed view of a portion of the sensor 32 illustrated in Fig. 2, according to one embodiment of the invention. In particular, Fig. 3 shows in greater detail the four unit cells 56A, 56B, 56C, and 56D of the column 56 of the sensor 32. Fig. 3 also shows the PA 58, the DAC 60 and the A/D 62 associated with the column 56. As can be seen in Fig. 3, according to one embodiment of the invention, each detector unit cell includes two transistors each having a gate coupled to the same row select bus. Each unit cell also includes a detector, illustrated symbolically as the resistors 72A, 72B, 72C, and 72D respectively in the unit cells 56A, 56B, 56C, and 56D. Upon the activation of a row select signal for a particular row, one transistor of the unit cell connects one terminal of the detector to a detector common 68 (e.g., a ground potential), and the other transistor of the unit cell connects the other terminal of the detector to the column bus 54. Fig. 3 also illustrates that the controller 38 includes a coarse offset map 77 that provides the DAC 60 for the column 56 with coarse offset digital values 75 for each of the unit cells of the column 56. The coarse offset digital values 75 control the DAC 60 to adjust the global bias current provided by the global offset 66, so as to compensate for detector non-uniformities, as discussed further below.

- 12 -

Fig. 4 is a diagram showing one example of the DACs 60 used in the sensor processing circuitry 34 shown in Figs. 2 and 3, according to one embodiment of the invention. Other examples of digital-to-analog converter implementations for the DACs 60 suitable for purposes of the present invention are provided in U.S. patent application
5 Serial No. 08/981,109, filed December 17, 1997, and entitled "DIGITAL OFFSET CORRECTOR," which application is hereby incorporated herein by reference. It should be appreciated, however, that the present invention is not limited to the examples of DACs discussed in this application, nor to the exemplary DAC illustrated in Fig. 4, as other implementations are possible.

10 Essentially, the DAC 60 shown in Fig. 4 is used to incrementally adjust the value of a bias resistor coupled between a column bus 54 and the global offset 66, so as to adjust a DC bias current provided to each of the detectors of the sensor 32. In Fig. 4, this bias resistor is shown schematically in five parts for purposes of illustration, as the resistors 55A, 55B, 55C, 55D, and 55E. Different parts of the bias resistor are
15 selectively "bypassed" to change the overall bias resistance by activating one or more of bypass transistors 57A, 57B, 57C, and 57D via a corresponding one of the input bits of the coarse offset digital values 75. For each detector of the sensor 32, the controller 38 stores a coarse offset digital value in a coarse offset map 77 (e.g., shown in Fig. 3). This offset value corresponds to an adjustment to the bias resistance that is required for the
20 particular detector so as to compensate for inherent non-uniformities amongst the detectors, as discussed further below.

Fig. 5 is a diagram showing one example of the PAs 58 used in the processing circuitry 34 shown in Figs. 2 and 3, according to one embodiment of the invention. Other examples of preamplifier/integrator implementations for the PAs 58 suitable for purposes
25 of the present invention are provided in U.S. patent application Serial No. 09/011,942, filed February 20, 1998, and entitled "BOLOMETRIC FOCAL PLANE ARRAY," and U.S. patent application Serial No. 09/051,180, filed April 3, 1998, and entitled "UNCOOLED FOCAL PLANE ARRAY SENSOR," which applications are hereby incorporated herein by reference. It should be appreciated, however, that the present
30 invention is not limited to the examples of PAs discussed in these applications, nor to the exemplary PA illustrated in Fig. 5, as other implementations are possible.

- 13 -

According to one embodiment, as can be seen from the exemplary circuit of Fig. 5, the column bus 54 is actually biased at one V_{be} (i.e., approximately 0.7 Volts) above the global detector bias 64, due to the base-emitter junction of the preamp transistor. Fig. 5 also illustrates that the supply voltage 70 (V_R) supplies current to the column bus 54 via the pass transistor, and the output capacitor is charged to a voltage representing this current, which voltage is ultimately provided as the signal 74 to the A/D 62.

With reference again to Figs. 2 and 3, according to one embodiment of the invention, the individual detectors of the sensor 32 may be thermal detectors that detect primarily infrared radiation. Generally, a thermal detector detects radiation based upon a change in the temperature of an active region of the detector due to absorption of radiation of interest incident to the detector. Some examples of thermal detectors include, but are not limited to, pyroelectric devices, thermocouples, diode-based devices, and resistive devices; such as bolometers.

In particular, according to one embodiment of the invention, the detectors of the unit cells of the sensor 32 (e.g., the detectors 72A, 72B, 72C, and 72C of the unit cells 56A, 56B, 56C, and 56D shown in Fig. 3) may be bolometers, wherein each bolometer includes an infrared energy receiving surface that is made of a material having a resistivity that changes as its temperature changes, in response to the infrared energy impinging on and being absorbed by the material. Thus, as the bolometer absorbs radiation, both its temperature and electrical resistance change.

A measure of radiation absorbed by a bolometer can be made by measuring changes in its electrical resistance. For example, by placing the bolometer in series with a voltage supply (i.e., D.C. coupling the bolometer), the current in the bolometer varies in accordance with the amount of infrared energy incident to the bolometer. Accordingly, as shown in Fig. 3, a preamplifier / integrator (PA) 58 is connected to a voltage supply 70 (V_R) to provide current to a particular selected bolometer, and is serially connected to the bolometer so as to produce an output signal 74 representative of the incident infrared energy. As discussed above, the sensor 32 including an array of such bolometers produces a plurality of output signals that are ultimately fed to the controller 38, which processes the signals to provide an electronic image of the source of the infrared energy.

- 14 -

One significant issue related to bolometers is that various operational characteristics of bolometers (in addition to the sensitivity of its active area to incident radiation and corresponding changes in bolometer resistance due to the incident radiation of interest) are functions of the temperature of the bolometer itself. As a result, in some cases it may be challenging to separate signals of interest due to incident radiation from undesirable signal components due to temperature variations of the bolometer itself.

Preliminarily, it should be appreciated that gradual or steady state changes in temperature of the bolometer itself (e.g., due to changes in temperature in the vicinity of the bolometer) alter the steady state resistance of the bolometer; hence, one operational characteristic of the bolometer that changes as a function of bolometer temperature variations is its resistance. Such changes in steady state resistance due to bolometer temperature variations may be significantly larger (e.g., up to hundreds of times larger) than instantaneous changes in bolometer resistance due to incident radiation of interest. As a result, the effect of bolometer steady state temperature variations may significantly degrade the dynamic range and signal-to-noise ratio of bolometer output signals with respect to the radiation of interest.

Accordingly, as discussed above, imaging systems employing thermal sensors including bolometers typically require some type of thermal stabilization mechanism, as illustrated for example by the TE cooler 28 shown in Fig. 1. Such thermal stabilization mechanisms generally are employed to maintain the sensor at a predetermined temperature in an effort to minimize any changes in steady state resistance due to steady state changes in bolometer temperature. With reference again for the moment to Fig. 3, once the bolometer array sensor is thermally stabilized, the bolometers may be appropriately biased such that average output signals from the bolometers, once amplified by the PA 58, fall approximately in the middle of the available range of the A/D 62. This type of biasing generally affords the maximum dynamic range for bolometer output signals corresponding to radiation of interest within the performance limitations of the PA 58 and the A/D 62.

However, as discussed further below, Applicants have recognized that, as an alternative to thermal stabilization (or in addition to some degree of thermal stabilization) of bolometer array sensors, various operating and/or calibration parameters of the bolometers may be varied to compensate for steady state resistance changes

- 15 -

resulting from temperature variations of the bolometer. Accordingly, one embodiment of the present invention is directed to methods and apparatus for compensating operating parameters and/or output signals of a radiation sensor including an array of bolometers for temperature variations of the bolometers that are not due to radiation of interest, without necessarily employing thermal stabilization techniques for the sensor (e.g., without using a TE cooler). In one aspect, the methods and apparatus of this embodiment allow the temperature of the sensor to freely vary, and provide continuous thermal compensation feedback through dynamic adjustments to various operating and calibration parameters associated with the sensor. For purposes of this disclosure, “operating parameters” associated with a sensor generally refer to signals applied to the sensor during normal operation of the sensor to bias the sensor, while “calibration parameters” associated with a sensor generally refer to various parameters that may be used for processing output signals from the sensor to adjust for non-uniformities amongst individual radiation detectors of the sensor. Of course, it should be appreciated that the various compensation concepts discussed herein relating to sensors including bolometers may be applied more generally to sensors employing other types of radiation detectors as well.

More specifically, Applicants have appreciated that by varying one or both of the bolometer DC bias current and DC bias voltage in response to bolometer temperature variations so as to compensate for changes in steady state resistance, a suitable dynamic range and signal-to-noise ratio of bolometer output signals may be maintained. Additionally, Applicants have appreciated that by varying both of the bolometer bias current and bias voltage in a complementary manner, an essentially constant bias power may be maintained. By maintaining an essentially constant bias power, changes in the bolometer bias voltage or current themselves do not significantly contribute to or exacerbate changes in the bolometer temperature.

In addition to changes in steady state resistance due to steady state or gradual changes in bolometer temperature, Applicant's have also identified a bolometer “self-heating” effect that may change bolometer temperature locally on a relatively instantaneous time scale, irrespective of whether or not thermal stabilization techniques are employed to stabilize the steady state temperature of the sensor. This self-heating effect also may contribute to undesirable components in output signals from the

- 16 -

bolometer. In particular, Applicant's have recognized that when a bias voltage or current initially is applied to the bolometer (e.g., when a particular row is selected and the column busses are enabled in Fig. 2), current begins to flow through the bolometer, producing heat. This local heat produced by the bolometer itself in turn changes the resistance of the bolometer, independently of the radiation of interest incident to the bolometer.

In one aspect of the bolometer self-heating effect, the initial flow of current through one bolometer as the bolometer is enabled, followed by the bolometer being disabled and another bolometer being enabled (e.g., according to the scanning process discussed above in connection with Fig. 2), may be approximated by a saw tooth waveform. Accordingly, the bolometer self-heating effect may be thought of as contributing an undesirable time-varying (i.e., AC) waveform component to the bolometer output signals. The magnitude (amplitude) of this undesirable waveform component also may be a function of the steady state bolometer temperature. In view of the foregoing, Applicant's have recognized that by applying a time-varying waveform that is essentially the inverse of the undesirable "self-heating" waveform to one of the bolometer bias current or bias voltage, the self-heating effect can be significantly reduced. According to one embodiment of the invention, the amplitude of such a time-varying compensation waveform is dynamically adjusted as an operating parameter based on variations in the steady state temperature of the bolometer array.

Other examples of operational characteristics of a sensor including an array of bolometers that may change as a function of temperature variations of the sensor relate to non-uniformities amongst the bolometers. For example, the nominal resistance of one bolometer compared to another at a given array temperature may be different (assuming both bolometers receive the same incident radiation, or view a "control" or "reference source"). Given an array of such bolometers, each bolometer may have a different nominal resistance at a given array temperature and viewing a given reference source. This variation in nominal resistance from bolometer to bolometer, with reference to an average nominal resistance of all of the bolometers, is referred to for purposes of this disclosure as an "offset error." Accordingly, each bolometer may be associated with a particular resistance value that reflects that bolometer's offset error. It should be appreciated, however, that this resistance value may be converted to any convenient unit

of measure. For example, since the A/D 62 shown in the figures outputs digital voltage values, for purposes of the following discussion the offset error of each bolometer may be treated as a differential voltage V_{off} corresponding to the offset resistance value. A set of offset error values (e.g., voltages V_{off}) for an array of bolometers that are used as calibration parameters to adjust output signals of an array relative to each other is referred to herein as an "offset map."

Viewing the same reference source, the offset error of each bolometer in an array may change as the temperature of the array varies. Additionally, the change in offset error due to a change in array temperature may be different from bolometer to bolometer. Accordingly, one operational characteristic of a sensor including a bolometer array that may change as a function of temperature is referred to herein as "offset error variation." Again, an offset error variation for each bolometer may be thought of as a change in the offset resistance value of the bolometer due to a change in array temperature, and may be expressed for purposes of the following discussion as a temperature coefficient of resistance (TCR) function dV_{off}/dT_s (or $\Delta V_{\text{off}}/\Delta T_s$), where V_{off} represents the offset resistance and T_s indicates the sensor temperature (i.e., the temperature of the bolometer array).

It should be appreciated that the TCR of the bolometers is not necessarily a linear function of sensor temperature over a wide range of temperatures. However, according to various embodiments of the invention, either a nonlinear function for dV_{off}/dT_s , or suitable linear or piece-wise linear approximations for TCR within a particular range of temperatures ($\Delta V_{\text{off}}/\Delta T_s$), may be derived and employed to compensate for offset error variation. For example, according to one embodiment, one TCR value is derived for each bolometer over an anticipated operating temperature range, wherein an essentially linear TCR dependence on temperature is assumed over this temperature range. A set of such TCR values for the bolometer array (i.e., a "TCR map") subsequently is used to dynamically adjust the corresponding offset error calibration parameters of the respective bolometers, as maintained in an offset map. In other embodiments, nonlinear TCR functions, or interpolation of piece-wise linear approximations for TCR over multiple temperature ranges, may be similarly used to dynamically adjust the offset error calibration parameters stored in the offset map.

- 18 -

Yet another operating characteristic of a sensor including a bolometer array that may change as a function of temperature relates to a response or "gain" of each bolometer in the array. For example, the response to radiation of interest of one bolometer compared to another bolometer at a given array temperature (referred to hereafter as a "calibration temperature") may be different. This variation in response from bolometer to bolometer at a given calibration temperature is referred to for purposes of this disclosure as "gain error." Since a bolometer essentially measures the temperature of an object of interest relative to an average temperature of the scene being imaged, the gain of a bolometer may be expressed as $(\Delta V_{bol}/\Delta T_{obj})_{T_{cal}}$, where V_{bol} indicates the output digital voltage from an A/D 62 representing a signal of interest from a selected bolometer, T_{obj} indicates the temperature of the object of interest in the scene that emits radiation incident to the bolometer, and T_{cal} indicates the calibration temperature at which the bolometer array is held to measure the gain. Accordingly, each bolometer may be associated with a particular gain value, and a set of gain values for a sensor including an array of bolometers at a particular calibration temperature is referred to herein as a "gain map." The gain values of the gain map are used as calibration parameters, in a manner similar to that of the offset error values of the offset map discussed above, to adjust output signals of an array relative to each other.

Similar to offset errors, the gain or response of each bolometer in an array may change as the temperature of the array varies (e.g., from the calibration temperature). Additionally, the change in bolometer gain due to a change in array temperature may be different from bolometer to bolometer. Accordingly, another operational characteristic of a bolometer array that may change as a function of temperature is referred to herein as "gain variation." Again, gain variation for each bolometer may be thought of as a change in the gain value of the bolometer due to a change in array temperature, and may be expressed for purposes of the following discussion as a "gain variation function."

As with the TCR discussed above, it should be appreciated that the gain variation function of the bolometers is not necessarily a linear function of sensor temperature over a wide temperature range; hence, according to various embodiments, a nonlinear function, or suitable linear or piece-wise linear approximations for the gain variation function over a particular range of temperatures, may be derived and employed to compensate for gain variation. For example, according to one embodiment, a single gain

- 19 -

adjustment factor that multiplies the gain value of a bolometer based on a difference between a measured sensor temperature and the calibration temperature at which the gain values for the array were originally obtained is derived for each bolometer over an anticipated operating temperature range (i.e., a linear dependence of gain variation on temperature is assumed over this temperature range). A set of such gain adjustment factors for the bolometer array (i.e., a "gain adjust map") subsequently is used to dynamically adjust the gain values (gain calibration parameters) stored in the gain map. In other embodiments, nonlinear gain variation functions, or interpolation of piece-wise linear approximations for gain variation functions, may be similarly used to dynamically adjust the gain calibration parameters stored in the gain map.

In sum, Applicants have identified a number of operating and calibration parameters associated with a sensor including a bolometer array that may be dynamically adjusted as a function of sensor temperature, so as to compensate for changes in operational characteristics of the individual bolometers of the sensor due to temperature variations of the sensor. As outlined immediately above, these parameters may include, but are not necessarily limited to, a DC bias voltage, a DC bias current, and an AC self-heating compensation waveform applied to the bolometers (operating parameters), as well as individual entries of an offset map and a gain map that correct for non-uniformities amongst the bolometers (calibration parameters).

According to various embodiments of the invention, the operating parameters discussed above (i.e., DC bias voltage, DC bias current, and AC self-heating compensation waveform) are "globally" applied to all of the individual bolometers of the sensor, and one or more of these operating parameters may be dynamically adjusted in response to temperature variations of the sensor via analog or digital feedback loop implementations. Additionally, according to various embodiments of the invention, the calibration parameters of one or both of the offset and gain maps discussed above, either alone or in combination with one or more of the operating parameters, may be dynamically adjusted based on temperature variations of the sensor on a bolometer by bolometer basis, using nonlinear offset and gain variation functions, interpolations of piece-wise linear approximations of offset and gain variation, or linear approximations of offset and gain variation. The foregoing concepts are discussed in turn in greater detail below, in connection with Figs. 6-10.

- 20 -

Fig. 6 is a diagram showing a more detailed view of the portion of the imaging system shown in Fig. 3, illustrating one possible implementation of various temperature compensation features, according to one embodiment of the invention. In particular, Fig. 6 demonstrates some basic elements of one example of a primarily analog circuit implementation for dynamic control of various operating parameters associated with a sensor. Of course, it should be appreciated that the invention is not limited to the implementation outlined in Fig. 6, as other implementations are possible, as discussed further below.

In Fig. 6, a generic selected or enabled detector of the sensor 32 (e.g., see Figs. 2 and 3) is shown for purposes of illustration as the resistor 72 coupled to the detector common 68. As discussed above in connection with Figs. 2 and 3, each enabled detector of a selected row is coupled to a corresponding DAC 60 and PA 58 via the column bus 54. Accordingly, Fig. 6 shows the DAC 60 and the PA 58 coupled to the generic detector 72 via the column bus 54. Also as in Figs. 2 and 3, Fig. 6 shows that the DAC 60 receives a global offset 66, and the PA 58 receives a global detector bias 64 and a reference supply voltage V_R 70. Fig 6 also illustrates the A/D 62 and the controller 38, which process digital signals representing signals output by the detector 72 on the column bus 54.

As discussed above in connection with Figs. 2 and 3, according to one embodiment of the invention, the global offset 66, the global detector bias 64, and the voltage V_R 70 are applied similarly to each DAC 60 and each PA 58 associated with the sensor, such that these signals essentially are "common" to all detectors of the array. Hence, although Fig. 6 shows only one DAC and one PA, it should be appreciated that the global offset 66, the global detector bias 64, the voltage V_R 70 may be simultaneously applied to multiple DACs and PAs associated with the sensor.

As illustrated in Fig. 6, the global offset 66, via the DAC 60, determines a bias current I_{BIAS} 81 through the detector 72, while the supply voltage V_R 70 provides a power source to the PA 58 to allow a signal current I_{sig} 83 to flow through the detector 72 in response to radiation of interest incident to the detector. The total current through the detector 72 is indicated in Fig. 6 as I_D . The global detector bias 64 provides a bias voltage for the detector 72 via the PA 58; essentially, as discussed above in connection

with Fig. 5, the PA 58 maintains the column bus 54 at a potential approximately 0.7 Volts above the global detector bias 64.

In general, as discussed above, the bias current and the bias voltage for the detector 72 are selected such that average output signals from the detector, once
5 amplified by the PA 58, fall approximately in the middle of the available range of the A/D 62. This type of biasing generally affords the maximum dynamic range for detector output signals corresponding to radiation of interest within the performance limitations of the PA 58 and the A/D 62. In some cases, the bias current I_{BIAS} 81 required to
10 accomplish this may be significantly greater than the typical signal current I_{sig} 83 expected from the detector. For example, in some cases it may result that I_{BIAS} constitutes as much as approximately 99% of the current I_D through the detector, while I_{sig} constitutes merely approximately 1% of the current I_D . It should be appreciated, however, that these exemplary values are provided for purposes of illustration only, and that the invention is not limited in this respect.

15 Fig. 6 also shows various circuitry coupled to the global offset 66, the global detector bias 64, and the supply voltage 70 that is used in a feedback loop configuration to dynamically adjust one or both of the global offset 66 (and hence the detector bias current I_{BIAS} 81) and the global detector bias 64 based on temperature variations of the detector 72. In particular, Fig. 6 shows a current sampler 82A which measures the
20 current being drawn by the PA 58 from the supply voltage V_R 70 to provide the signal current I_{sig} 83 to the detectors of the sensor. As shown in Fig. 6, the current sampler 82A is inserted between a voltage source V_S and a supply voltage terminal of the PA that receives the supply voltage V_R 70. Essentially, the current sampler 82A provides a measure of an instantaneous signal current being drawn by enabled detectors of the
25 sensor; recall that, according to one embodiment, the supply voltage V_R 70 is applied to all of the PAs 58 (e.g., the supply voltage terminals to each of the PAs are tied together), and each PA in turn provides signal current to a corresponding enabled detector of a selected row. Thus, at any given time, the current sampler in this embodiment provides an indication of the total instantaneous signal current being drawn by a selected row of
30 detectors.

Averaged over time, the current measured by the current sampler 82A shown in Fig. 6 may provide an indication of temperature variations of the detector 72 not due to

- 22 -

the radiation of interest. In particular, as discussed above in connection with bolometers, changes in bolometer temperature affect the resistance of the bolometer, which in turn affects the signal current 83 being drawn by the bolometer. Hence, according to one embodiment, an output 87 of the current sampler 82A may be used as an input (or "error signal") to a feedback control loop as an indication of temperature variations of the detector 72.

As illustrated in Fig. 6, the output 87 of the current sampler 82A is coupled to a DC global offset adjust controller 78A and an AC global offset adjust controller 76A. According to one embodiment, the DC global offset adjust controller 78A dynamically varies a DC component of the global offset 66 (and hence a DC component of the detector bias current I_{BIAS} 81) in response to temperature variations of the detector 72, as reflected in the output 87 of the current sampler 82A. Similarly, according to one embodiment, the AC global offset adjust controller 76A dynamically varies an AC component of the global offset 66 (and hence an AC component of the detector bias current I_{BIAS} 81) in response to instantaneous temperature variations of the detector 72 that are not related to radiation of interest incident on the detector, as reflected in the output 87 of the current sampler 82A.

In particular, according to one embodiment, the AC global offset adjust controller 76A of Fig. 6 provides a dynamically adjusted time-varying waveform that compensates for self-heating effects of the detector 72. More specifically, as discussed above and in greater detail below in connection with Fig. 8, as a bias is initially applied to an enabled detector, the output 87 of the current sampler 82A indicates an instantaneous current component related to the initial flow of current through the detector, which begins to produce local heat. In response, the AC global offset adjust controller 76A provides an AC component to the detector bias current I_{BIAS} 81 (e.g., a saw tooth or other time-varying waveform) to compensate for this effect. As illustrated in Fig. 6, according to one embodiment, an output 83 of the AC global offset adjust controller 76A is summed with an output 85 of the DC global offset adjust controller 78A at a summing node 84 to provide the global offset 66.

Fig. 6 also shows that the output 85 of the DC global offset adjust controller 78A is coupled to a global bias adjust controller 80A. According to one embodiment, the global bias adjust controller 80A dynamically adjusts the global detector bias 64 (i.e., the

DC bias voltage applied to the detector 72) based on changes in the DC component of the detector bias current I_{BIAS} 81, as provided by the DC global offset adjust controller 78A. In this manner, the DC global offset adjust controller 78A and the global bias adjust controller 80A maintain an essentially constant bias power for the detector 72.

5 In the embodiment of Fig. 6, the controller 38 may provide various signals to the global bias adjust controller 80A, the DC global offset adjust controller 78A, and the AC global offset adjust controller 76A to facilitate operation of these devices. For example, the controller 38 may provide an HSYNCH signal to the AC global offset adjust controller 76A, so as to control timing of the AC compensation waveform with respect to
10 selection of consecutive rows of detectors in the sensor (e.g., similar to raster scanning, as discussed above). Likewise, the controller 38 also may provide a sample/hold (S/H) control signal to the DC global offset adjust controller 78A, so as to temporarily disable active feedback control of the global offset 66 for various calibration purposes, as discussed further below.

15 Additionally, the controller 38 may provide a bias voltage V_{BIAS} to the global bias adjust controller 80A, which is adjusted by the global bias adjust controller 80A as discussed above to provide the global detector bias 64. For example, in one embodiment, the controller may include (or be associated with) a digital-to-analog converter (not shown in Fig. 6), which receives a digital signal from the controller 38
20 corresponding to a desired bias voltage, and outputs an analog value for the voltage V_{BIAS} .

 In the embodiment of Fig. 6, the controller 38 also may monitor the output 85 of the DC global offset adjust controller 78A, which as discussed above is related to the DC component of the detector bias current I_{BIAS} 81. According to one aspect of this
25 embodiment, the controller 38 may use the output 85 as an indication of the temperature of the sensor 32, by calibrating the output 85 based on measurements of sensor temperature. Alternatively, as discussed above in connection with Fig. 1, the controller 38 may directly monitor sensor temperature by receiving as an input a sensor temperature signal 44 output by a temperature sensor located in proximity of the sensor
30 32. In some radiometry applications in which measurements of absolute temperature of objects of interest in a scene are desired, the measurement of sensor temperature provided by either the output 85 of the DC global offset adjust controller 78A or the

- 24 -

sensor temperature signal 44 may be used in radiometric calculations to provide the required level of accuracy for radiometry measurements. It should be appreciated that one or both of the output 85 and the sensor temperature signal 44 may be input to the controller 38 as analog signals and converted, for example, by an analog-to-digital converter in the controller 38 (not shown in Fig. 6) to provide digital representations of these signals.

Finally, Fig. 6 shows that the controller 38 contains a coarse offset map 77 which includes coarse offset digital values 75 that are used to control the DAC 60, so to provide adjustments to the detector bias current I_{BIAS} 81 on a detector-by-detector basis, as discussed briefly above in connection with Fig. 3. These adjustments relate to non-uniformities amongst the detectors of the sensor, and are discussed in greater detail below in connection with Fig. 10.

Fig. 7 is a diagram showing examples of analog circuit implementations for the current sampler, DC global offset adjust controller, and global bias adjust controller of Fig. 6, according to one embodiment of the invention. It should be appreciated that these examples are provided for purposes of illustration only, and that the invention is not limited to the particular circuits shown in Fig. 7. In Fig. 7, the current sampler 82A and the DC global offset adjust controller 78A are implemented in a circuit that performs both functions. In particular, resistors R9 and R10 form an adjustable voltage divider, which places a portion of the source voltage V_S on the non-inverting input of amplifier AR2. Accordingly, this voltage also appears on the inverting input of AR2. Resistor R8 hence essentially provides the current sampling function; as the average current drawn from the supply voltage V_R 70 changes due to temperature variations of the sensor, the current flowing through the resistor R8 changes. The amplifier AR2 in turn varies the output current 85 provided to the summing node 84 shown in Fig. 6 based on the changes in current through R8. Transistor Q5 is controlled by the S/H control signal from the controller 38; when the transistor Q5 is "disabled," the resistor R8 is disconnected from the amplifier AR2, and the capacitor C8 serves as a hold capacitor. When the transistor Q5 is "enabled", resistor R8 and capacitor C8 determine the response time of the DC global offset adjust feedback loop; according to one embodiment, values for these components are selected such that the response time of the loop is several image frames (e.g., several scans of the sensor) so as to reduce image artifacts. Capacitor C7 provides

- 25 -

a low impedance to AC signal components in the average current drawn from the supply voltage V_R 70, so that these components do not significantly affect the DC global offset adjust feedback loop.

In Fig. 7, the global bias adjust controller 80A is implemented by a circuit including amplifier AR3, which samples the DC current output 85. The resistors R11, R12, and R13 and the capacitors C9 and C10 provide gain and filtering of the sampled signal. In the exemplary circuit shown in Fig. 7, increases in the output current 85 (corresponding to increases in the detector bias current I_{BIAS}) cause some proportional decrease in the global detector bias 64. Hence, the circuits shown in Fig. 7 tend to act so as to keep a sum of the detector bias current and bias voltage constant, rather than keeping the product of the bias current and voltage constant (so as to maintain essentially constant detector power). However, over a relatively limited or small range of detector powers, regulating the sum rather than the product of detector bias current and voltage provides adequate control of detector power according to this embodiment.

Fig. 8 is a diagram showing an example of an analog circuit implementation for the current sampler and AC global offset adjust controller of Fig. 6, according to one embodiment of the invention. It should be appreciated that these examples are provided for purposes of illustration only, and that the invention is not limited to the particular circuit shown in Fig. 8. Similar to Fig. 7, in Fig. 8 the current sampler 82A and the AC global offset adjust controller 76A are implemented in a circuit that performs both functions. In particular, in Fig. 8, R1 is a low value (e.g., 10 Ohm) resistor, and the voltage drop across R1 is a measure of the average current drawn by bolometers of the array. Capacitor C1 is a high frequency bypass for resistor R1. A high gain AC amplifier comprising C2, Q1, Q2, R2, R3 and R4 amplify the AC (instantaneous) component of the current drawn by a row of detectors coupled to the supply voltage V_R 70. The amplified AC component is then detected by a synchronous rectifier comprising C3 and Q3. The output of the synchronous rectifier is integrated by AR1, R5, and C4. The output voltage of the integrator controls the current through resistor R6. Capacitor C6 is periodically reset to a high voltage at an appropriate time by an analog switch connected to the point labeled open_d. When the voltage at open_d is not applied, capacitor C6 discharges at a rate determined by the current through R6, thereby generating an essentially saw tooth waveform. The waveform generated by this process

- 26 -

is then provided as an output 83 via transistor Q4, and ultimately is AC coupled into the summing node 84 shown in Fig. 6. The polarity of the feedback loop represented by the circuit in Fig. 8 is selected such that the AC component of the average current drawn by the bolometers from the supply voltage V_R 70 is reduced to approximately zero during the initial bias time of the detectors, thereby compensating for the self-heating effects discussed above.

Fig. 9 is a diagram similar to Fig. 6 showing a more detailed view of the portion of the imaging system shown in Fig. 3, illustrating another possible implementation of various temperature compensation features, according to one embodiment of the invention. In particular, Fig. 9 demonstrates some basic elements of one example of a primarily digital implementation for dynamic control of various operating parameters associated with a sensor.

In the embodiment of Fig. 9, essentially the controller 38 monitors various input signals and outputs various signals so as to implement closed feedback loop control of detector bias current and bias voltage in a manner similar to that discussed above in connection with Fig. 6. In particular, it should be appreciated that the controller 38 may be programmed in a variety of manners so as to execute one or more algorithms to implement such control. In one aspect of this embodiment, the controller 38 may include a number of analog-to-digital converters (not explicitly shown in Fig. 9) to digitize one or more signals input to the controller that are not already in digital form; for example, while the signals 40 received by the controller 38 from the A/D 62 are in digital form, the controller 38 may include one or more analog-to-digital converters to convert the output 87 from the current sampler 82B or the sensor temperature signal 44 to digital form. Similarly, according to one embodiment, the AC global offset adjust controller 76B, the DC global offset adjust controller 78B and the global bias adjust controller 80B each may include a digital-to-analog converter that receives digital output signals from the controller 38 and converts these signals to an analog voltage or current.

The embodiment of Fig. 9 provides a significantly versatile solution to feedback control of the various sensor operating parameters based on temperature variations of the sensor. For example, the controller 38 may monitor the average steady state temperature of the sensor by either monitoring the sensor temperature signal 44, the output 87 of the

- 27 -

current sampler 82B, or periodically calculating an average detector output signal based on any number of the individually sampled digital detector output signals provided by the A/D 62, and monitoring any changes in this calculated signal. Any of these approaches may provide an input or "error signal" to the feedback loop. Additionally, 5 the controller may monitor instantaneous changes in the current drawn by detectors of the sensor from the supply voltage V_R 70 by sampling the output 87 of the current sampler 82B at an appropriate rate to acquire and store data related to detector self-heating.

Based on any of the foregoing sampled input signals, the controller 38 may 10 flexibly control one or more of the AC global offset adjust controller 76A, the DC global offset adjust controller 78B and the global bias adjust 80B by merely outputting a digital value to these devices corresponding to the desired control. In particular, the controller 38 may be specifically programmed such that the DC global offset adjust controller dynamically maintains an appropriate bias current for the detectors based on measured 15 temperature variations of the sensor, the global bias adjust controller 80B dynamically adjusts the global detector bias such that a product of the detector bias current and bias voltage remains essentially constant (so as to maintain an essentially constant detector power), and a timing and amplitude of a time-varying waveform generated by the AC global offset adjust controller 76B is dynamically adjusted based on the data acquired by 20 sampling the output 87 of the current sampler 82B.

Fig. 10 is a block diagram showing a more detailed view of a portion of the controller 38, illustrating one possible implementation of various temperature compensation features relating to calibration parameters associated with the sensor, according to one embodiment of the invention. In particular, Fig. 10 demonstrates some 25 basic elements of one example of a calibration parameter compensation algorithm implemented by the controller 38. Of course, it should be appreciated that the invention is not limited to the algorithmic implementation outlined in Fig. 10, as other algorithmic implementations are possible, as discussed further below.

As discussed above, a number of calibration parameters associated with a sensor 30 including a detector array may be dynamically adjusted as a function of sensor temperature, so as to compensate for changes in operational characteristics of the sensor due to temperature variations of the sensor. These calibration parameters may include,

- 28 -

but are not necessarily limited to, individual entries in an offset map and a gain map that correct for non-uniformities amongst the detectors. Some of the operational characteristics of the sensor that change due to temperature variations of the sensor relate to changes in the offset error and gain of individual detectors; these changes were referred to earlier as "offset variation" and "gain variation." According to one embodiment of the invention, such offset variation and gain variation with sensor temperature necessitate dynamic adjustments of the calibration parameters constituting the offset and gain maps when thermal stabilization of the sensor is not employed (e.g., a TE cooler is not used in the system). According to another embodiment, even if thermal stabilization of the sensor is employed, dynamic adjustments of calibration parameters also may be employed to improve accuracy and reliability of the imaging system.

In view of the foregoing, according to various embodiments of the invention, the calibration parameters contained in one or both of the offset and gain maps, either alone or in combination with one or more of the operating parameters discussed above, may be dynamically adjusted based on temperature variations of the sensor on a detector by detector basis. Such adjustments may be accomplished using nonlinear offset and gain variation functions, interpolations of piece-wise linear approximations of offset and gain variation, or linear approximations of offset and gain variation.

In particular, Fig. 10 illustrates an example of a dynamic calibration parameter adjustment algorithm based on linear approximations of offset and gain variation, according to one embodiment of the invention. In particular, according to one embodiment, an initial sensor calibration procedure is executed to obtain a number of calibration parameters related to a coarse offset error, a fine offset error, and a gain for each detector of a sensor. As illustrated in Fig. 10, these parameters are stored respectively in a coarse offset map 77, a fine offset map 108, and a gain map 104.

Additionally, during the calibration procedure, a number of adjustment values are determined that are used subsequently during normal operation to dynamically adjust at least some of the calibration parameters based on changes in sensor temperature. In particular, during the calibration procedure, according to one embodiment, a TCR (temperature coefficient of resistance) value and a gain adjustment factor is determined for each detector of a sensor as a linear approximation of offset error variation and gain

- 29 -

variation, respectively. As also illustrated in Fig. 10, these adjustment values are stored respectively in a TCR map 106 and a gain adjust map 102.

An exemplary calibration procedure to obtain the calibration parameters and determine the adjustment values discussed immediately above is executed as follows, with reference to Figs. 1, 2, 3, and 10. It should be appreciated that this exemplary procedure is provided here for purposes of illustration only, and that the invention is not limited to this particular calibration procedure. Additionally, it should be appreciated that while the calibration procedure outlined below employs two offset maps (namely, a coarse offset map and a fine offset map) to store offset error calibration parameters, the invention is not limited to employing any particular number of offset and gain maps, as numerous implementations of the various concepts discussed herein relating to dynamic adjustment of sensor calibration parameters are possible.

In one exemplary calibration procedure according to the invention, based on a particular temperature range over which it is anticipated that the sensor 32 will be operated, the sensor initially is thermally stabilized at a first temperature within this range, referred to as T_{cal} . Additionally, the shutter 26 shown in Fig. 1 may be positioned so as to essentially block radiation from a scene from impinging on the sensor 32 (i.e., the controller 38 may control the shutter control signal 46 to appropriately activate the shutter and block incident radiation). Alternatively, the sensor 32 may be aimed at a standardized radiating black body at a known temperature to provide a controlled input to the sensor 32.

Once the sensor is thermally stabilized with no input (i.e., shutter closed) or a controlled input, an initial global bias current and global bias voltage is applied to the sensor (e.g., via the global offset 66 and the global detector bias 64, common to all of the detectors), and the controller 38 begins to sequentially read digitized output values from each detector of the sensor via the A/Ds 62. Typically, many of the individual detector digitized output values initially are either significantly above or below a mid-scale value of the A/Ds 62. The variation in these outputs reflects the offset error of the individual detectors at the temperature T_{cal} . The controller 38 scans the sensor a number of times, and with each scan adjusts and applies a coarse offset digital value 75 for each detector (maintained in the coarse offset map 77) to an appropriate one of the DACs 60, so to adjust the individual detector bias current such that each detector output approximates a

- 30 -

mid-scale value of the A/Ds 62. In this manner, the controller 38 executes a coarse offset calibration, or coarse "zeroing" of the sensor on an detector-by-detector basis. The final coarse offset digital values 75 that accomplishes this coarse zeroing are stored in the coarse offset map 77. This process is referred to as "coarse" offset calibration because, according to one embodiment, the number of bits employed by the DACs 60 to make adjustments to the individual detector bias currents so as to bring the respective digitized detector output signals to approximately mid-scale of the A/Ds 62 typically is less than the number of bits used by the A/Ds 62 to digitize the amplified detector output signals.

Once the coarse offset calibration is completed, typically the individual detector signals are still not quite at a mid-scale value of the A/Ds 62. Accordingly, the controller 38 repeats the scanning process at T_{cal} to compile a fine offset map 108, as shown in Fig. 10. Essentially, the controller 38 acquires several digital output samples from each detector (corrected for coarse offset) via the A/Ds 62, averages the samples, and stores this average as a calibration parameter for each detector in the fine offset map 108. During normal operation of the sensor (i.e., after the initial calibration procedure is completed), the respective fine offset values are used to make fine adjustments to the sampled digital outputs of corresponding detectors so as to further compensate for non-uniformities amongst the detectors.

Next, while the sensor temperature is still maintained at T_{cal} , the sensor 32 is aimed at a standardized black body radiating at a first known object temperature, T_{obj1} . Again, the controller 38 scans the array, applies the coarse and fine offset calibration parameters to each detector, and records the digitized output signal of each detector at T_{obj1} . Subsequently, the sensor 32 is aimed at a standardized black body radiating at a second known object temperature T_{obj2} , and the controller 38 again scans the array, applies the coarse and fine offset parameters to each detector, and records the digitized output signal of each detector at T_{obj2} . The controller 38 then calculates the gain of each detector by dividing the difference in digitized output signals of each detector at the two object temperatures by the difference in object temperatures ΔT_{obj} , and stores this calibration parameter for the detector as an entry in the gain map 104 shown in Fig. 10. During normal operation (i.e., after the initial calibration procedure is completed), this gain value is used as a calibration parameter to make adjustments to the sampled digital

output signals of the detector so as to further compensate for non-uniformities amongst the detectors.

At this point in the exemplary calibration procedure, the temperature T_{cal} at which the sensor is initially stabilized is changed to a new temperature, T_{cal2} , so that the controller 38 may determine the adjustment factors (i.e., TCRs and gain adjustment factors) that are ultimately used as linear approximations of offset error variation and gain variation in the embodiment of Fig. 10 to compensate (e.g., dynamically adjust) the individual calibration parameters of the fine offset map 108 and the gain map 104 based on temperature variations of the sensor. It should be appreciated that offset error and gain for a given type of detector do not necessarily vary similarly with temperature variations of the sensor; for example, with respect to bolometers, offset error variation generally is significantly more sensitive than gain variation as a function of sensor temperature. Accordingly, the choice of a particular second sensor stabilization temperature T_{cal2} for the calibration procedure may depend on the degree of accuracy desired by the linear approximations of offset error variation and gain variation for a given anticipated operating temperature range of the sensor. Notwithstanding the particular choice of T_{cal2} , the determination of the various (e.g., TCR and gain) adjustment factors may be understood conceptually as follows.

At T_{cal2} , the controller 38 repeats the procedure discussed above for obtaining fine offset values (i.e., with the shutter closed or with the sensor viewing a standardized black body radiating at a known temperature) to compile a new set of fine offset values at the sensor temperature T_{cal2} . The controller then calculates the TCR value for each detector by dividing the difference in fine offset values at T_{cal} and T_{cal2} for each detector by the temperature difference between T_{cal} and T_{cal2} , and stores the TCR values for respective detectors in the TCR map 106 shown in Fig. 10. In this embodiment, as discussed above, each TCR value may be thought of conceptually in units of $\Delta V_{off}/\Delta T_s$, where ΔV_{off} represents the difference in fine offset values for a given detector, and ΔT_s indicates the variation in sensor temperature (i.e., $|T_{cal2} - T_{cal}|$).

Similarly, at T_{cal2} , the controller 38 repeats the procedure discussed above for obtaining gain values (i.e., using two standardized black bodies radiating at different known temperatures T_{obj1} and T_{obj2}) to compile a new set of gain values at the sensor temperature T_{cal2} . The controller then calculates the gain adjustment factor for each

- 32 -

detector by taking the ratio of the gain values at T_{cal} and T_{cal2} , and dividing the ratio by the temperature difference between T_{cal} and T_{cal2} . This gain adjustment factor for each detector is then stored in the gain adjust map 102 shown in Fig. 10. In this embodiment, each gain adjustment factor of the gain adjust map 102 may be thought of conceptually
5 as a gain multiplier divided by $|T_{cal2} - T_{cal}|$.

Once the controller 38 has completed building the various maps discussed above, the exemplary calibration procedure is essentially completed, and thereafter the imaging system may be operated without necessarily requiring thermal stabilization of the sensor 32, according to one embodiment of the invention. In particular, according to one aspect
10 of this embodiment, the controller 38 may dynamically update the calibration parameters of the fine offset map 108 using the corresponding TCR values of the TCR map 106, and may dynamically update the calibration parameters of the gain map 104 using the corresponding gain adjustment factors of the gain adjust map 102, by evaluating temperature variations of the sensor 32 based on a variety of criteria.

For example, according to one embodiment of the invention, the controller may periodically operate the shutter 26 via a shutter controller 98 (that outputs the shutter control signal 46) to block incident radiation to the sensor 32, at which time the controller recalculates (i.e., updates) each of the calibration parameters of the fine offset map 108 by scanning the sensor, as discussed above. In one aspect of this embodiment,
20 the periodic operation of the shutter to perform this procedure may be based on a predetermined time interval. In yet another aspect, as illustrated in Fig. 10, the operation of the shutter may be based on a difference in sensor temperature from the last operation of the shutter.

More specifically, as illustrated in the embodiment of Fig. 10, the sensor temperature signal 44 output by the temperature sensor 36 shown in Fig. 1 is digitized by
25 an analog-to-digital converter 90, and the controller 38 maintains a record 94 of the digitized sensor temperature at each shutter operation. The controller 38 also may be programmed with a predetermined threshold temperature difference value 92, which may be used to activate the shutter. In particular, in the embodiment of Fig. 10, the shutter comparator 96 compares the predetermined threshold temperature difference value 92 to
30 the difference 110 (ΔT) between the present digitized sensor temperature and the record 94 of the sensor temperature at the last shutter operation; if this difference 110 exceeds

the value 92, the shutter comparator 96 activates the shutter controller 98 so as to operate the shutter 26, at which point the controller 38 updates the fine offset map 108 by scanning the sensor as discussed above. In this manner, the fine offset map 108 is periodically updated based on sensor temperature variations.

5 Between shutter operations (i.e., between updates of the fine offset map 108 by a sensor rescan), the controller 38 may nonetheless continually adjust and update both the fine offset map 108 and the gain map based on the difference between a present sensor temperature and the sensor temperature at the previous shutter operation. For example, as illustrated in Fig. 10, the temperature difference 110 between the present sensor
10 temperature and the sensor temperature at the previous shutter operation may be used to multiply individual entries of the TCR map 106, which are then used to update the individual entries in the fine offset map 108. Similarly, a signal 112 representing the difference between the present sensor temperature and the calibration temperature 100 (i.e., T_{cal}) may be used to multiply individual entries of the gain adjust map 102, which
15 are then used to update the individual entries in the gain map 104. In this manner, the frequency of shutter operations to update the fine offset map 108 by a sensor rescan may be reduced (e.g., the predetermined threshold temperature difference value 92 may be set at a higher value).

While the embodiment discussed above in connection with Fig. 10 discusses
20 updates to a fine offset map to dynamically adjust offset error calibration parameters for offset error variation, it should be appreciated that the invention is not limited in this respect. Namely, in other embodiments, compensation algorithms for dynamic adjustment of offset error calibration parameters may perform such adjustments using the coarse offset map 77 shown in Fig. 10, or both the coarse offset map 77 and the fine
25 offset map 108. Alternatively, as discussed above, compensation algorithms for dynamic adjustment of offset error calibration parameters according to other embodiments of the invention may compile, maintain, and update a single offset map based on the general concepts discussed above.

Additionally, while the embodiment discussed above in connection with Fig. 10
30 involves linear approximations of offset error variation and gain variation to dynamically adjust the calibration parameters of the fine offset map and the gain map using a TCR map and a gain adjust map, respectively, it should be appreciated that the invention is not

- 34 -

limited in this respect. Namely, the general concepts discussed above may be employed to implement compensation algorithms according to other embodiments of the invention that use interpolation of piece-wise linear approximations of offset error variation and gain variation to compensate for these variations. Moreover, the general concepts
5 discussed above may be employed to implement compensation algorithms according to other embodiments of the invention that determine and utilize offset error variation and gain variation as nonlinear functions of sensor temperature to compensate for these variations. Furthermore, it should be appreciated that according to yet other embodiments, one of a nonlinear function, interpolation of piece-wise linear
10 approximations, or a linear approximation may be employed by a compensation algorithm to compensate for offset error variation, while a different one of a nonlinear function, interpolation of piece-wise linear approximations, or a linear approximation may be employed by the compensation algorithm to compensate for gain variation.

For example, regarding nonlinear functions for offset error variation and gain
15 variation, according to one embodiment of the invention, a significant number of offset maps and gain maps may be compiled by the controller 38 (as discussed above) at a number of different sensor calibration temperatures. Essentially, each offset map and each gain map provides a "sample" of a nonlinear function of offset error variation and gain variation, respectively. Accordingly, it should be appreciated that the greater
20 number of samples acquired (i.e., the greater number of offset and gain maps compiled by the controller 38), the more accurate the sampled representation of the functions are. While in some cases the compilation of several offset and gain maps during a calibration procedure may prove to be a memory and computation intensive process, this scheme may nonetheless provide a viable and effective alternative for precision compensation of
25 offset error variation and gain variation. During normal operation following such a calibration procedure, the particular offset and gain map that the controller 38 uses at any given time to adjust the digitized output signals of respective detectors of the sensor may be selected as a function of the present sensor temperature (e.g., as measured via the sensor temperature signal 44).

30 Alternatively, another embodiment of the invention relates to dynamic compensation of calibration parameters by interpolation of piece-wise linear approximation of offset error variation and gain variation. In this embodiment, similar to

the nonlinear function embodiment discussed immediately above, a smaller number (e.g., two to five) of offset maps or TCR maps, as well as gain maps, may be compiled by the controller 38 at a number of different sensor calibration temperatures throughout an anticipated temperature operating range for the sensor. Using a smaller number of maps or “samples” of the respective variation functions essentially creates a piece-wise linear approximation of the functions. In particular TCR maps may be compiled at different temperature sub-ranges of an overall anticipated operating range to provide interpolations of piece-wise linear approximations of offset error variation.

In this embodiment, once such maps are compiled during a calibration procedure, they may be employed during normal operation again based on a measured present sensor temperature. For example, two gain maps and two TCR maps may be selected, wherein one of each type of map was compiled at or near a calibration temperature close to but below the present sensor temperature, and the other of each type of map was compiled at a calibration temperature close to but above the present sensor temperature. The controller 38 may then calculate the difference between corresponding entries of the two gain maps and the two TCR maps, and determine an interpolated adjustment value for each of gain and offset based on the present sensor temperature and the ΔT_{cal} between the two maps of each type (ΔT_{cal} would be “weighted” by the present sensor temperature). These interpolated adjustment values may then be applied to respective entries of each of the offset map and gain map, as discussed above.

In yet another embodiment of the present invention, with reference again to Fig. 1, thermal stabilization components (e.g., the TE cooler 28) are employed to thermally stabilize the sensor 32 selectively at various predetermined temperatures as a function of the ambient temperature in the proximity of the sensor, as indicated by the ambient temperature signal 45. Although thermal stabilization components are employed in this embodiment, power consumption of these components is nonetheless significantly reduced according to the invention by dynamically selecting one of several predetermined stabilization temperatures that is in the vicinity of the measured ambient temperature.

For example, with respect to TE coolers, the power consumption of a TE cooler generally is a function approximately of the square of the temperature difference between the ambient temperature in proximity of the TE cooler and the desired (set-point)

- 36 -

temperature of the TE cooler. Accordingly, power consumption of the TE cooler may be significantly reduced if the difference between the TE cooler set point and the ambient temperature is reduced. Additionally, in Fig. 1, generally the electronic signals through the sensor itself warms the sensor to some temperature above the ambient temperature in proximity of the sensor (e.g., approximately 10 to 20 degrees Celsius above ambient).
5 According to one embodiment of the invention, the foregoing factors are taken into consideration to strategically reduce power consumption of a TE cooler thermally coupled to a sensor during operation of the sensor.

In one aspect of this embodiment, a number of sensor temperature/TE cooler set-
10 points are predetermined based on an anticipated ambient temperature operating range over which the sensor will be used. For example, according to one embodiment, the ambient temperature range over which the sensor may be used is from approximately -40 degrees Celsius to +60 degrees Celsius (i.e., an approximately 100 degree Celsius range). This temperature range is then divided into a number of sub-ranges, for
15 example, three sub-ranges of approximately 30 degrees Celsius each. Within each of these sub-ranges, a sensor temperature/TE cooler set-point is chosen that approximately minimizes the power consumption of the TE cooler over the sub-range. For example, according to one embodiment, a set-point for each sub-range is chosen by taking the center temperature within the range and adding approximately 10 degrees to it (to
20 account for electronic signal "warm-up" of the sensor).

Once the TE cooler set-points are identified (i.e., in the above example, three predetermined set-points are chosen), various operating and calibration parameters associated with the sensor initially are measured or determined during a calibration procedure (e.g., as discussed above), wherein each of the predetermined TE cooler set-
25 points serves as a different calibration temperature. For example, in the above scenario using three predetermined set-points, during a calibration procedure one offset map and one gain map would be compiled at each set-point, for a total of three offset maps and three gain maps. Additionally, at each TE cooler set-point, an optimum global offset (detector bias current), global detector bias (detector bias voltage), and self-heating
30 compensation waveform may be determined.

According to one aspect of this embodiment, during subsequent operation of the sensor after such a calibration procedure, the controller 38 continuously monitors the

- 37 -

ambient temperature, and selects one of the TE cooler set-points that will significantly reduce power consumption of the TE cooler based on the difference between the ambient temperature and the selected set-point. Fig. 11 is a diagram of a portion of the controller 38, showing various components of a temperature stabilization feedback loop according to one embodiment of the invention. In Fig. 11, a set-point select controller 152 monitors the ambient temperature signal 45, and outputs the selected set-point 150 based on the available set-points and the monitored ambient temperature. An amplifier/comparator 156 compares the selected set-point 150 to the present sensor temperature 44 to produce an error signal 158 for the temperature stabilization feedback loop. This error signal 158 is further processed by various conditioning circuitry 160 that provides loop filtering and gain and outputs the temperature control signal 48 to the TE cooler.

In Fig. 11, the set-point select controller 152 also provides the selected set-point 150 to a calibration parameter select controller 154, which then selects the appropriate offset and gain maps (shown in Fig. 11 in the map table with entries OM1, OM2, OM3, GM1, GM2, GM3, etc.) to be used by the controller 38 as calibration parameters. While not shown explicitly in Fig. 11, according to one embodiment, the calibration parameter select controller 154 also may indicate or select the appropriate operating parameters (e.g. bias current and voltage and self-heating compensation waveform) that the controller 38 applies to the sensor at respective TE cooler set-points.

In accordance with the invention, feedback temperature control may be provided in response to any combination of one or more of sensor temperature monitor 44, ambient temperature monitor 45, and a subset of or all of the digital image signals 40.

Compensation of the sensor can be provided in response to any combination of a temperature variation of the sensor, a change in the ambient temperature of the environment (but not the chip), and a change in the digital output of the sensor (but not in the chip). This compensation can be provided continuously, only when the shutter is being calibrated, or only when the shutter is not being calibrated.

Having thus described at least one illustrative embodiment of the invention, various alterations, modifications, and improvements will readily occur to those skilled in the art. Such alterations, modifications, and improvements are intended to be part of this disclosure, and are intended to be within the spirit and scope of the invention.

- 38 -

Accordingly, the foregoing description is by way of example only and is limited only as defined in the following claims and the equivalents thereto.

What is claimed is:

- 39 -

CLAIMS

1. A method of compensating a radiation sensor for changes in at least one
5 operational characteristic of the sensor due to a temperature variation of the sensor,
comprising an act of:
dynamically adjusting at least one of at least one operating parameter associated
with the radiation sensor and at least one calibration parameter associated with the
radiation sensor based on the temperature variation of the sensor.
- 10 2. The method of claim 1, wherein the at least one operational characteristic
of the sensor that changes due to the temperature variation of the sensor includes a
resistance of the sensor.
- 15 3. The method of claim 1, wherein the at least one operating parameter
associated with the sensor includes at least one of a DC bias voltage applied to the
sensor, a DC bias current applied to the sensor, and an AC bias waveform applied to the
sensor.
- 20 4. The method of claim 1, wherein the sensor includes a plurality of
radiation detectors, and wherein the at least one calibration parameter associated with the
sensor includes at least one of an offset error value for each radiation detector and a gain
value for each radiation detector.
- 25 5. The method of claim 4, wherein the at least one operational characteristic
of the sensor that changes due to the temperature variation of the sensor includes at least
one of an offset error variation and a gain variation.
- 30 6. An apparatus, comprising:
a controller to compensate a radiation sensor for changes in at least one
operational characteristic of the sensor due to a temperature variation of the sensor, the
controller dynamically adjusting at least one of at least one operating parameter

- 40 -

associated with the radiation sensor and at least one calibration parameter associated with the radiation sensor based on the temperature variation of the sensor.

7. The apparatus of claim 6, wherein the at least one operational
5 characteristic of the sensor that changes due to the temperature variation of the sensor includes a resistance of the sensor.

8. The apparatus of claim 6, wherein the at least one operating parameter
10 includes at least one of a DC bias voltage applied to the sensor, a DC bias current applied to the sensor, and an AC bias waveform applied to the sensor.

9. The apparatus of claim 6, wherein the sensor includes a plurality of
radiation detectors, and wherein the at least one calibration parameter associated with the
sensor includes at least one of an offset error value for each radiation detector and a gain
15 value for each radiation detector.

10. The apparatus of claim 9, wherein the at least one operational
characteristic of the sensor that changes due to the temperature variation of the sensor
includes at least one of an offset error variation and a gain variation.

20

11. A method of compensating a radiation sensor for changes in at least one
operational characteristic of the sensor due to a temperature variation of
the sensor, comprising:

dynamically adjusting at least one operating parameter associated with the
25 radiation sensor or at least one calibration parameter associated with the radiation sensor
based on the temperature variation of the sensor.

12. An apparatus, comprising:

a controller to compensate a radiation sensor for changes in at least one
30 operational characteristic of the sensor due to a temperature variation of the sensor, the
controller dynamically adjusting at least one operating parameter associated with the

- 41 -

radiation sensor or at least one calibration parameter associated with the radiation sensor based on the temperature variation of the sensor.

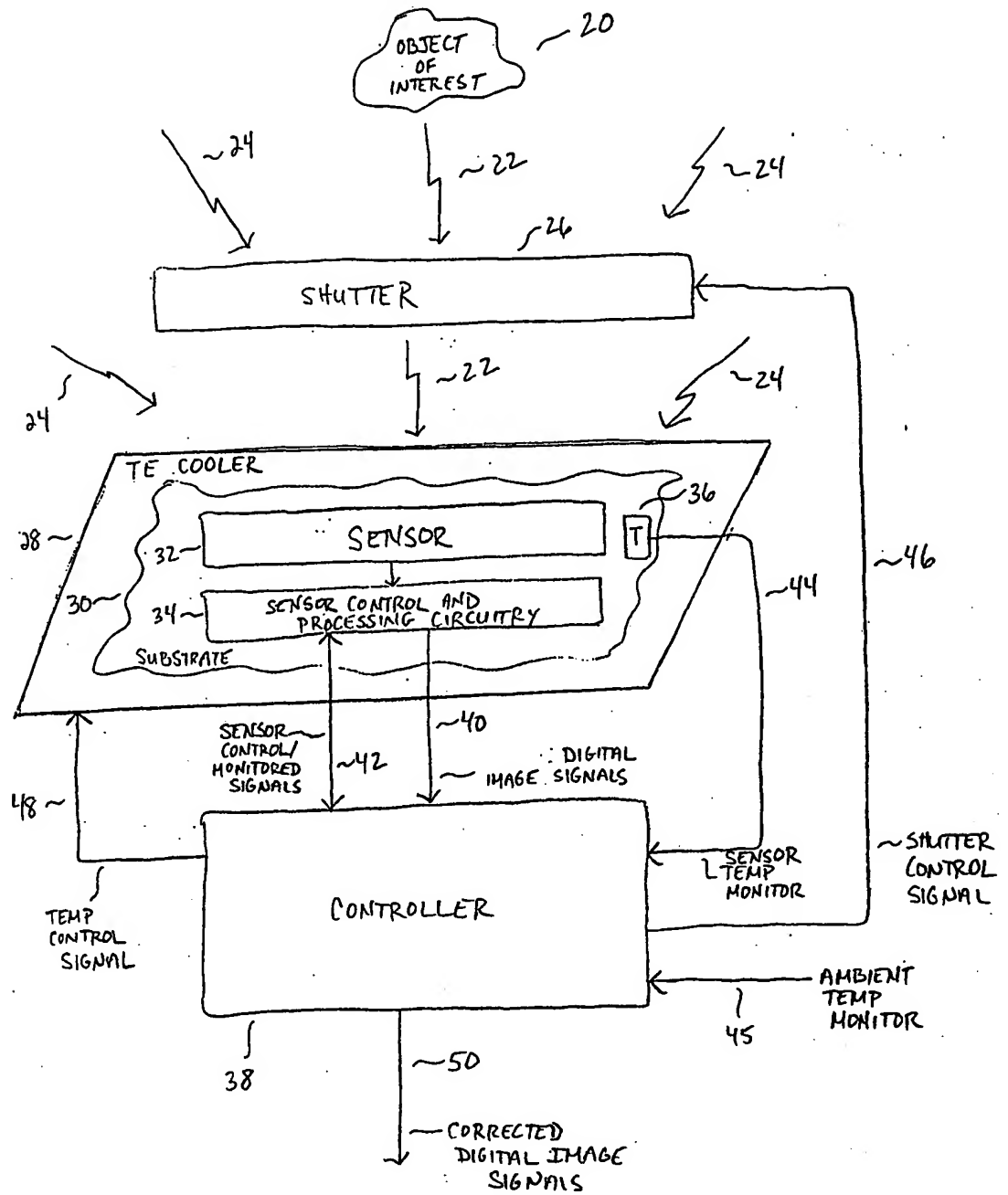


Fig. 1

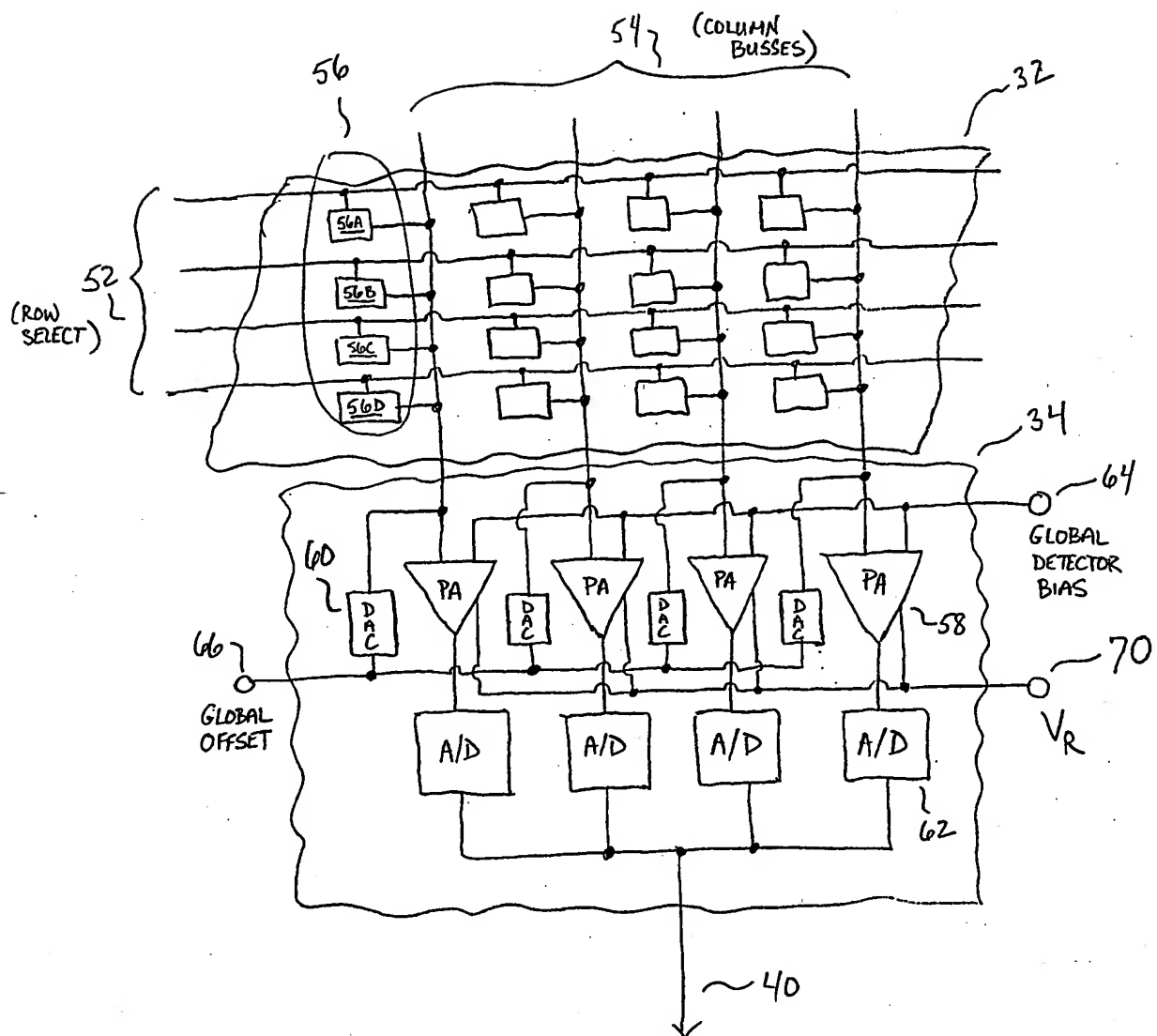


Fig. 2

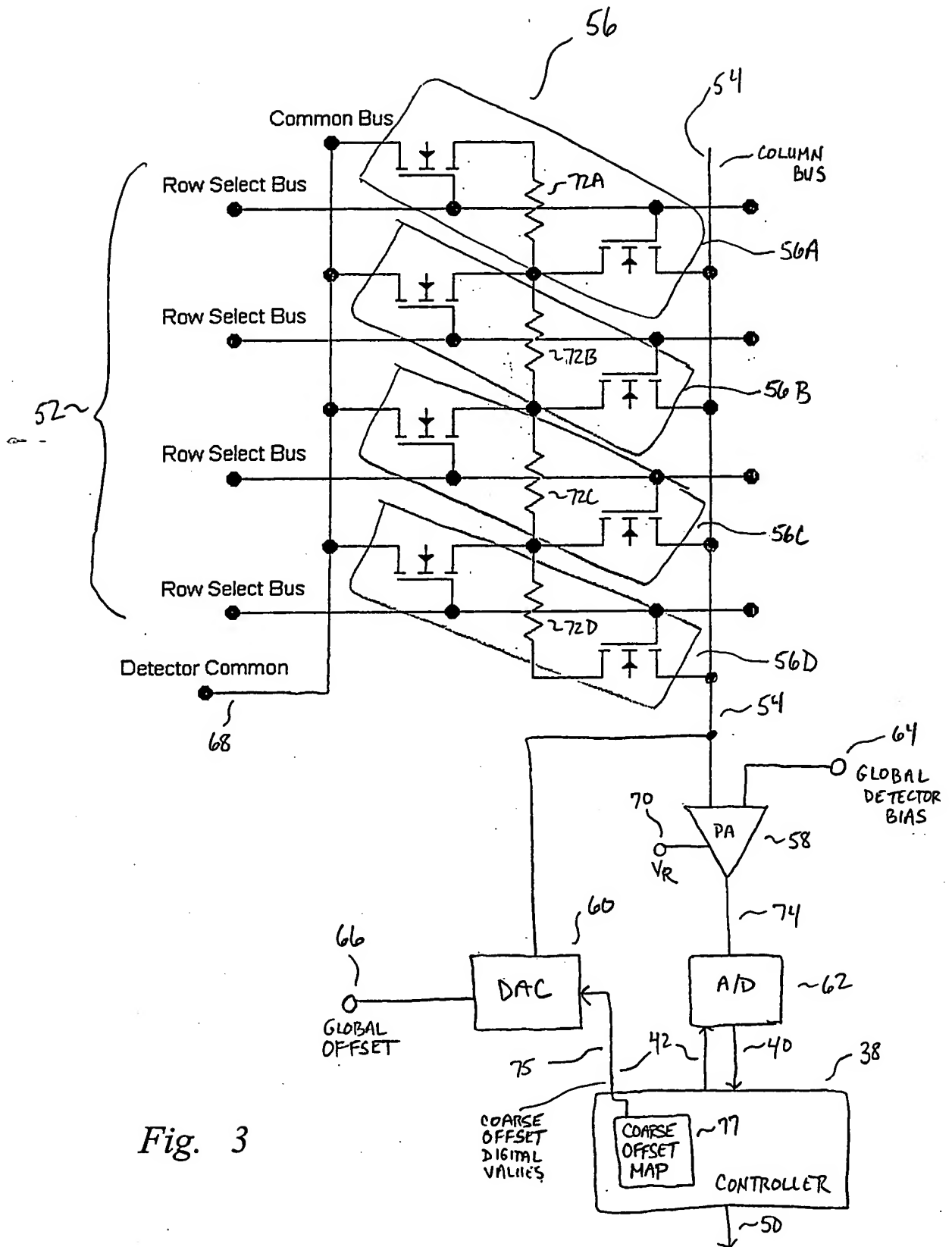


Fig. 3

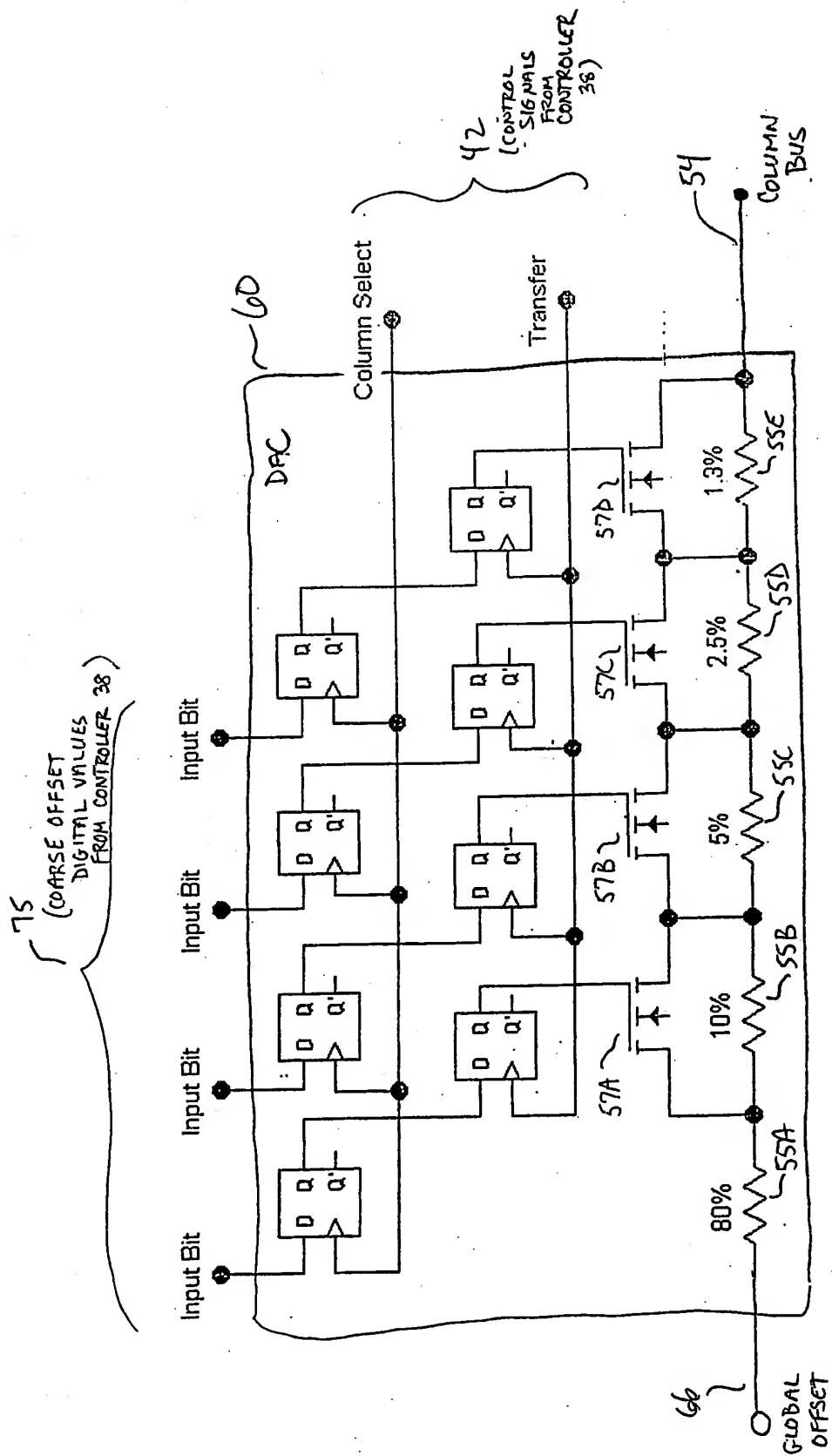


Fig. 4

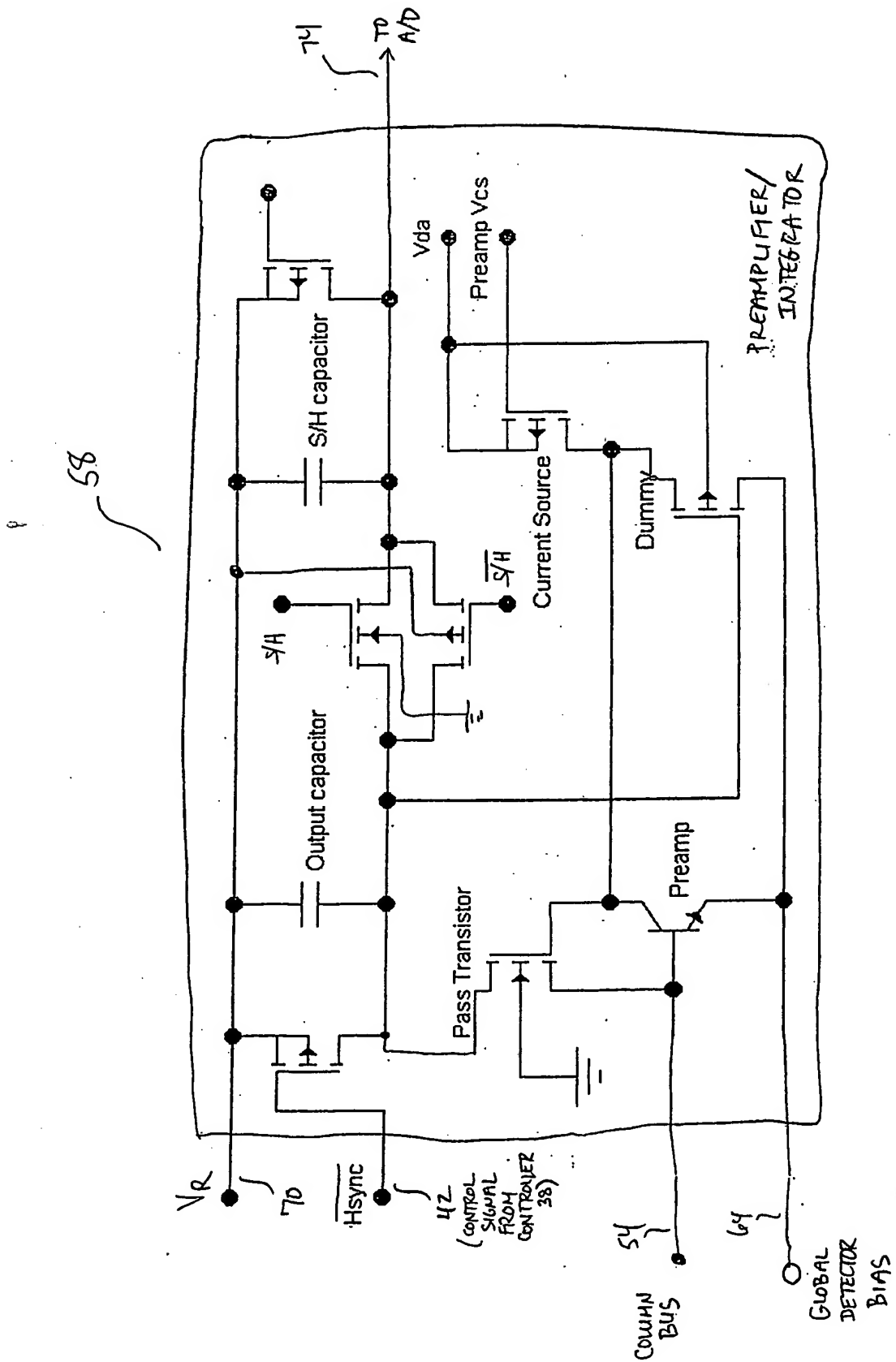


Fig. 5

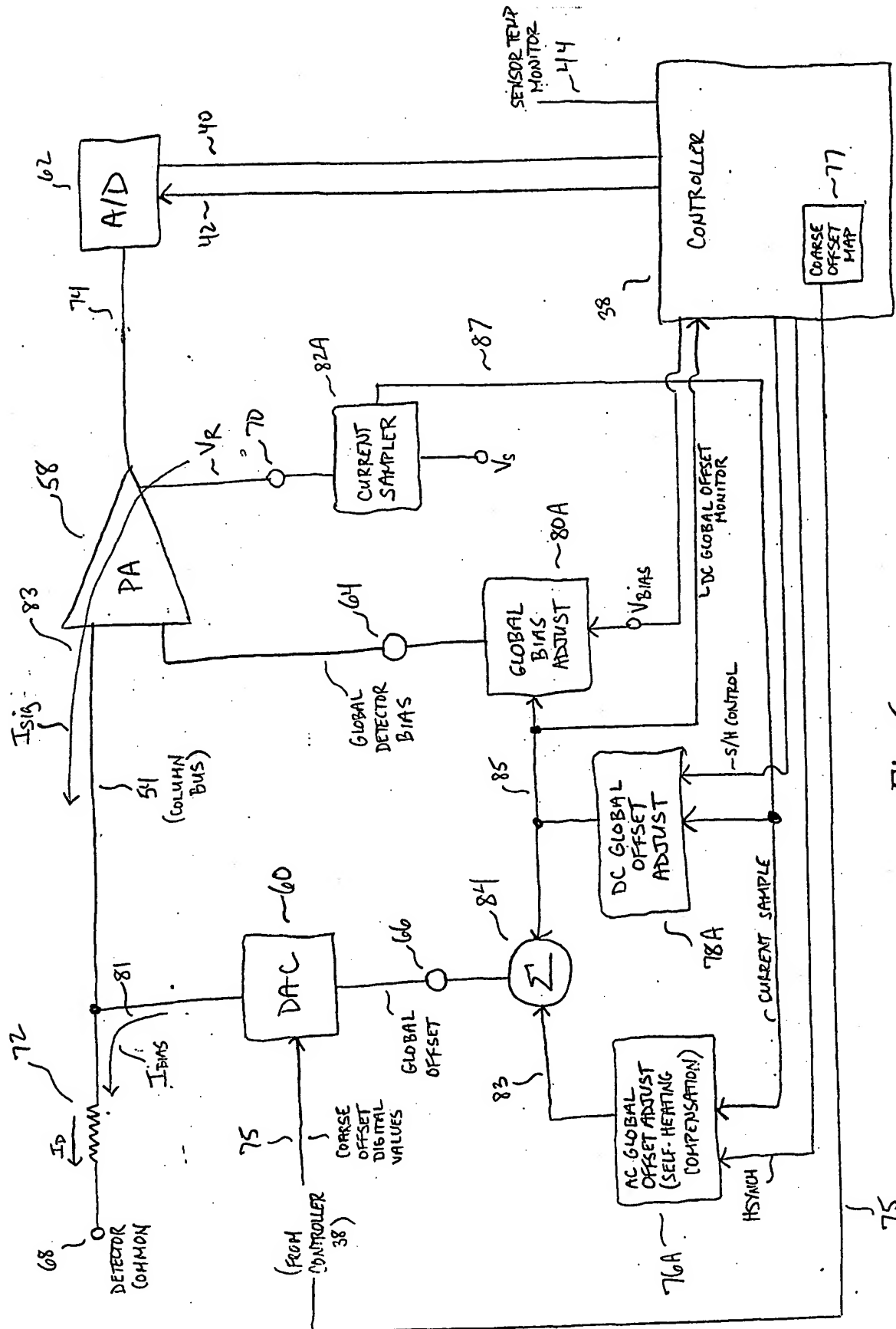


Fig. 6

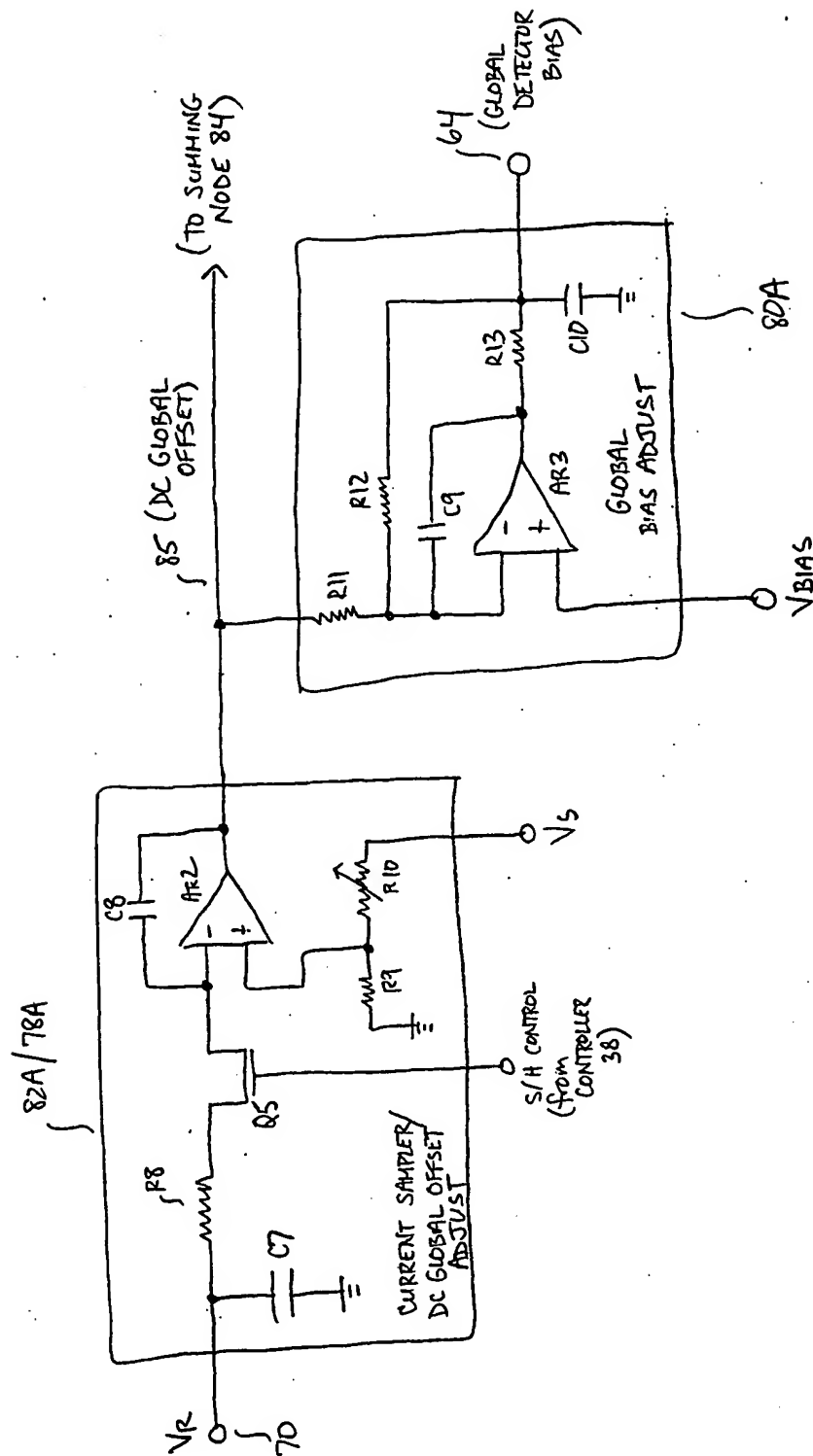


Fig. 7

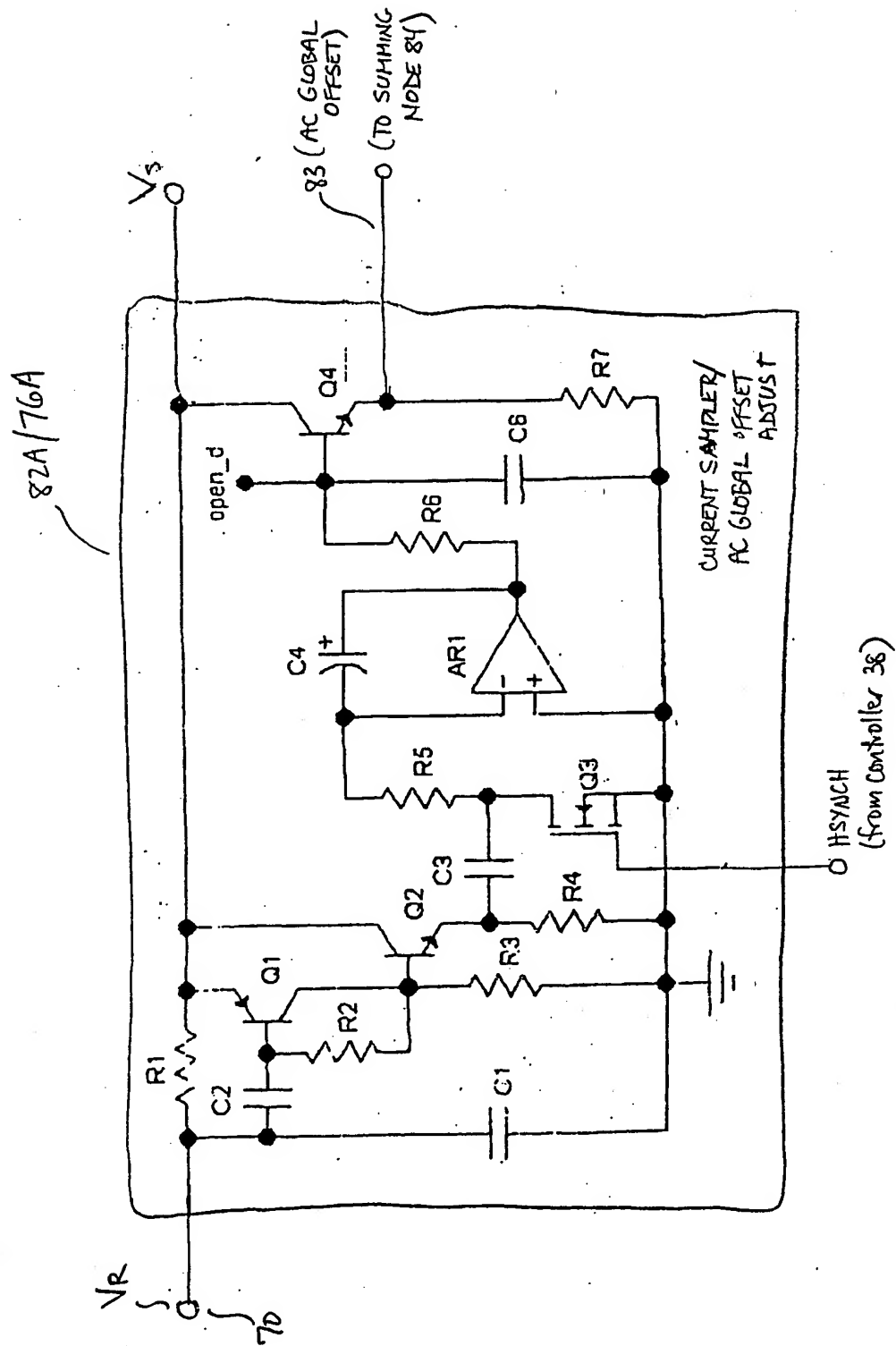


Fig. 8

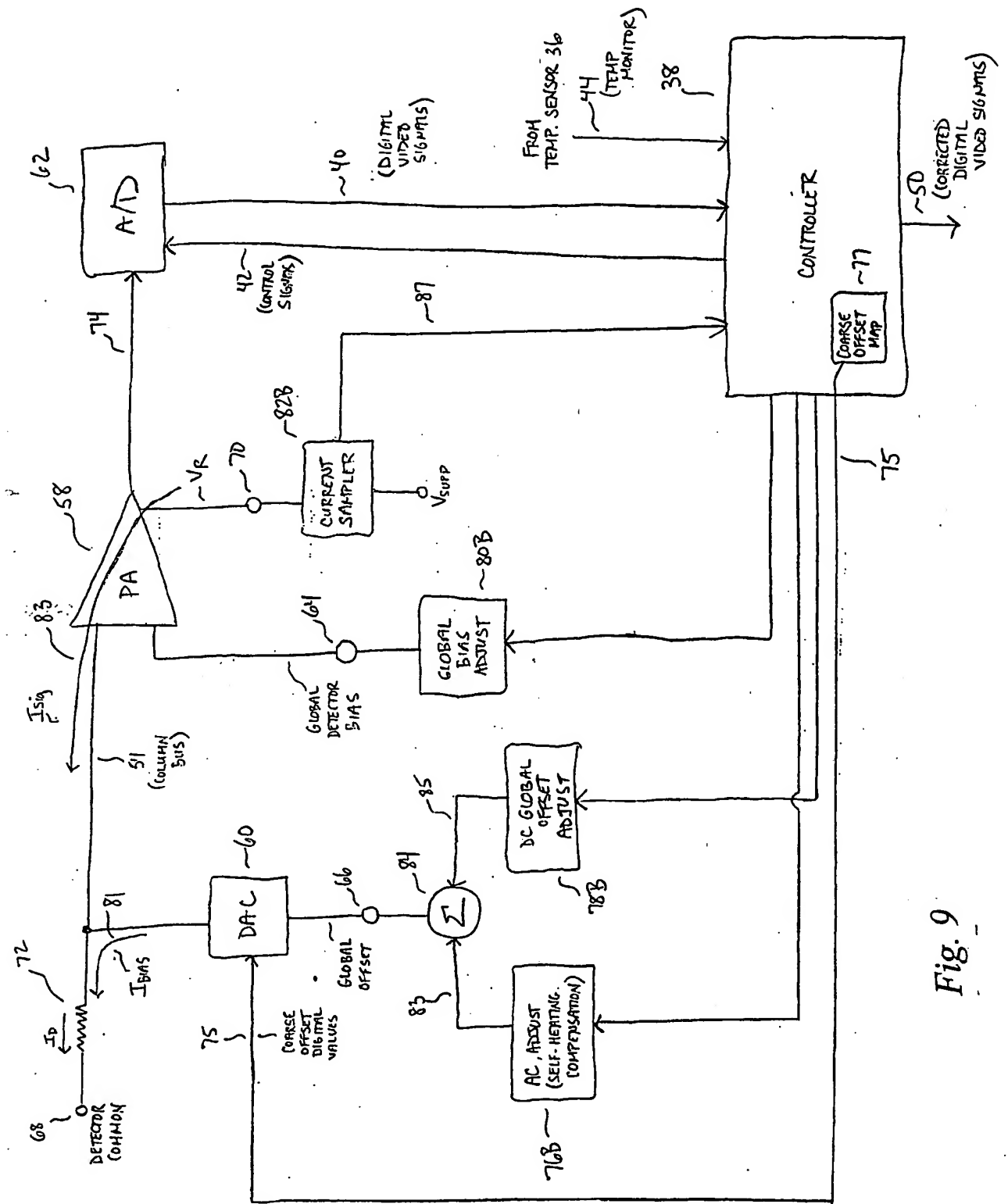
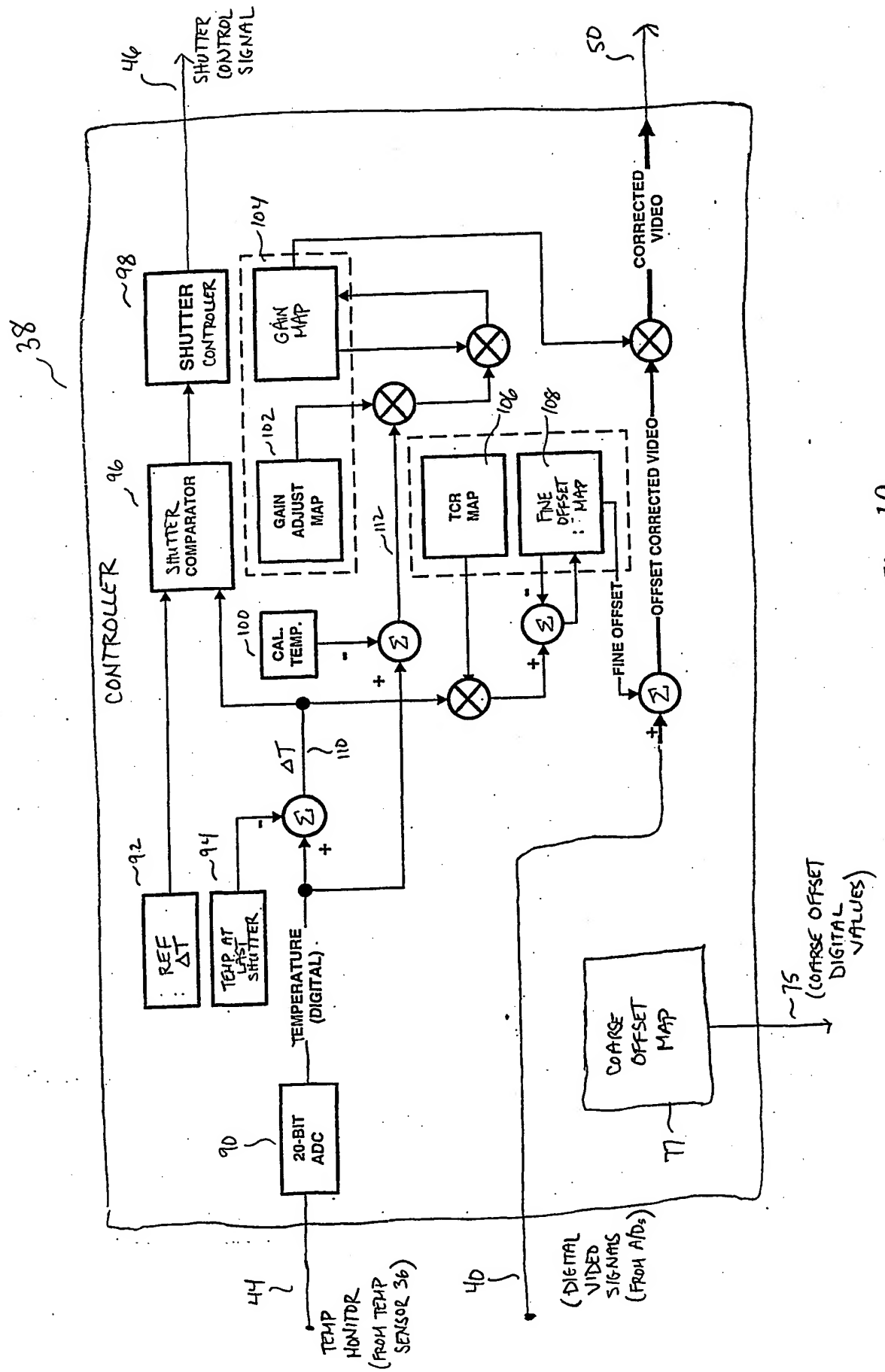


Fig. 9



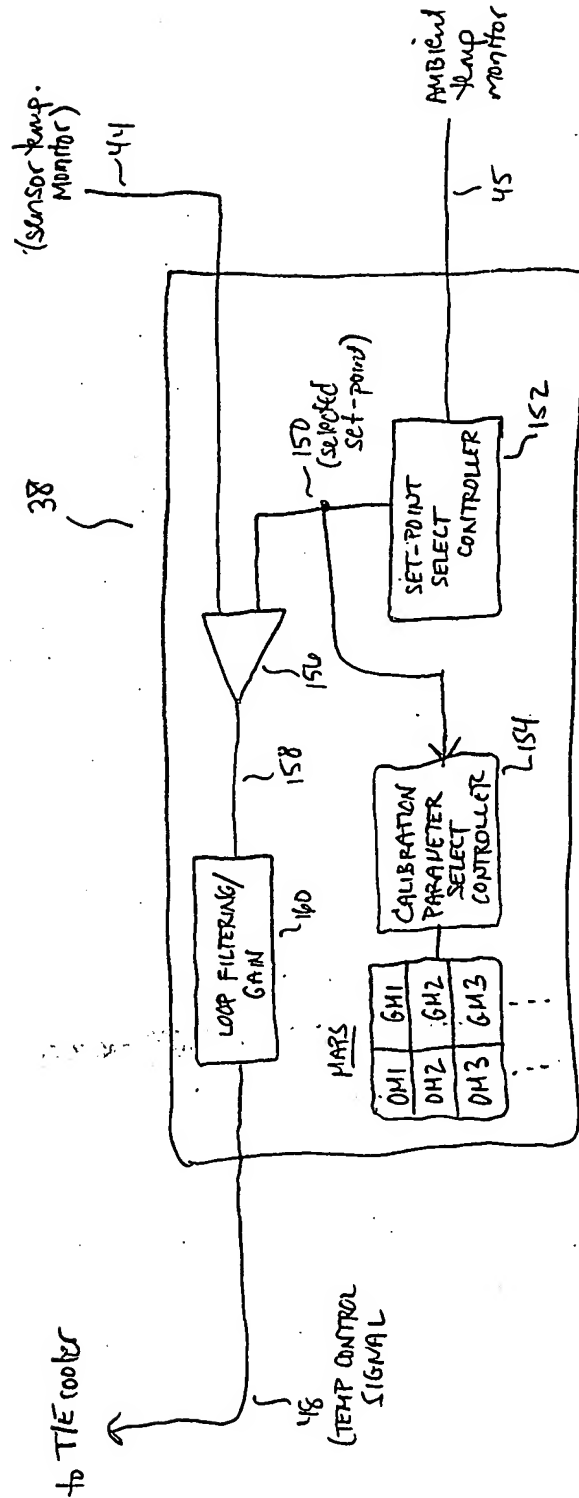


Fig. 11

THIS PAGE BLANK (USPTO)

(19) World Intellectual Property Organization
International Bureau



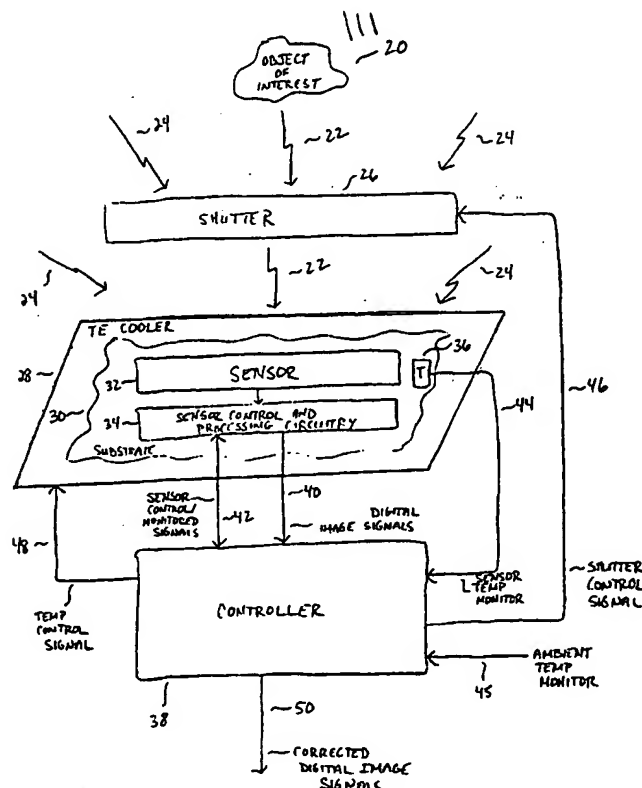
(43) International Publication Date
8 November 2001 (08.11.2001)

PCT

(10) International Publication Number
WO 01/84118 A3

- (51) International Patent Classification⁷: **G01J 5/20**
- (21) International Application Number: **PCT/US01/13612**
- (22) International Filing Date: **27 April 2001 (27.04.2001)**
- (25) Filing Language: **English**
- (26) Publication Language: **English**
- (30) Priority Data:
60/201,577 **1 May 2000 (01.05.2000)** **US**
- (71) Applicant: **BAE, INC. [US/US];** Two Forbes Road, Lexington, MA 02173 (US).
- (72) Inventor: **BUTLER, Neal, R.;** 144 School Street, Acton, MA 01710 (US).
- (74) Agent: **MORRIS, James, H.;** Wolf, Greenfield & Sacks, P.C., 600 Atlantic Avenue, Boston, MA 02210 (US).
- (81) Designated States (*national*): **IL, JP.**
- (84) Designated States (*regional*): **European patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, TR).**
- Published:
— *with international search report*
- (88) Date of publication of the international search report:
4 April 2002
- For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.*

(54) Title: **METHODS AND APPARATUS FOR COMPENSATING A RADIATION SENSOR FOR TEMPERATURE VARIATIONS OF THE SENSOR**



(57) Abstract: In one example, the radiation sensor is a thermal sensor having at least one property that varies as a function of temperature. The thermal sensor outputs signals based on thermal radiation of interest from a particular radiating body in its view. These signals may contain significant undesirable components due in part to changes in temperature of the sensor itself. Methods and apparatus of the invention compensate the sensor for temperature variations of the sensor that are not due to the radiation of interest, so as to significantly reduce undesirable components in the instantaneous signals output by the sensor. In one example, this is accomplished without thermally stabilizing the sensor itself (i.e., dynamic temperature compensation). In another example, the sensor is thermally stabilized selectively at various predetermined temperatures as a function of the ambient temperature in the proximity of the sensor.

WO 01/84118 A3

INTERNATIONAL SEARCH REPORT

International Application No
PCT/US 01/13612

A. CLASSIFICATION OF SUBJECT MATTER
IPC 7 G01J5/20

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)
IPC 7 G01J

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)
EPO-Internal

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X A X	WO 98 35212 A (INDIGO SYSTEMS CORP) 13 August 1998 (1998-08-13) page 16, line 2 - page 19, line 16; figures page 18, line 25 - line 27 page 18, line 28 - line 31 -----	1, 4-6, 9-12 3, 8 2, 7

☐ Further documents are listed in the continuation of box C.

☒ Patent family members are listed in annex.

* Special categories of cited documents:

- *A* document defining the general state of the art which is not considered to be of particular relevance
- *E* earlier document but published on or after the international filing date
- *L* document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)
- *O* document referring to an oral disclosure, use, exhibition or other means
- *P* document published prior to the international filing date but later than the priority date claimed

T later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention

X document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone

Y document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art.

G document member of the same patent family

Date of the actual completion of the international search

21 December 2001

Date of mailing of the international search report

07/01/2002

Name and mailing address of the ISA
European Patent Office, P.B. 5818 Patentlaan 2
NL - 2280 HV Rijswijk
Tel. (+31-70) 340-2040, Tx. 31 651 epo nl.
Fax: (+31-70) 340-3016

Authorized officer

Ramboer, P

INTERNATIONAL SEARCH REPORT

Information on patent family members

International Application No

PCT/US 01/13612

Patent document cited in search report		Publication date	Patent family member(s)	Publication date
WO 9835212	A	13-08-1998	US 5756999 A	26-05-1998
			US 6028309 A	22-02-2000
			AU 6263498 A	26-08-1998
			EP 1007920 A1	14-06-2000
			WO 9835212 A1	13-08-1998

THIS PAGE BLANK (USPTO)

CORRECTED VERSION

(19) World Intellectual Property Organization
International Bureau



(43) International Publication Date
8 November 2001 (08.11.2001)

PCT

(10) International Publication Number
WO 01/084118 A3

(51) International Patent Classification⁷: G01J 5/20

(72) Inventor: BUTLER, Neal, R.; 144 School Street, Acton, MA 01710 (US).

(21) International Application Number: PCT/US01/13612

(74) Agent: MORRIS, James, H.; Wolf, Greenfield & Sacks, P.C., 600 Atlantic Avenue, Boston, MA 02210 (US).

(22) International Filing Date: 27 April 2001 (27.04.2001)

(81) Designated States (*national*): IL, JP.

(25) Filing Language: English

(84) Designated States (*regional*): European patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, TR).

(26) Publication Language: English

(30) Priority Data:
60/201,577 1 May 2000 (01.05.2000) US

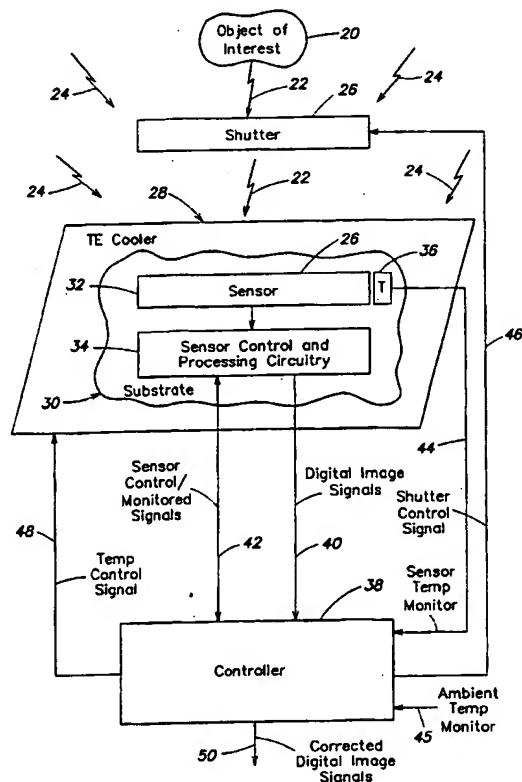
Published:
— with international search report

(71) Applicant: BAE SYSTEMS INFORMATION AND ELECTRONIC SYSTEMS INTEGRATION INC. [US/US]; 65 Spit Brook Road, Nashua, NH 03061 (US).

(88) Date of publication of the international search report:
4 April 2002

[Continued on next page]

(54) Title: METHODS AND APPARATUS FOR COMPENSATING A RADIATION SENSOR FOR TEMPERATURE VARIATIONS OF THE SENSOR



(57) Abstract: In one example, the radiation sensor is a thermal sensor having at least one property that varies as a function of temperature. The thermal sensor outputs signals based on thermal radiation of interest from a particular radiating body in its view. These signals may contain significant undesirable components due in part to changes in temperature of the sensor itself. Methods and apparatus of the invention compensate the sensor for temperature variations of the sensor that are not due to the radiation of interest, so as to significantly reduce undesirable components in the instantaneous signals output by the sensor. In one example, this is accomplished without thermally stabilizing the sensor itself (i.e., dynamic temperature compensation). In another example, the sensor is thermally stabilized selectively at various predetermined temperatures as a function of the ambient temperature in the proximity of the sensor.

WO 01/084118 A3



(48) Date of publication of this corrected version:

30 January 2003

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

(15) Information about Correction:

see PCT Gazette No. 05/2003 of 30 January 2003, Section II

**METHODS AND APPARATUS FOR COMPENSATING A RADIATION
SENSOR FOR TEMPERATURE VARIATIONS OF THE SENSOR**

Cross Reference to Related Application

5 This application claims the benefit of U.S. Provisional Application Serial No. 60/201,577, filed May 1, 2000, entitled AMBIENT TEMPERATURE OPERATION OF MICROBOLOMETER FOCAL PLANE ARRAYS, which application is hereby incorporated herein by reference.

Background of the Invention

10

1. **Field Of The Invention**

 The present invention generally relates to radiation sensors, and in particular, to compensating operating parameters and/or output signals of radiation sensors for changes in temperature of the sensors.

15

2. **Discussion of the Related Art**

 A radiation detector is a device that produces an output signal which is a function of an amount of radiation that is incident upon an active region of the radiation detector. Radiation detectors may be designed and constructed to be sensitive to particular regions of the electromagnetic spectrum. For example, infrared detectors are radiation detectors that are sensitive to radiation in the infrared region of the electromagnetic spectrum. One example of an infrared detector includes a thermal detector, which detects radiation based upon a change in the temperature of an active region of the detector due to absorption of radiation incident to the detector.

25

 A variety of imaging sensors may be constructed using an array of radiation detectors. Such sensors may be used in an imaging system that produces an image (e.g., on a display) based on radiation impinging on the imaging sensor. Based on the type of detectors used, the imaging sensor may be responsive to a particular region of spectrum. For example, an infrared or thermal imaging sensor may include a number of thermal detectors that detect a representation of an object by the objects' thermal emissions. In particular, energy emitted by an object may depend on numerous quantities such as, for example, the emissivity and the temperature of the object. Infrared thermal sensors typically detect one or both of these quantities and use the detected information to produce an object image that may be viewed, for example, on a display.

30

- 2 -

One issue in connection with at least some types of radiation detectors is that often it may be challenging to separate those signals output by the detector that are actually due to radiation of interest incident to the detector from various undesirable components which may be present in the detector output signals. For example, detector output signals may include various undesirable components due to variations in temperature of the detector itself that are not necessarily due to the radiation of interest.

In particular, temperature changes in the vicinity of the detector that may affect the temperature of the detector, sometimes referred to as ambient temperature variations (e.g., changes in temperature of a substrate on which the detector is fabricated, changes in temperature of a package in which the detector is housed, average temperature changes in a scene of interest itself), in turn may cause undesirable components to be present in the detector output signals. In some cases, these undesirable components may be hundreds of times larger than the instantaneous signals resulting from the radiation of interest, thereby detrimentally reducing the dynamic range of the detector and/or processing circuitry associated with the detector with respect to the radiation of interest.

In view of the foregoing, some conventional imaging systems employing imaging sensors comprising a number (e.g., array) of radiation detectors require some type of temperature stabilization of the detectors to reduce such undesirable components in the detector output signals. In particular, with respect to conventional thermal imaging systems, it is generally thought to be impractical to operate such systems without active stabilization of the temperature of the detectors. In some cases, thermal stabilization components may include a thermoelectric cooler (hereinafter, "TE cooler") which is thermally coupled to the detectors (e.g., the substrate on which the detectors are fabricated is mounted on the TE cooler) to hold the detectors at a predetermined temperature. Depending on the difference between the predetermined stabilization temperature and the actual ambient temperature in the vicinity of the detectors, the TE cooler may consume appreciable power resources of the imaging system.

30

Summary of the Invention

- 3 -

One embodiment of the invention is directed to a method of compensating a radiation sensor for changes in at least one operational characteristic of the sensor due to a temperature variation of the sensor. The method comprises an act of dynamically adjusting at least one operating parameter associated with the radiation sensor and/or at least one calibration parameter associated with the radiation sensor based on the temperature variation of the sensor.

According to one aspect of this embodiment, the at least one operational characteristic of the sensor that changes due to the temperature variation of the sensor includes a resistance of the sensor.

According to another aspect of this embodiment, the at least one operating parameter associated with the sensor includes at least one of a DC bias voltage applied to the sensor, a DC bias current applied to the sensor, and an AC bias waveform applied to the sensor.

According to another aspect of this embodiment, the sensor includes a plurality of radiation detectors, and the at least one calibration parameter associated with the sensor includes at least one of an offset error value for each radiation detector and a gain value for each radiation detector.

According to another aspect of this embodiment, the sensor includes a plurality of radiation detectors, and the at least one operational characteristic of the sensor that changes due to the temperature variation of the sensor includes at least one of an offset error variation and a gain variation.

Another embodiment of the invention is directed to an apparatus, comprising a controller to compensate a radiation sensor for changes in at least one operational characteristic of the sensor due to a temperature variation of the sensor. The controller dynamically adjusts at least one operating parameter associated with the radiation sensor and/or at least one calibration parameter associated with the radiation sensor based on the temperature variation of the sensor.

Brief Description of the Drawings

Fig. 1 is a diagram showing a portion of an imaging system according to one embodiment of the invention;

Fig. 2 is a diagram showing a portion of an integrated sensor array and some associated signal processing circuitry used in the imaging system of Fig. 1, according to one embodiment of the invention;

Fig. 3 is a diagram showing a more detailed view of a portion of the sensor array
5 illustrated in Fig. 2, according to one embodiment of the invention;

Fig. 4 is a diagram showing one example of a digital-to-analog converter used in the processing circuitry shown in Figs. 2 and 3, according to one embodiment of the invention;

Fig. 5 is a diagram showing one example of a preamplifier/integrator used in the
10 processing circuitry shown in Figs. 2 and 3, according to one embodiment of the invention;

Fig. 6 is a diagram showing a more detailed view of the portion of the imaging system shown in Fig. 3, illustrating one possible implementation of various temperature compensation features, according to one embodiment of the invention;

Fig. 7 is a diagram showing examples of a current sampler/DC global offset
15 adjust circuit and a global bias adjust circuit as analog circuit implementations of the temperature compensation features shown in Fig. 6, according to one embodiment of the invention;

Fig. 8 is a diagram showing an example of a current sampler/AC global offset
20 adjust circuit as an analog circuit implementation of a sensor self-heating temperature compensation feature shown in Fig. 6, according to one embodiment of the invention;

Fig. 9 is a diagram showing a more detailed view of the portion of the imaging system shown in Fig. 3, illustrating another implementation of various temperature compensation features, according to one embodiment of the invention;

Fig. 10 is a block-diagram showing one example of a portion of a compensation
25 algorithm implemented by a controller of the imaging system of Fig. 1, according to one embodiment of the invention; and

Fig. 11 is a diagram of a portion of a controller of the imaging system of Fig. 1, showing various components of a temperature stabilization feedback loop according to
30 one embodiment of the invention.

- 5 -

Detailed Description

As discussed above, a radiation sensor outputs signals based on radiation that impinges on the sensor. Such a sensor may be used in an imaging system that produces images (e.g., on a display) based on radiation incident to the sensor from a scene of interest. The sensor output signals, however, may contain significant undesirable components due in part to changes in temperature of the sensor itself that are not necessarily due to the radiation of interest. In some cases, these undesirable signal components may be hundreds of times larger than the instantaneous signals resulting from the radiation of interest in the scene being imaged, thereby detrimentally reducing the dynamic range of the sensor and/or processing circuitry associated with the sensor with respect to the radiation of interest.

With respect to undesirable signal components, changes in temperature of the sensor that are not related to the radiation of interest may have an average effect over time (i.e., a DC drift in the sensor output signals). Such changes in temperature may be related to ambient temperature variations, such as a change in temperature of a substrate on which the sensor is fabricated, a change in temperature of a package in which the sensor is housed, or a change in the average temperature of the scene of interest around the sensor. Additionally, Applicants have recognized that essentially instantaneous (i.e., AC) undesirable signal components may be observed due to "self-heating" of the sensor, for example, when a bias voltage initially is applied to the sensor and current begins to flow through the sensor, producing heat. Furthermore, individual detectors of a detector array constituting an imaging sensor each may respond differently to temperature variations, creating undesirable signal components due to detector non-uniformities.

In view of the foregoing, the present invention is directed generally to methods and apparatus for compensating operating parameters and/or output signals of a radiation sensor for temperature variations of the sensor that are not due to radiation of interest. The compensation provided by various embodiments of methods and apparatus of the invention significantly reduces undesirable components in the instantaneous signals output by the sensor. In one aspect of the present invention, the radiation sensor is an infrared thermal imaging sensor including an array of thermal detectors, such as bolometers. It should be appreciated, however, that the invention is not limited in this

respect, as various compensation methods, apparatus, and concepts discussed herein may be applied generally to a variety of sensors and detection devices.

In one embodiment, methods and apparatus of the invention provide compensation for temperature variations of a sensor without thermally stabilizing the sensor itself; in particular, the sensor is allowed to freely vary in temperature and is dynamically compensated for temperature variations. In one aspect of this embodiment, one or more operating and/or calibration parameters associated with the sensor are dynamically determined or updated based on temperature variations of the sensor, and used to dynamically compensate for changes in operational characteristics of the sensor due to the temperature variations of the sensor. Essentially, in one aspect, the methods and apparatus of this embodiment provide continuous thermal compensation feedback without thermal stabilization of the sensor through dynamic operating and/or calibration parameter adjustments.

Some examples of operating parameters associated with the sensor that may be dynamically adjusted based on sensor temperature variations according to one embodiment of the invention include, but are not limited to, an average (i.e., DC) bias current of the sensor, a bias voltage of the sensor, and a waveform and amplitude of an AC signal used to compensate for sensor self-heating. Additionally, for imaging sensors including an array of detectors, examples of calibration parameters that may be dynamically adjusted based on sensor temperature variations include individual detector offset and response (gain) coefficients that account for differences in operating characteristics from detector to detector.

The foregoing approach of temperature compensation without thermal stabilization constitutes a significant departure from conventional thermal imaging techniques, which generally require active stabilization of sensor temperature. Thus, methods and apparatus of the invention according to one embodiment facilitate the design of a thermal imaging system that does not necessarily require thermal stabilization components (e.g., a thermoelectric cooler), thereby providing for reduced system power consumption and potential production cost savings.

In another embodiment of the present invention, thermal stabilization components are employed to thermally stabilize a radiation sensor selectively at various predetermined temperatures as a function of the ambient temperature in the proximity of

- 7 -

the sensor. Although thermal stabilization components are employed in this embodiment, power consumption of these components is nonetheless significantly reduced according to the invention by dynamically selecting one of several predetermined stabilization temperatures that is in the vicinity of the measured ambient temperature. In one aspect of this embodiment, various operating and calibration parameters associated with the sensor (e.g., as discussed above) initially are measured or determined at each of the different predetermined stabilization temperatures. During subsequent operation, these operating and calibration parameters are dynamically selected and utilized to compensate the sensor based on the corresponding stabilization temperature in use.

Following below are more detailed descriptions of various concepts related to, and embodiments of, methods and apparatus according to the present invention for compensating a radiation sensor for temperature variations of the sensor. It should be appreciated that various aspects of the invention, as discussed above and outlined further below, may be implemented in any of numerous ways, as the invention is not limited to any particular manner of implementation. Examples of specific implementations are provided for illustrative purposes only.

Fig. 1 is a diagram showing a portion of an imaging system according to one embodiment of the invention. Some of the basic components of the imaging system shown in Fig. 1 include a shutter 26, a sensor 32, sensor control and processing circuitry 34, and a controller 38. In one aspect of the system of Fig. 1, the sensor 32 may comprise a thermal imaging sensor that responds primarily to infrared radiation, wherein the sensor includes an array of thermal detectors, such as bolometers. At least one operational characteristic of a bolometer that may be affected by temperature variations of the bolometer itself include a resistance of the bolometer, as discussed in greater detail below.

According to yet another aspect of the imaging system shown in Fig. 1, the sensor 32 and the circuitry 34 may be monolithically integrated on a semiconductor substrate 30 along with a temperature sensor 36, which outputs a sensor temperature signal 44 corresponding to the temperature of the sensor 32. Fig. 1 also shows that in one embodiment, the substrate 30 may be thermally coupled to (e.g., mounted on) a TE cooler 28 which provides thermal stabilization for the sensor 32. It should be

- 8 -

appreciated, however, that the invention is not limited in this respect, as other embodiments of the invention discussed further below do not necessarily require the TE cooler 28.

While not shown explicitly in Fig. 1, the substrate 30 including the sensor 32 and the circuitry 34, along with the TE cooler 28, may be housed together in a vacuum package having a window that allows radiation to pass through to the sensor 32. In embodiments of the invention that do not require the TE cooler 28, the vacuum package merely may house the substrate 30 including the sensor 32 and the circuitry 34.

In the system of Fig. 1, according to one embodiment, the controller 38 monitors the sensor temperature signal 44 output by the temperature sensor 36, receives digitized signals 40 output by the circuitry 34 (which represent signals output by the sensor 32), and exchanges various other sensor control and monitor signals 42 with the circuitry 34. Additionally, according to one embodiment, the controller 38 also may monitor an ambient temperature signal 45 corresponding to an ambient temperature outside the package housing the sensor 32. In various embodiments of the invention employing the TE cooler 28, the controller 38 also may output a temperature control signal 48 to the TE cooler 28 in response to one or more of the sensor temperature signal 44, the ambient temperature signal 45, or a sensor temperature as calculated based on an average value of the digitized output signals 40. Finally, as shown in Fig. 1, the controller 38 outputs a shutter control signal 46 to control the operation of the shutter 26, as discussed further below.

With respect to various functions of the controller 38, as well as other components of imaging systems according to various embodiments of the invention, it should be appreciated that the invention is not limited to any particular manner of implementation. For example, methods and apparatus for compensating a radiation sensor for temperature variations of the sensor as discussed herein may be implemented in hardware, software, or various combinations thereof. In particular, the controller 38 may include dedicated hardware to perform various functions and/or may include one or more processors programmed using microcode or software to execute various algorithms to perform various functions discussed herein. In this respect, it should be appreciated that the controller 38 also may include a variety of digital logic circuits and memory or storage circuits or devices, including volatile, programmable, and permanent memory

circuits or devices (e.g., RAM, ROM, EPROM, EEPROM). Such components are not necessarily explicitly indicated in each of the figures showing the controller 38.

As illustrated in Fig. 1, an object of interest 20 in a scene to be imaged emanates radiation 22. The radiation 22 constitutes the radiation of interest from which an image of the object of interest 20 is generated by the imaging system. Fig. 1 also illustrates background radiation 24, which may related to an average temperature of the scene to be imaged, and in some cases also may be related to the ambient temperature in the vicinity of the package housing the sensor 32. For thermal imaging systems in particular, at a given temperature of the sensor 32, this background radiation 24 may contribute to an average (i.e., DC) component of signals from the sensor 32, and hence may be compensated for (e.g., subtracted out of the signals) by the imaging system. Accordingly, it should be appreciated that the instantaneous signals of interest output by the sensor 32 typically may be considered as essentially time-varying (i.e., essentially AC components) with respect to an average DC signal component. More specifically, in thermal imaging systems, the signals of interest output by the sensor 32 correspond to the radiation 22 from one or more objects having a temperature different than that of the average scene temperature.

Fig. 2 is a diagram showing a portion of an integrated sensor including an array of detectors and some associated signal processing circuitry used in the imaging system of Fig. 1, according to one embodiment of the invention. In particular, Fig. 2 illustrates a portion of the sensor 32, showing a four-by-four array of detector unit cells arranged in rows and columns. In Fig. 2, a first column 56 of detector unit cells is particularly identified, including four detector unit cells 56A, 56B, 56C, and 56D. According to one embodiment, each row of the sensor 32 may be selected by a corresponding row select signal 52, and each column of unit cells is associated with a common column bus 54, on which each of the unit cells of the column outputs a signal.

From Fig. 2, it may be appreciated that for each row of the sensor 32 that is selected via the row select signals 52, each column bus 54 carries one signal corresponding to a respective detector unit cell of the selected row. In particular, according to one embodiment of the invention, each row of the sensor 32 is sequentially selected (e.g., the row select signals may be derived from control signals output by the controller 38 shown in Fig. 1), and the respective detector unit cells of the selected row

- 10 -

output a signal on a corresponding column bus 54. Additionally, the column busses 54 may be "enabled" or activated with a particular timing to pass the output signals from the selected row of unit cells onto the processing circuitry 34 (e.g., again via control signals output by the controller 38). In this manner, rows of detector unit cells may be scanned
5 in a manner similar to that of a television video signal (i.e., a raster scan). For simplicity, various row select and column bus enable circuitry is not illustrated in Fig. 2, and it should be appreciated that such circuitry may be implemented in a variety of manners.

Fig. 2 also shows a portion of the sensor control and processing circuitry 34 that is integrated with the sensor 32. In particular, Fig. 2 shows that each column bus 54 of
10 the sensor 32 is coupled to a preamplifier/integrator 58 (labeled in Fig. 2 as "PA"). Each of the PAs 58 also receives as an input a global detector bias 62, which provides a common DC bias voltage for all of the detector unit cells of the sensor 32, as discussed further below. Additionally, Fig. 2 shows that the PAs 58 are each coupled to a common
15 supply voltage 70 (labeled in Fig. 2 as " V_R "), which provides a common source of current for the PAs 58 to drive respective selected detector unit cells of the sensor 32. The instantaneous current drawn from the voltage V_R by a given preamplifier/integrator 58 and supplied to a selected detector unit cell when a scene is actively being viewed preferably constitutes the instantaneous signal of interest from the selected detector, as also discussed further below.

20 In Fig. 2, each column bus 54 of the sensor 32 is also coupled to a digital-to-analog converter 60 (labeled in Fig. 2 as "DAC") included in the sensor control and processing circuitry 34. Each DAC 60 is in turn coupled to a common or "global" offset 66. The global offset 66 may be a voltage or current applied to all of the DACs 60 to ultimately provide a bias current to each selected detector unit cell via the column busses
25 54. As discussed further below in connection with Figs. 3 and 4, each DAC 60 is controlled by the controller 38 to provide a coarse offset adjustment to the bias current supplied to each selected detector unit cell, to compensate for detector non-uniformities (i.e., non-uniform responses from detector to detector).

30 Additionally, Fig. 2 shows that the output of each PA 58 is coupled to an analog-to-digital converter 62 (labeled in Fig. 2 as "A/D"), which converts the analog signal output by each PA to a digital signal 40. At least one example of an analog-to-digital converter implementation for the A/Ds 62 suitable for purposes of the present invention

- 11 -

is provided in U.S. Patent No. 6,225,937, issued May 1, 2001, and entitled "METASTABILITY RESOLVED MONOLITHIC ANALOG-TO-DIGITAL CONVERTER," which patent is hereby incorporated herein by reference. It should be appreciated, however, that the present invention is not limited to the analog-to-digital converter implementations discussed in this patent, as other implementations are possible.

While not explicitly shown in Fig. 2 (again for purposes of simplicity), the A/Ds 62 are sequentially enabled via control signals output by the controller 38 shown in Fig. 1, so that each digital signal may be individually output from a corresponding A/D as the signal 40, and thereafter individually processed and/or stored in memory by the controller 38. Accordingly, it should be appreciated that each row of the sensor is sequentially enabled to obtain a set of "parallel" signals corresponding to the unit cells of the selected row, these signals are converted by the A/Ds 62 to a set of parallel digital signals, and then each signal from the set of digital signals is sequentially passed onto the controller 38 for individual processing and/or storage.

Fig. 3 is a diagram showing a more detailed view of a portion of the sensor 32 illustrated in Fig. 2, according to one embodiment of the invention. In particular, Fig. 3 shows in greater detail the four unit cells 56A, 56B, 56C, and 56D of the column 56 of the sensor 32. Fig. 3 also shows the PA 58, the DAC 60 and the A/D 62 associated with the column 56. As can be seen in Fig. 3, according to one embodiment of the invention, each detector unit cell includes two transistors each having a gate coupled to the same row select bus. Each unit cell also includes a detector, illustrated symbolically as the resistors 72A, 72B, 72C, and 72D respectively in the unit cells 56A, 56B, 56C, and 56D. Upon the activation of a row select signal for a particular row, one transistor of the unit cell connects one terminal of the detector to a detector common 68 (e.g., a ground potential), and the other transistor of the unit cell connects the other terminal of the detector to the column bus 54. Fig. 3 also illustrates that the controller 38 includes a coarse offset map 77 that provides the DAC 60 for the column 56 with coarse offset digital values 75 for each of the unit cells of the column 56. The coarse offset digital values 75 control the DAC 60 to adjust the global bias current provided by the global offset 66, so as to compensate for detector non-uniformities, as discussed further below.

Fig. 4 is a diagram showing one example of the DACs 60 used in the sensor processing circuitry 34 shown in Figs. 2 and 3, according to one embodiment of the invention. Other examples of digital-to-analog converter implementations for the DACs 60 suitable for purposes of the present invention are provided in U.S. patent application Serial No. 08/981,109, filed December 17, 1997, and entitled "DIGITAL OFFSET CORRECTOR," which application is hereby incorporated herein by reference. It should be appreciated, however, that the present invention is not limited to the examples of DACs discussed in this application, nor to the exemplary DAC illustrated in Fig. 4, as other implementations are possible.

Essentially, the DAC 60 shown in Fig. 4 is used to incrementally adjust the value of a bias resistor coupled between a column bus 54 and the global offset 66, so as to adjust a DC bias current provided to each of the detectors of the sensor 32. In Fig. 4, this bias resistor is shown schematically in five parts for purposes of illustration, as the resistors 55A, 55B, 55C, 55D, and 55E. Different parts of the bias resistor are selectively "bypassed" to change the overall bias resistance by activating one or more of bypass transistors 57A, 57B, 57C, and 57D via a corresponding one of the input bits of the coarse offset digital values 75. For each detector of the sensor 32, the controller 38 stores a coarse offset digital value in a coarse offset map 77 (e.g., shown in Fig. 3). This offset value corresponds to an adjustment to the bias resistance that is required for the particular detector so as to compensate for inherent non-uniformities amongst the detectors, as discussed further below.

Fig. 5 is a diagram showing one example of the PAs 58 used in the processing circuitry 34 shown in Figs. 2 and 3, according to one embodiment of the invention. Other examples of preamplifier/integrator implementations for the PAs 58 suitable for purposes of the present invention are provided in U.S. patent application Serial No. 09/011,942, filed February 20, 1998, and entitled "BOLOMETRIC FOCAL PLANE ARRAY," and U.S. patent application Serial No. 09/051,180, filed April 3, 1998, and entitled "UNCOOLED FOCAL PLANE ARRAY SENSOR," which applications are hereby incorporated herein by reference. It should be appreciated, however, that the present invention is not limited to the examples of PAs discussed in these applications, nor to the exemplary PA illustrated in Fig. 5, as other implementations are possible.

- 13 -

According to one embodiment, as can be seen from the exemplary circuit of Fig. 5, the column bus 54 is actually biased at one V_{be} (i.e., approximately 0.7 Volts) above the global detector bias 64, due to the base-emitter junction of the preamp transistor. Fig. 5 also illustrates that the supply voltage 70 (V_R) supplies current to the column bus 54 via the pass transistor, and the output capacitor is charged to a voltage representing this current, which voltage is ultimately provided as the signal 74 to the A/D 62.

With reference again to Figs. 2 and 3, according to one embodiment of the invention, the individual detectors of the sensor 32 may be thermal detectors that detect primarily infrared radiation. Generally, a thermal detector detects radiation based upon a change in the temperature of an active region of the detector due to absorption of radiation of interest incident to the detector. Some examples of thermal detectors include, but are not limited to, pyroelectric devices, thermocouples, diode-based devices, and resistive devices, such as bolometers.

In particular, according to one embodiment of the invention, the detectors of the unit cells of the sensor 32 (e.g., the detectors 72A, 72B, 72C, and 72C of the unit cells 56A, 56B, 56C, and 56D shown in Fig. 3) may be bolometers, wherein each bolometer includes an infrared energy receiving surface that is made of a material having a resistivity that changes as its temperature changes, in response to the infrared energy impinging on and being absorbed by the material. Thus, as the bolometer absorbs radiation, both its temperature and electrical resistance change.

A measure of radiation absorbed by a bolometer can be made by measuring changes in its electrical resistance. For example, by placing the bolometer in series with a voltage supply (i.e., D.C. coupling the bolometer), the current in the bolometer varies in accordance with the amount of infrared energy incident to the bolometer. Accordingly, as shown in Fig. 3, a preamplifier / integrator (PA) 58 is connected to a voltage supply 70 (V_R) to provide current to a particular selected bolometer, and is serially connected to the bolometer so as to produce an output signal 74 representative of the incident infrared energy. As discussed above, the sensor 32 including an array of such bolometers produces a plurality of output signals that are ultimately fed to the controller 38, which processes the signals to provide an electronic image of the source of the infrared energy.

- 14 -

One significant issue related to bolometers is that various operational characteristics of bolometers (in addition to the sensitivity of its active area to incident radiation and corresponding changes in bolometer resistance due to the incident radiation of interest) are functions of the temperature of the bolometer itself. As a result, in some cases it may be challenging to separate signals of interest due to incident radiation from undesirable signal components due to temperature variations of the bolometer itself.

Preliminarily, it should be appreciated that gradual or steady state changes in temperature of the bolometer itself (e.g., due to changes in temperature in the vicinity of the bolometer) alter the steady state resistance of the bolometer; hence, one operational characteristic of the bolometer that changes as a function of bolometer temperature variations is its resistance. Such changes in steady state resistance due to bolometer temperature variations may be significantly larger (e.g., up to hundreds of times larger) than instantaneous changes in bolometer resistance due to incident radiation of interest. As a result, the effect of bolometer steady state temperature variations may significantly degrade the dynamic range and signal-to-noise ratio of bolometer output signals with respect to the radiation of interest.

Accordingly, as discussed above, imaging systems employing thermal sensors including bolometers typically require some type of thermal stabilization mechanism, as illustrated for example by the TE cooler 28 shown in Fig. 1. Such thermal stabilization mechanisms generally are employed to maintain the sensor at a predetermined temperature in an effort to minimize any changes in steady state resistance due to steady state changes in bolometer temperature. With reference again for the moment to Fig. 3, once the bolometer array sensor is thermally stabilized, the bolometers may be appropriately biased such that average output signals from the bolometers, once amplified by the PA 58, fall approximately in the middle of the available range of the A/D 62. This type of biasing generally affords the maximum dynamic range for bolometer output signals corresponding to radiation of interest within the performance limitations of the PA 58 and the A/D 62.

However, as discussed further below, Applicants have recognized that, as an alternative to thermal stabilization (or in addition to some degree of thermal stabilization) of bolometer array sensors, various operating and/or calibration parameters of the bolometers may be varied to compensate for steady state resistance changes

- 15 -

resulting from temperature variations of the bolometer. Accordingly, one embodiment of the present invention is directed to methods and apparatus for compensating operating parameters and/or output signals of a radiation sensor including an array of bolometers for temperature variations of the bolometers that are not due to radiation of interest, 5 without necessarily employing thermal stabilization techniques for the sensor (e.g., without using a TE cooler). In one aspect, the methods and apparatus of this embodiment allow the temperature of the sensor to freely vary, and provide continuous thermal compensation feedback through dynamic adjustments to various operating and calibration parameters associated with the sensor. For purposes of this disclosure, 10 "operating parameters" associated with a sensor generally refer to signals applied to the sensor during normal operation of the sensor to bias the sensor, while "calibration parameters" associated with a sensor generally refer to various parameters that may be used for processing output signals from the sensor to adjust for non-uniformities amongst individual radiation detectors of the sensor. Of course, it should be appreciated that the 15 various compensation concepts discussed herein relating to sensors including bolometers may be applied more generally to sensors employing other types of radiation detectors as well.

More specifically, Applicants have appreciated that by varying one or both of the bolometer DC bias current and DC bias voltage in response to bolometer temperature 20 variations so as to compensate for changes in steady state resistance, a suitable dynamic range and signal-to-noise ratio of bolometer output signals may be maintained. Additionally, Applicants have appreciated that by varying both of the bolometer bias current and bias voltage in a complementary manner, an essentially constant bias power may be maintained. By maintaining an essentially constant bias power, changes in the 25 bolometer bias voltage or current themselves do not significantly contribute to or exacerbate changes in the bolometer temperature.

In addition to changes in steady state resistance due to steady state or gradual changes in bolometer temperature, Applicant's have also identified a bolometer "self-heating" effect that may change bolometer temperature locally on a relatively 30 instantaneous time scale, irrespective of whether or not thermal stabilization techniques are employed to stabilize the steady state temperature of the sensor. This self-heating effect also may contribute to undesirable components in output signals from the

- 18 -

Yet another operating characteristic of a sensor including a bolometer array that may change as a function of temperature relates to a response or "gain" of each bolometer in the array. For example, the response to radiation of interest of one bolometer compared to another bolometer at a given array temperature (referred to hereafter as a "calibration temperature") may be different. This variation in response from bolometer to bolometer at a given calibration temperature is referred to for purposes of this disclosure as "gain error." Since a bolometer essentially measures the temperature of an object of interest relative to an average temperature of the scene being imaged, the gain of a bolometer may be expressed as $(\Delta V_{\text{bol}}/\Delta T_{\text{obj}})_{T_{\text{cal}}}$, where V_{bol} indicates the output digital voltage from an A/D 62 representing a signal of interest from a selected bolometer, T_{obj} indicates the temperature of the object of interest in the scene that emits radiation incident to the bolometer, and T_{cal} indicates the calibration temperature at which the bolometer array is held to measure the gain. Accordingly, each bolometer may be associated with a particular gain value, and a set of gain values for a sensor including an array of bolometers at a particular calibration temperature is referred to herein as a "gain map." The gain values of the gain map are used as calibration parameters, in a manner similar to that of the offset error values of the offset map discussed above, to adjust output signals of an array relative to each other.

Similar to offset errors, the gain or response of each bolometer in an array may change as the temperature of the array varies (e.g., from the calibration temperature). Additionally, the change in bolometer gain due to a change in array temperature may be different from bolometer to bolometer. Accordingly, another operational characteristic of a bolometer array that may change as a function of temperature is referred to herein as "gain variation." Again, gain variation for each bolometer may be thought of as a change in the gain value of the bolometer due to a change in array temperature, and may be expressed for purposes of the following discussion as a "gain variation function."

As with the TCR discussed above, it should be appreciated that the gain variation function of the bolometers is not necessarily a linear function of sensor temperature over a wide temperature range; hence, according to various embodiments, a nonlinear function, or suitable linear or piece-wise linear approximations for the gain variation function over a particular range of temperatures, may be derived and employed to compensate for gain variation. For example, according to one embodiment, a single gain

- 16 -

bolometer. In particular, Applicant's have recognized that when a bias voltage or current initially is applied to the bolometer (e.g., when a particular row is selected and the column busses are enabled in Fig. 2), current begins to flow through the bolometer, producing heat. This local heat produced by the bolometer itself in turn changes the resistance of the bolometer, independently of the radiation of interest incident to the
5 bolometer.

In one aspect of the bolometer self-heating effect, the initial flow of current through one bolometer as the bolometer is enabled, followed by the bolometer being disabled and another bolometer being enabled (e.g., according to the scanning process
10 discussed above in connection with Fig. 2), may be approximated by a saw tooth waveform. Accordingly, the bolometer self-heating effect may be thought of as contributing an undesirable time-varying (i.e., AC) waveform component to the bolometer output signals. The magnitude (amplitude) of this undesirable waveform component also may be a function of the steady state bolometer temperature. In view of
15 the foregoing, Applicant's have recognized that by applying a time-varying waveform that is essentially the inverse of the undesirable "self-heating" waveform to one of the bolometer bias current or bias voltage, the self-heating effect can be significantly reduced. According to one embodiment of the invention, the amplitude of such a time-varying compensation waveform is dynamically adjusted as an operating parameter
20 based on variations in the steady state temperature of the bolometer array.

Other examples of operational characteristics of a sensor including an array of bolometers that may change as a function of temperature variations of the sensor relate to non-uniformities amongst the bolometers. For example, the nominal resistance of one bolometer compared to another at a given array temperature may be different (assuming
25 both bolometers receive the same incident radiation, or view a "control" or "reference source"). Given an array of such bolometers, each bolometer may have a different nominal resistance at a given array temperature and viewing a given reference source. This variation in nominal resistance from bolometer to bolometer, with reference to an average nominal resistance of all of the bolometers, is referred to for purposes of this
30 disclosure as an "offset error." Accordingly, each bolometer may be associated with a particular resistance value that reflects that bolometer's offset error. It should be appreciated, however, that this resistance value may be converted to any convenient unit

- 17 -

of measure. For example, since the A/D 62 shown in the figures outputs digital voltage values, for purposes of the following discussion the offset error of each bolometer may be treated as a differential voltage V_{off} corresponding to the offset resistance value. A set of offset error values (e.g., voltages V_{off}) for an array of bolometers that are used as calibration parameters to adjust output signals of an array relative to each other is referred to herein as an "offset map."

Viewing the same reference source, the offset error of each bolometer in an array may change as the temperature of the array varies. Additionally, the change in offset error due to a change in array temperature may be different from bolometer to bolometer. Accordingly, one operational characteristic of a sensor including a bolometer array that may change as a function of temperature is referred to herein as "offset error variation." Again, an offset error variation for each bolometer may be thought of as a change in the offset resistance value of the bolometer due to a change in array temperature, and may be expressed for purposes of the following discussion as a temperature coefficient of resistance (TCR) function dV_{off}/dT_s (or $\Delta V_{\text{off}}/\Delta T_s$), where V_{off} represents the offset resistance and T_s indicates the sensor temperature (i.e., the temperature of the bolometer array).

It should be appreciated that the TCR of the bolometers is not necessarily a linear function of sensor temperature over a wide range of temperatures. However, according to various embodiments of the invention, either a nonlinear function for dV_{off}/dT_s , or suitable linear or piece-wise linear approximations for TCR within a particular range of temperatures ($\Delta V_{\text{off}}/\Delta T_s$), may be derived and employed to compensate for offset error variation. For example, according to one embodiment, one TCR value is derived for each bolometer over an anticipated operating temperature range, wherein an essentially linear TCR dependence on temperature is assumed over this temperature range. A set of such TCR values for the bolometer array (i.e., a "TCR map") subsequently is used to dynamically adjust the corresponding offset error calibration parameters of the respective bolometers, as maintained in an offset map. In other embodiments, nonlinear TCR functions, or interpolation of piece-wise linear approximations for TCR over multiple temperature ranges, may be similarly used to dynamically adjust the offset error calibration parameters stored in the offset map.

- 19 -

adjustment factor that multiplies the gain value of a bolometer based on a difference between a measured sensor temperature and the calibration temperature at which the gain values for the array were originally obtained is derived for each bolometer over an anticipated operating temperature range (i.e., a linear dependence of gain variation on temperature is assumed over this temperature range). A set of such gain adjustment factors for the bolometer array (i.e., a "gain adjust map") subsequently is used to dynamically adjust the gain values (gain calibration parameters) stored in the gain map. In other embodiments, nonlinear gain variation functions, or interpolation of piece-wise linear approximations for gain variation functions, may be similarly used to dynamically adjust the gain calibration parameters stored in the gain map.

In sum, Applicants have identified a number of operating and calibration parameters associated with a sensor including a bolometer array that may be dynamically adjusted as a function of sensor temperature, so as to compensate for changes in operational characteristics of the individual bolometers of the sensor due to temperature variations of the sensor. As outlined immediately above, these parameters may include, but are not necessarily limited to, a DC bias voltage, a DC bias current, and an AC self-heating compensation waveform applied to the bolometers (operating parameters), as well as individual entries of an offset map and a gain map that correct for non-uniformities amongst the bolometers (calibration parameters).

According to various embodiments of the invention, the operating parameters discussed above (i.e., DC bias voltage, DC bias current, and AC self-heating compensation waveform) are "globally" applied to all of the individual bolometers of the sensor, and one or more of these operating parameters may be dynamically adjusted in response to temperature variations of the sensor via analog or digital feedback loop implementations. Additionally, according to various embodiments of the invention, the calibration parameters of one or both of the offset and gain maps discussed above, either alone or in combination with one or more of the operating parameters, may be dynamically adjusted based on temperature variations of the sensor on a bolometer by bolometer basis, using nonlinear offset and gain variation functions, interpolations of piece-wise linear approximations of offset and gain variation, or linear approximations of offset and gain variation. The foregoing concepts are discussed in turn in greater detail below, in connection with Figs. 6-10.

Fig. 6 is a diagram showing a more detailed view of the portion of the imaging system shown in Fig. 3, illustrating one possible implementation of various temperature compensation features, according to one embodiment of the invention. In particular, Fig. 6 demonstrates some basic elements of one example of a primarily analog circuit implementation for dynamic control of various operating parameters associated with a sensor. Of course, it should be appreciated that the invention is not limited to the implementation outlined in Fig. 6, as other implementations are possible, as discussed further below.

In Fig. 6, a generic selected or enabled detector of the sensor 32 (e.g., see Figs. 2 and 3) is shown for purposes of illustration as the resistor 72 coupled to the detector common 68. As discussed above in connection with Figs. 2 and 3, each enabled detector of a selected row is coupled to a corresponding DAC 60 and PA 58 via the column bus 54. Accordingly, Fig. 6 shows the DAC 60 and the PA 58 coupled to the generic detector 72 via the column bus 54. Also as in Figs. 2 and 3, Fig. 6 shows that the DAC 60 receives a global offset 66, and the PA 58 receives a global detector bias 64 and a reference supply voltage V_R 70. Fig 6 also illustrates the A/D 62 and the controller 38, which process digital signals representing signals output by the detector 72 on the column bus 54.

As discussed above in connection with Figs. 2 and 3, according to one embodiment of the invention, the global offset 66, the global detector bias 64, and the voltage V_R 70 are applied similarly to each DAC 60 and each PA 58 associated with the sensor, such that these signals essentially are "common" to all detectors of the array. Hence, although Fig. 6 shows only one DAC and one PA, it should be appreciated that the global offset 66, the global detector bias 64, the voltage V_R 70 may be simultaneously applied to multiple DACs and PAs associated with the sensor.

As illustrated in Fig. 6, the global offset 66, via the DAC 60, determines a bias current I_{BIAS} 81 through the detector 72, while the supply voltage V_R 70 provides a power source to the PA 58 to allow a signal current I_{sig} 83 to flow through the detector 72 in response to radiation of interest incident to the detector. The total current through the detector 72 is indicated in Fig. 6 as I_D . The global detector bias 64 provides a bias voltage for the detector 72 via the PA 58; essentially, as discussed above in connection

- 21 -

with Fig. 5, the PA 58 maintains the column bus 54 at a potential approximately 0.7 Volts above the global detector bias 64.

In general, as discussed above, the bias current and the bias voltage for the detector 72 are selected such that average output signals from the detector, once
5 amplified by the PA 58, fall approximately in the middle of the available range of the A/D 62. This type of biasing generally affords the maximum dynamic range for detector output signals corresponding to radiation of interest within the performance limitations of the PA 58 and the A/D 62. In some cases, the bias current I_{BIAS} 81 required to accomplish this may be significantly greater than the typical signal current I_{sig} 83
10 expected from the detector. For example, in some cases it may result that I_{BIAS} constitutes as much as approximately 99% of the current I_D through the detector, while I_{sig} constitutes merely approximately 1% of the current I_D . It should be appreciated, however, that these exemplary values are provided for purposes of illustration only, and that the invention is not limited in this respect.

15 Fig. 6 also shows various circuitry coupled to the global offset 66, the global detector bias 64, and the supply voltage 70 that is used in a feedback loop configuration to dynamically adjust one or both of the global offset 66 (and hence the detector bias current I_{BIAS} 81) and the global detector bias 64 based on temperature variations of the detector 72. In particular, Fig. 6 shows a current sampler 82A which measures the
20 current being drawn by the PA 58 from the supply voltage V_R 70 to provide the signal current I_{sig} 83 to the detectors of the sensor. As shown in Fig. 6, the current sampler 82A is inserted between a voltage source V_S and a supply voltage terminal of the PA that receives the supply voltage V_R 70. Essentially, the current sampler 82A provides a measure of an instantaneous signal current being drawn by enabled detectors of the
25 sensor; recall that, according to one embodiment, the supply voltage V_R 70 is applied to all of the PAs 58 (e.g., the supply voltage terminals to each of the PAs are tied together), and each PA in turn provides signal current to a corresponding enabled detector of a selected row. Thus, at any given time, the current sampler in this embodiment provides an indication of the total instantaneous signal current being drawn by a selected row of
30 detectors.

Averaged over time, the current measured by the current sampler 82A shown in Fig. 6 may provide an indication of temperature variations of the detector 72 not due to

- 22 -

the radiation of interest. In particular, as discussed above in connection with bolometers, changes in bolometer temperature affect the resistance of the bolometer, which in turn affects the signal current 83 being drawn by the bolometer. Hence, according to one embodiment, an output 87 of the current sampler 82A may be used as an input (or "error signal") to a feedback control loop as an indication of temperature variations of the detector 72.

As illustrated in Fig. 6, the output 87 of the current sampler 82A is coupled to a DC global offset adjust controller 78A and an AC global offset adjust controller 76A. According to one embodiment, the DC global offset adjust controller 78A dynamically varies a DC component of the global offset 66 (and hence a DC component of the detector bias current I_{BIAS} 81) in response to temperature variations of the detector 72, as reflected in the output 87 of the current sampler 82A. Similarly, according to one embodiment, the AC global offset adjust controller 76A dynamically varies an AC component of the global offset 66 (and hence an AC component of the detector bias current I_{BIAS} 81) in response to instantaneous temperature variations of the detector 72 that are not related to radiation of interest incident on the detector, as reflected in the output 87 of the current sampler 82A.

In particular, according to one embodiment, the AC global offset adjust controller 76A of Fig. 6 provides a dynamically adjusted time-varying waveform that compensates for self-heating effects of the detector 72. More specifically, as discussed above and in greater detail below in connection with Fig. 8, as a bias is initially applied to an enabled detector, the output 87 of the current sampler 82A indicates an instantaneous current component related to the initial flow of current through the detector, which begins to produce local heat. In response, the AC global offset adjust controller 76A provides an AC component to the detector bias current I_{BIAS} 81 (e.g., a saw tooth or other time-varying waveform) to compensate for this effect. As illustrated in Fig. 6, according to one embodiment, an output 83 of the AC global offset adjust controller 76A is summed with an output 85 of the DC global offset adjust controller 78A at a summing node 84 to provide the global offset 66.

Fig. 6 also shows that the output 85 of the DC global offset adjust controller 78A is coupled to a global bias adjust controller 80A. According to one embodiment, the global bias adjust controller 80A dynamically adjusts the global detector bias 64 (i.e., the

DC bias voltage applied to the detector 72) based on changes in the DC component of the detector bias current I_{BIAS} 81, as provided by the DC global offset adjust controller 78A. In this manner, the DC global offset adjust controller 78A and the global bias adjust controller 80A maintain an essentially constant bias power for the detector 72.

5 In the embodiment of Fig. 6, the controller 38 may provide various signals to the global bias adjust controller 80A, the DC global offset adjust controller 78A, and the AC global offset adjust controller 76A to facilitate operation of these devices. For example, the controller 38 may provide an HSYNCH signal to the AC global offset adjust controller 76A, so as to control timing of the AC compensation waveform with respect to
10 selection of consecutive rows of detectors in the sensor (e.g., similar to raster scanning, as discussed above). Likewise, the controller 38 also may provide a sample/hold (S/H) control signal to the DC global offset adjust controller 78A, so as to temporarily disable active feedback control of the global offset 66 for various calibration purposes, as discussed further below.

15 Additionally, the controller 38 may provide a bias voltage V_{BIAS} to the global bias adjust controller 80A, which is adjusted by the global bias adjust controller 80A as discussed above to provide the global detector bias 64. For example, in one embodiment, the controller may include (or be associated with) a digital-to-analog converter (not shown in Fig. 6), which receives a digital signal from the controller 38
20 corresponding to a desired bias voltage, and outputs an analog value for the voltage V_{BIAS} .

In the embodiment of Fig. 6, the controller 38 also may monitor the output 85 of the DC global offset adjust controller 78A, which as discussed above is related to the DC component of the detector bias current I_{BIAS} 81. According to one aspect of this
25 embodiment, the controller 38 may use the output 85 as an indication of the temperature of the sensor 32, by calibrating the output 85 based on measurements of sensor temperature. Alternatively, as discussed above in connection with Fig. 1, the controller 38 may directly monitor sensor temperature by receiving as an input a sensor temperature signal 44 output by a temperature sensor located in proximity of the sensor
30 32. In some radiometry applications in which measurements of absolute temperature of objects of interest in a scene are desired, the measurement of sensor temperature provided by either the output 85 of the DC global offset adjust controller 78A or the

sensor temperature signal 44 may be used in radiometric calculations to provide the required level of accuracy for radiometry measurements. It should be appreciated that one or both of the output 85 and the sensor temperature signal 44 may be input to the controller 38 as analog signals and converted, for example, by an analog-to-digital converter in the controller 38 (not shown in Fig. 6) to provide digital representations of these signals.

Finally, Fig. 6 shows that the controller 38 contains a coarse offset map 77 which includes coarse offset digital values 75 that are used to control the DAC 60, so to provide adjustments to the detector bias current I_{BIAS} 81 on a detector-by-detector basis, as discussed briefly above in connection with Fig. 3. These adjustments relate to non-uniformities amongst the detectors of the sensor, and are discussed in greater detail below in connection with Fig. 10.

Fig. 7 is a diagram showing examples of analog circuit implementations for the current sampler, DC global offset adjust controller, and global bias adjust controller of Fig. 6, according to one embodiment of the invention. It should be appreciated that these examples are provided for purposes of illustration only, and that the invention is not limited to the particular circuits shown in Fig. 7. In Fig. 7, the current sampler 82A and the DC global offset adjust controller 78A are implemented in a circuit that performs both functions. In particular, resistors R9 and R10 form an adjustable voltage divider, which places a portion of the source voltage V_S on the non-inverting input of amplifier AR2. Accordingly, this voltage also appears on the inverting input of AR2. Resistor R8 hence essentially provides the current sampling function; as the average current drawn from the supply voltage V_R 70 changes due to temperature variations of the sensor, the current flowing through the resistor R8 changes. The amplifier AR2 in turn varies the output current 85 provided to the summing node 84 shown in Fig. 6 based on the changes in current through R8. Transistor Q5 is controlled by the S/H control signal from the controller 38; when the transistor Q5 is "disabled," the resistor R8 is disconnected from the amplifier AR2, and the capacitor C8 serves as a hold capacitor. When the transistor Q5 is "enabled", resistor R8 and capacitor C8 determine the response time of the DC global offset adjust feedback loop; according to one embodiment, values for these components are selected such that the response time of the loop is several image frames (e.g., several scans of the sensor) so as to reduce image artifacts. Capacitor C7 provides

- 25 -

a low impedance to AC signal components in the average current drawn from the supply voltage V_R 70, so that these components do not significantly affect the DC global offset adjust feedback loop.

In Fig. 7, the global bias adjust controller 80A is implemented by a circuit including amplifier AR3, which samples the DC current output 85. The resistors R11, R12, and R13 and the capacitors C9 and C10 provide gain and filtering of the sampled signal. In the exemplary circuit shown in Fig. 7, increases in the output current 85 (corresponding to increases in the detector bias current I_{BIAS}) cause some proportional decrease in the global detector bias 64. Hence, the circuits shown in Fig. 7 tend to act so as to keep a sum of the detector bias current and bias voltage constant, rather than keeping the product of the bias current and voltage constant (so as to maintain essentially constant detector power). However, over a relatively limited or small range of detector powers, regulating the sum rather than the product of detector bias current and voltage provides adequate control of detector power according to this embodiment.

Fig. 8 is a diagram showing an example of an analog circuit implementation for the current sampler and AC global offset adjust controller of Fig. 6, according to one embodiment of the invention. It should be appreciated that these examples are provided for purposes of illustration only, and that the invention is not limited to the particular circuit shown in Fig. 8. Similar to Fig. 7, in Fig. 8 the current sampler 82A and the AC global offset adjust controller 76A are implemented in a circuit that performs both functions. In particular, in Fig. 8, R1 is a low value (e.g., 10 Ohm) resistor, and the voltage drop across R1 is a measure of the average current drawn by bolometers of the array. Capacitor C1 is a high frequency bypass for resistor R1. A high gain AC amplifier comprising C2, Q1, Q2, R2, R3 and R4 amplify the AC (instantaneous) component of the current drawn by a row of detectors coupled to the supply voltage V_R 70. The amplified AC component is then detected by a synchronous rectifier comprising C3 and Q3. The output of the synchronous rectifier is integrated by AR1, R5, and C4. The output voltage of the integrator controls the current through resistor R6. Capacitor C6 is periodically reset to a high voltage at an appropriate time by an analog switch connected to the point labeled open_d. When the voltage at open_d is not applied, capacitor C6 discharges at a rate determined by the current through R6, thereby generating an essentially saw tooth waveform. The waveform generated by this process

- 26 -

is then provided as an output 83 via transistor Q4, and ultimately is AC coupled into the summing node 84 shown in Fig. 6. The polarity of the feedback loop represented by the circuit in Fig. 8 is selected such that the AC component of the average current drawn by the bolometers from the supply voltage V_R 70 is reduced to approximately zero during the initial bias time of the detectors, thereby compensating for the self-heating effects discussed above.

Fig. 9 is a diagram similar to Fig. 6 showing a more detailed view of the portion of the imaging system shown in Fig. 3, illustrating another possible implementation of various temperature compensation features, according to one embodiment of the invention. In particular, Fig. 9 demonstrates some basic elements of one example of a primarily digital implementation for dynamic control of various operating parameters associated with a sensor.

In the embodiment of Fig. 9, essentially the controller 38 monitors various input signals and outputs various signals so as to implement closed feedback loop control of detector bias current and bias voltage in a manner similar to that discussed above in connection with Fig. 6. In particular, it should be appreciated that the controller 38 may be programmed in a variety of manners so as to execute one or more algorithms to implement such control. In one aspect of this embodiment, the controller 38 may include a number of analog-to-digital converters (not explicitly shown in Fig. 9) to digitize one or more signals input to the controller that are not already in digital form; for example, while the signals 40 received by the controller 38 from the A/D 62 are in digital form, the controller 38 may include one or more analog-to-digital converters to convert the output 87 from the current sampler 82B or the sensor temperature signal 44 to digital form. Similarly, according to one embodiment, the AC global offset adjust controller 76B, the DC global offset adjust controller 78B and the global bias adjust controller 80B each may include a digital-to-analog converter that receives digital output signals from the controller 38 and converts these signals to an analog voltage or current.

The embodiment of Fig. 9 provides a significantly versatile solution to feedback control of the various sensor operating parameters based on temperature variations of the sensor. For example, the controller 38 may monitor the average steady state temperature of the sensor by either monitoring the sensor temperature signal 44, the output 87 of the

- 27 -

current sampler 82B, or periodically calculating an average detector output signal based on any number of the individually sampled digital detector output signals provided by the A/D 62, and monitoring any changes in this calculated signal. Any of these approaches may provide an input or "error signal" to the feedback loop. Additionally, 5 the controller may monitor instantaneous changes in the current drawn by detectors of the sensor from the supply voltage V_R 70 by sampling the output 87 of the current sampler 82B at an appropriate rate to acquire and store data related to detector self-heating.

Based on any of the foregoing sampled input signals, the controller 38 may 10 flexibly control one or more of the AC global offset adjust controller 76A, the DC global offset adjust controller 78B and the global bias adjust 80B by merely outputting a digital value to these devices corresponding to the desired control. In particular, the controller 38 may be specifically programmed such that the DC global offset adjust controller dynamically maintains an appropriate bias current for the detectors based on measured 15 temperature variations of the sensor, the global bias adjust controller 80B dynamically adjusts the global detector bias such that a product of the detector bias current and bias voltage remains essentially constant (so as to maintain an essentially constant detector power), and a timing and amplitude of a time-varying waveform generated by the AC global offset adjust controller 76B is dynamically adjusted based on the data acquired by 20 sampling the output 87 of the current sampler 82B.

Fig. 10 is a block diagram showing a more detailed view of a portion of the controller 38, illustrating one possible implementation of various temperature compensation features relating to calibration parameters associated with the sensor, according to one embodiment of the invention. In particular, Fig. 10 demonstrates some 25 basic elements of one example of a calibration parameter compensation algorithm implemented by the controller 38. Of course, it should be appreciated that the invention is not limited to the algorithmic implementation outlined in Fig. 10, as other algorithmic implementations are possible, as discussed further below.

As discussed above, a number of calibration parameters associated with a sensor 30 including a detector array may be dynamically adjusted as a function of sensor temperature, so as to compensate for changes in operational characteristics of the sensor due to temperature variations of the sensor. These calibration parameters may include,

- 28 -

but are not necessarily limited to, individual entries in an offset map and a gain map that correct for non-uniformities amongst the detectors. Some of the operational characteristics of the sensor that change due to temperature variations of the sensor relate to changes in the offset error and gain of individual detectors; these changes were referred to earlier as "offset variation" and "gain variation." According to one embodiment of the invention, such offset variation and gain variation with sensor temperature necessitate dynamic adjustments of the calibration parameters constituting the offset and gain maps when thermal stabilization of the sensor is not employed (e.g., a TE cooler is not used in the system). According to another embodiment, even if thermal stabilization of the sensor is employed, dynamic adjustments of calibration parameters also may be employed to improve accuracy and reliability of the imaging system.

In view of the foregoing, according to various embodiments of the invention, the calibration parameters contained in one or both of the offset and gain maps, either alone or in combination with one or more of the operating parameters discussed above, may be dynamically adjusted based on temperature variations of the sensor on a detector by detector basis. Such adjustments may be accomplished using nonlinear offset and gain variation functions, interpolations of piece-wise linear approximations of offset and gain variation, or linear approximations of offset and gain variation.

In particular, Fig. 10 illustrates an example of a dynamic calibration parameter adjustment algorithm based on linear approximations of offset and gain variation, according to one embodiment of the invention. In particular, according to one embodiment, an initial sensor calibration procedure is executed to obtain a number of calibration parameters related to a coarse offset error, a fine offset error, and a gain for each detector of a sensor. As illustrated in Fig. 10, these parameters are stored respectively in a coarse offset map 77, a fine offset map 108, and a gain map 104.

Additionally, during the calibration procedure, a number of adjustment values are determined that are used subsequently during normal operation to dynamically adjust at least some of the calibration parameters based on changes in sensor temperature. In particular, during the calibration procedure, according to one embodiment, a TCR (temperature coefficient of resistance) value and a gain adjustment factor is determined for each detector of a sensor as a linear approximation of offset error variation and gain

- 29 -

variation, respectively. As also illustrated in Fig. 10, these adjustment values are stored respectively in a TCR map 106 and a gain adjust map 102.

An exemplary calibration procedure to obtain the calibration parameters and determine the adjustment values discussed immediately above is executed as follows, with reference to Figs. 1, 2, 3, and 10. It should be appreciated that this exemplary procedure is provided here for purposes of illustration only, and that the invention is not limited to this particular calibration procedure. Additionally, it should be appreciated that while the calibration procedure outlined below employs two offset maps (namely, a coarse offset map and a fine offset map) to store offset error calibration parameters, the invention is not limited to employing any particular number of offset and gain maps, as numerous implementations of the various concepts discussed herein relating to dynamic adjustment of sensor calibration parameters are possible.

In one exemplary calibration procedure according to the invention, based on a particular temperature range over which it is anticipated that the sensor 32 will be operated, the sensor initially is thermally stabilized at a first temperature within this range, referred to as T_{cal} . Additionally, the shutter 26 shown in Fig. 1 may be positioned so as to essentially block radiation from a scene from impinging on the sensor 32 (i.e., the controller 38 may control the shutter control signal 46 to appropriately activate the shutter and block incident radiation). Alternatively, the sensor 32 may be aimed at a standardized radiating black body at a known temperature to provide a controlled input to the sensor 32.

Once the sensor is thermally stabilized with no input (i.e., shutter closed) or a controlled input, an initial global bias current and global bias voltage is applied to the sensor (e.g., via the global offset 66 and the global detector bias 64, common to all of the detectors), and the controller 38 begins to sequentially read digitized output values from each detector of the sensor via the A/Ds 62. Typically, many of the individual detector digitized output values initially are either significantly above or below a mid-scale value of the A/Ds 62. The variation in these outputs reflects the offset error of the individual detectors at the temperature T_{cal} . The controller 38 scans the sensor a number of times, and with each scan adjusts and applies a coarse offset digital value 75 for each detector (maintained in the coarse offset map 77) to an appropriate one of the DACs 60, so to adjust the individual detector bias current such that each detector output approximates a

mid-scale value of the A/Ds 62. In this manner, the controller 38 executes a coarse offset calibration, or coarse "zeroing" of the sensor on an detector-by-detector basis. The final coarse offset digital values 75 that accomplishes this coarse zeroing are stored in the coarse offset map 77. This process is referred to as "coarse" offset calibration because, according to one embodiment, the number of bits employed by the DACs 60 to make adjustments to the individual detector bias currents so as to bring the respective digitized detector output signals to approximately mid-scale of the A/Ds 62 typically is less than the number of bits used by the A/Ds 62 to digitize the amplified detector output signals.

Once the coarse offset calibration is completed, typically the individual detector signals are still not quite at a mid-scale value of the A/Ds 62. Accordingly, the controller 38 repeats the scanning process at T_{cal} to compile a fine offset map 108, as shown in Fig. 10. Essentially, the controller 38 acquires several digital output samples from each detector (corrected for coarse offset) via the A/Ds 62, averages the samples, and stores this average as a calibration parameter for each detector in the fine offset map 108. During normal operation of the sensor (i.e., after the initial calibration procedure is completed), the respective fine offset values are used to make fine adjustments to the sampled digital outputs of corresponding detectors so as to further compensate for non-uniformities amongst the detectors.

Next, while the sensor temperature is still maintained at T_{cal} , the sensor 32 is aimed at a standardized black body radiating at a first known object temperature, T_{obj1} . Again, the controller 38 scans the array, applies the coarse and fine offset calibration parameters to each detector, and records the digitized output signal of each detector at T_{obj1} . Subsequently, the sensor 32 is aimed at a standardized black body radiating at a second known object temperature T_{obj2} , and the controller 38 again scans the array, applies the coarse and fine offset parameters to each detector, and records the digitized output signal of each detector at T_{obj2} . The controller 38 then calculates the gain of each detector by dividing the difference in digitized output signals of each detector at the two object temperatures by the difference in object temperatures ΔT_{obj} , and stores this calibration parameter for the detector as an entry in the gain map 104 shown in Fig. 10. During normal operation (i.e., after the initial calibration procedure is completed), this gain value is used as a calibration parameter to make adjustments to the sampled digital

output signals of the detector so as to further compensate for non-uniformities amongst the detectors.

At this point in the exemplary calibration procedure, the temperature T_{cal} at which the sensor is initially stabilized is changed to a new temperature, T_{cal2} , so that the controller 38 may determine the adjustment factors (i.e., TCRs and gain adjustment factors) that are ultimately used as linear approximations of offset error variation and gain variation in the embodiment of Fig. 10 to compensate (e.g., dynamically adjust) the individual calibration parameters of the fine offset map 108 and the gain map 104 based on temperature variations of the sensor. It should be appreciated that offset error and gain for a given type of detector do not necessarily vary similarly with temperature variations of the sensor; for example, with respect to bolometers, offset error variation generally is significantly more sensitive than gain variation as a function of sensor temperature. Accordingly, the choice of a particular second sensor stabilization temperature T_{cal2} for the calibration procedure may depend on the degree of accuracy desired by the linear approximations of offset error variation and gain variation for a given anticipated operating temperature range of the sensor. Notwithstanding the particular choice of T_{cal2} , the determination of the various (e.g., TCR and gain) adjustment factors may be understood conceptually as follows.

At T_{cal2} , the controller 38 repeats the procedure discussed above for obtaining fine offset values (i.e., with the shutter closed or with the sensor viewing a standardized black body radiating at a known temperature) to compile a new set of fine offset values at the sensor temperature T_{cal2} . The controller then calculates the TCR value for each detector by dividing the difference in fine offset values at T_{cal} and T_{cal2} for each detector by the temperature difference between T_{cal} and T_{cal2} , and stores the TCR values for respective detectors in the TCR map 106 shown in Fig. 10. In this embodiment, as discussed above, each TCR value may be thought of conceptually in units of $\Delta V_{off}/\Delta T_s$, where ΔV_{off} represents the difference in fine offset values for a given detector, and ΔT_s indicates the variation in sensor temperature (i.e., $|T_{cal2} - T_{cal}|$).

Similarly, at T_{cal2} , the controller 38 repeats the procedure discussed above for obtaining gain values (i.e., using two standardized black bodies radiating at different known temperatures T_{obj1} and T_{obj2}) to compile a new set of gain values at the sensor temperature T_{cal2} . The controller then calculates the gain adjustment factor for each

- 32 -

detector by taking the ratio of the gain values at T_{cal} and T_{cal2} , and dividing the ratio by the temperature difference between T_{cal} and T_{cal2} . This gain adjustment factor for each detector is then stored in the gain adjust map 102 shown in Fig. 10. In this embodiment, each gain adjustment factor of the gain adjust map 102 may be thought of conceptually
5 as a gain multiplier divided by $|T_{cal2} - T_{cal}|$.

Once the controller 38 has completed building the various maps discussed above, the exemplary calibration procedure is essentially completed, and thereafter the imaging system may be operated without necessarily requiring thermal stabilization of the sensor 32, according to one embodiment of the invention. In particular, according to one aspect
10 of this embodiment, the controller 38 may dynamically update the calibration parameters of the fine offset map 108 using the corresponding TCR values of the TCR map 106, and may dynamically update the calibration parameters of the gain map 104 using the corresponding gain adjustment factors of the gain adjust map 102, by evaluating temperature variations of the sensor 32 based on a variety of criteria.

For example, according to one embodiment of the invention, the controller may periodically operate the shutter 26 via a shutter controller 98 (that outputs the shutter control signal 46) to block incident radiation to the sensor 32, at which time the controller recalculates (i.e., updates) each of the calibration parameters of the fine offset map 108 by scanning the sensor, as discussed above. In one aspect of this embodiment,
20 the periodic operation of the shutter to perform this procedure may be based on a predetermined time interval. In yet another aspect, as illustrated in Fig. 10, the operation of the shutter may be based on a difference in sensor temperature from the last operation of the shutter.

More specifically, as illustrated in the embodiment of Fig. 10, the sensor
25 temperature signal 44 output by the temperature sensor 36 shown in Fig. 1 is digitized by an analog-to-digital converter 90, and the controller 38 maintains a record 94 of the digitized sensor temperature at each shutter operation. The controller 38 also may be programmed with a predetermined threshold temperature difference value 92, which may be used to activate the shutter. In particular, in the embodiment of Fig. 10, the shutter
30 comparator 96 compares the predetermined threshold temperature difference value 92 to the difference 110 (ΔT) between the present digitized sensor temperature and the record 94 of the sensor temperature at the last shutter operation; if this difference 110 exceeds

the value 92, the shutter comparator 96 activates the shutter controller 98 so as to operate the shutter 26, at which point the controller 38 updates the fine offset map 108 by scanning the sensor as discussed above. In this manner, the fine offset map 108 is periodically updated based on sensor temperature variations.

5 Between shutter operations (i.e., between updates of the fine offset map 108 by a sensor rescan), the controller 38 may nonetheless continually adjust and update both the fine offset map 108 and the gain map based on the difference between a present sensor temperature and the sensor temperature at the previous shutter operation. For example, as illustrated in Fig. 10, the temperature difference 110 between the present sensor
10 temperature and the sensor temperature at the previous shutter operation may be used to multiply individual entries of the TCR map 106, which are then used to update the individual entries in the fine offset map 108. Similarly, a signal 112 representing the difference between the present sensor temperature and the calibration temperature 100 (i.e., T_{cal}) may be used to multiply individual entries of the gain adjust map 102, which
15 are then used to update the individual entries in the gain map 104. In this manner, the frequency of shutter operations to update the fine offset map 108 by a sensor rescan may be reduced (e.g., the predetermined threshold temperature difference value 92 may be set at a higher value).

 While the embodiment discussed above in connection with Fig. 10 discusses
20 updates to a fine offset map to dynamically adjust offset error calibration parameters for offset error variation, it should be appreciated that the invention is not limited in this respect. Namely, in other embodiments, compensation algorithms for dynamic adjustment of offset error calibration parameters may perform such adjustments using the coarse offset map 77 shown in Fig. 10, or both the coarse offset map 77 and the fine
25 offset map 108. Alternatively, as discussed above, compensation algorithms for dynamic adjustment of offset error calibration parameters according to other embodiments of the invention may compile, maintain, and update a single offset map based on the general concepts discussed above.

 Additionally, while the embodiment discussed above in connection with Fig. 10
30 involves linear approximations of offset error variation and gain variation to dynamically adjust the calibration parameters of the fine offset map and the gain map using a TCR map and a gain adjust map, respectively, it should be appreciated that the invention is not

limited in this respect. Namely, the general concepts discussed above may be employed to implement compensation algorithms according to other embodiments of the invention that use interpolation of piece-wise linear approximations of offset error variation and gain variation to compensate for these variations. Moreover, the general concepts discussed above may be employed to implement compensation algorithms according to other embodiments of the invention that determine and utilize offset error variation and gain variation as nonlinear functions of sensor temperature to compensate for these variations. Furthermore, it should be appreciated that according to yet other embodiments, one of a nonlinear function, interpolation of piece-wise linear approximations, or a linear approximation may be employed by a compensation algorithm to compensate for offset error variation, while a different one of a nonlinear function, interpolation of piece-wise linear approximations, or a linear approximation may be employed by the compensation algorithm to compensate for gain variation.

For example, regarding nonlinear functions for offset error variation and gain variation, according to one embodiment of the invention, a significant number of offset maps and gain maps may be compiled by the controller 38 (as discussed above) at a number of different sensor calibration temperatures. Essentially, each offset map and each gain map provides a "sample" of a nonlinear function of offset error variation and gain variation, respectively. Accordingly, it should be appreciated that the greater number of samples acquired (i.e., the greater number of offset and gain maps compiled by the controller 38), the more accurate the sampled representation of the functions are. While in some cases the compilation of several offset and gain maps during a calibration procedure may prove to be a memory and computation intensive process, this scheme may nonetheless provide a viable and effective alternative for precision compensation of offset error variation and gain variation. During normal operation following such a calibration procedure, the particular offset and gain map that the controller 38 uses at any given time to adjust the digitized output signals of respective detectors of the sensor may be selected as a function of the present sensor temperature (e.g., as measured via the sensor temperature signal 44).

Alternatively, another embodiment of the invention relates to dynamic compensation of calibration parameters by interpolation of piece-wise linear approximation of offset error variation and gain variation. In this embodiment, similar to

the nonlinear function embodiment discussed immediately above, a smaller number (e.g., two to five) of offset maps or TCR maps, as well as gain maps, may be compiled by the controller 38 at a number of different sensor calibration temperatures throughout an anticipated temperature operating range for the sensor. Using a smaller number of maps or “samples” of the respective variation functions essentially creates a piece-wise linear approximation of the functions. In particular TCR maps may be compiled at different temperature sub-ranges of an overall anticipated operating range to provide interpolations of piece-wise linear approximations of offset error variation.

In this embodiment, once such maps are compiled during a calibration procedure, they may be employed during normal operation again based on a measured present sensor temperature. For example, two gain maps and two TCR maps may be selected, wherein one of each type of map was compiled at or near a calibration temperature close to but below the present sensor temperature, and the other of each type of map was compiled at a calibration temperature close to but above the present sensor temperature. The controller 38 may then calculate the difference between corresponding entries of the two gain maps and the two TCR maps, and determine an interpolated adjustment value for each of gain and offset based on the present sensor temperature and the ΔT_{cal} between the two maps of each type (ΔT_{cal} would be “weighted” by the present sensor temperature). These interpolated adjustment values may then be applied to respective entries of each of the offset map and gain map, as discussed above.

In yet another embodiment of the present invention, with reference again to Fig. 1, thermal stabilization components (e.g., the TE cooler 28) are employed to thermally stabilize the sensor 32 selectively at various predetermined temperatures as a function of the ambient temperature in the proximity of the sensor, as indicated by the ambient temperature signal 45. Although thermal stabilization components are employed in this embodiment, power consumption of these components is nonetheless significantly reduced according to the invention by dynamically selecting one of several predetermined stabilization temperatures that is in the vicinity of the measured ambient temperature.

For example, with respect to TE coolers, the power consumption of a TE cooler generally is a function approximately of the square of the temperature difference between the ambient temperature in proximity of the TE cooler and the desired (set-point)

- 36 -

temperature of the TE cooler. Accordingly, power consumption of the TE cooler may be significantly reduced if the difference between the TE cooler set point and the ambient temperature is reduced. Additionally, in Fig. 1, generally the electronic signals through the sensor itself warms the sensor to some temperature above the ambient temperature in proximity of the sensor (e.g., approximately 10 to 20 degrees Celsius above ambient). According to one embodiment of the invention, the foregoing factors are taken into consideration to strategically reduce power consumption of a TE cooler thermally coupled to a sensor during operation of the sensor.

In one aspect of this embodiment, a number of sensor temperature/TE cooler set-points are predetermined based on an anticipated ambient temperature operating range over which the sensor will be used. For example, according to one embodiment, the ambient temperature range over which the sensor may be used is from approximately -40 degrees Celsius to +60 degrees Celsius (i.e., an approximately 100 degree Celsius range). This temperature range is then divided into a number of sub-ranges, for example, three sub-ranges of approximately 30 degrees Celsius each. Within each of these sub-ranges, a sensor temperature/TE cooler set-point is chosen that approximately minimizes the power consumption of the TE cooler over the sub-range. For example, according to one embodiment, a set-point for each sub-range is chosen by taking the center temperature within the range and adding approximately 10 degrees to it (to account for electronic signal "warm-up" of the sensor).

Once the TE cooler set-points are identified (i.e., in the above example, three predetermined set-points are chosen), various operating and calibration parameters associated with the sensor initially are measured or determined during a calibration procedure (e.g., as discussed above), wherein each of the predetermined TE cooler set-points serves as a different calibration temperature. For example, in the above scenario using three predetermined set-points, during a calibration procedure one offset map and one gain map would be compiled at each set-point, for a total of three offset maps and three gain maps. Additionally, at each TE cooler set-point, an optimum global offset (detector bias current), global detector bias (detector bias voltage), and self-heating compensation waveform may be determined.

According to one aspect of this embodiment, during subsequent operation of the sensor after such a calibration procedure, the controller 38 continuously monitors the

- 37 -

ambient temperature, and selects one of the TE cooler set-points that will significantly reduce power consumption of the TE cooler based on the difference between the ambient temperature and the selected set-point. Fig. 11 is a diagram of a portion of the controller 38, showing various components of a temperature stabilization feedback loop according to one embodiment of the invention. In Fig. 11, a set-point select controller 152 monitors the ambient temperature signal 45, and outputs the selected set-point 150 based on the available set-points and the monitored ambient temperature. An amplifier/comparator 156 compares the selected set-point 150 to the present sensor temperature 44 to produce an error signal 158 for the temperature stabilization feedback loop. This error signal 158 is further processed by various conditioning circuitry 160 that provides loop filtering and gain and outputs the temperature control signal 48 to the TE cooler.

In Fig. 11, the set-point select controller 152 also provides the selected set-point 150 to a calibration parameter select controller 154, which then selects the appropriate offset and gain maps (shown in Fig. 11 in the map table with entries OM1, OM2, OM3, GM1, GM2, GM3, etc.) to be used by the controller 38 as calibration parameters. While not shown explicitly in Fig. 11, according to one embodiment, the calibration parameter select controller 154 also may indicate or select the appropriate operating parameters (e.g. bias current and voltage and self-heating compensation waveform) that the controller 38 applies to the sensor at respective TE cooler set-points.

In accordance with the invention, feedback temperature control may be provided in response to any combination of one or more of sensor temperature monitor 44, ambient temperature monitor 45, and a subset of or all of the digital image signals 40.

Compensation of the sensor can be provided in response to any combination of a temperature variation of the sensor, a change in the ambient temperature of the environment (but not the chip), and a change in the digital output of the sensor (but not in the chip). This compensation can be provided continuously, only when the shutter is being calibrated, or only when the shutter is not being calibrated.

Having thus described at least one illustrative embodiment of the invention, various alterations, modifications, and improvements will readily occur to those skilled in the art. Such alterations, modifications, and improvements are intended to be part of this disclosure, and are intended to be within the spirit and scope of the invention.

- 38 -

Accordingly, the foregoing description is by way of example only and is limited only as defined in the following claims and the equivalents thereto.

What is claimed is:

CLAIMS

1. A method of compensating a radiation sensor for changes in at least one
5 operational characteristic of the sensor due to a temperature variation of the sensor,
comprising an act of:

dynamically adjusting at least one of at least one operating parameter associated
with the radiation sensor and at least one calibration parameter associated with the
radiation sensor based on the temperature variation of the sensor.

10

2. The method of claim 1, wherein the at least one operational characteristic
of the sensor that changes due to the temperature variation of the sensor includes a
resistance of the sensor.

15

3. The method of claim 1, wherein the at least one operating parameter
associated with the sensor includes at least one of a DC bias voltage applied to the
sensor, a DC bias current applied to the sensor, and an AC bias waveform applied to the
sensor.

20

4. The method of claim 1, wherein the sensor includes a plurality of
radiation detectors, and wherein the at least one calibration parameter associated with the
sensor includes at least one of an offset error value for each radiation detector and a gain
value for each radiation detector.

25

5. The method of claim 4, wherein the at least one operational characteristic
of the sensor that changes due to the temperature variation of the sensor includes at least
one of an offset error variation and a gain variation.

30

6. An apparatus, comprising:
a controller to compensate a radiation sensor for changes in at least one
operational characteristic of the sensor due to a temperature variation of the sensor, the
controller dynamically adjusting at least one of at least one operating parameter

- 40 -

associated with the radiation sensor and at least one calibration parameter associated with the radiation sensor based on the temperature variation of the sensor.

7. The apparatus of claim 6, wherein the at least one operational
5 characteristic of the sensor that changes due to the temperature variation of the sensor includes a resistance of the sensor.

8. The apparatus of claim 6, wherein the at least one operating parameter
includes at least one of a DC bias voltage applied to the sensor, a DC bias current applied
10 to the sensor, and an AC bias waveform applied to the sensor.

9. The apparatus of claim 6, wherein the sensor includes a plurality of
radiation detectors, and wherein the at least one calibration parameter associated with the
sensor includes at least one of an offset error value for each radiation detector and a gain
15 value for each radiation detector.

10. The apparatus of claim 9, wherein the at least one operational
characteristic of the sensor that changes due to the temperature variation of the sensor
includes at least one of an offset error variation and a gain variation.

20

11. A method of compensating a radiation sensor for changes in at least one
operational characteristic of the sensor due to a temperature variation of
the sensor, comprising:

dynamically adjusting at least one operating parameter associated with the
25 radiation sensor or at least one calibration parameter associated with the radiation sensor
based on the temperature variation of the sensor.

12. An apparatus, comprising:
a controller to compensate a radiation sensor for changes in at least one
30 operational characteristic of the sensor due to a temperature variation of the sensor, the
controller dynamically adjusting at least one operating parameter associated with the

- 41 -

radiation sensor or at least one calibration parameter associated with the radiation sensor based on the temperature variation of the sensor.

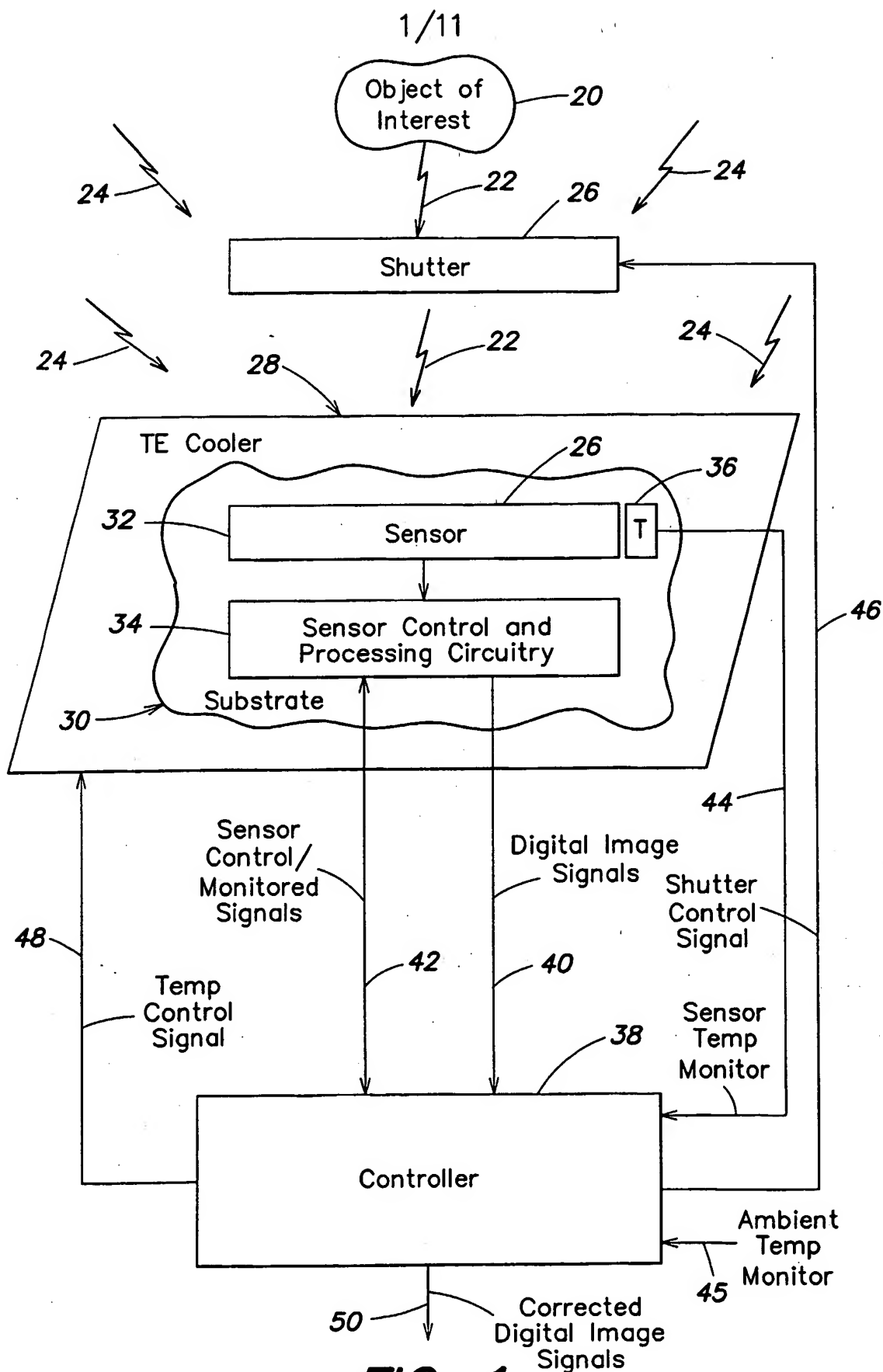


FIG. 1
SUBSTITUTE SHEET (RULE 26)

3/11

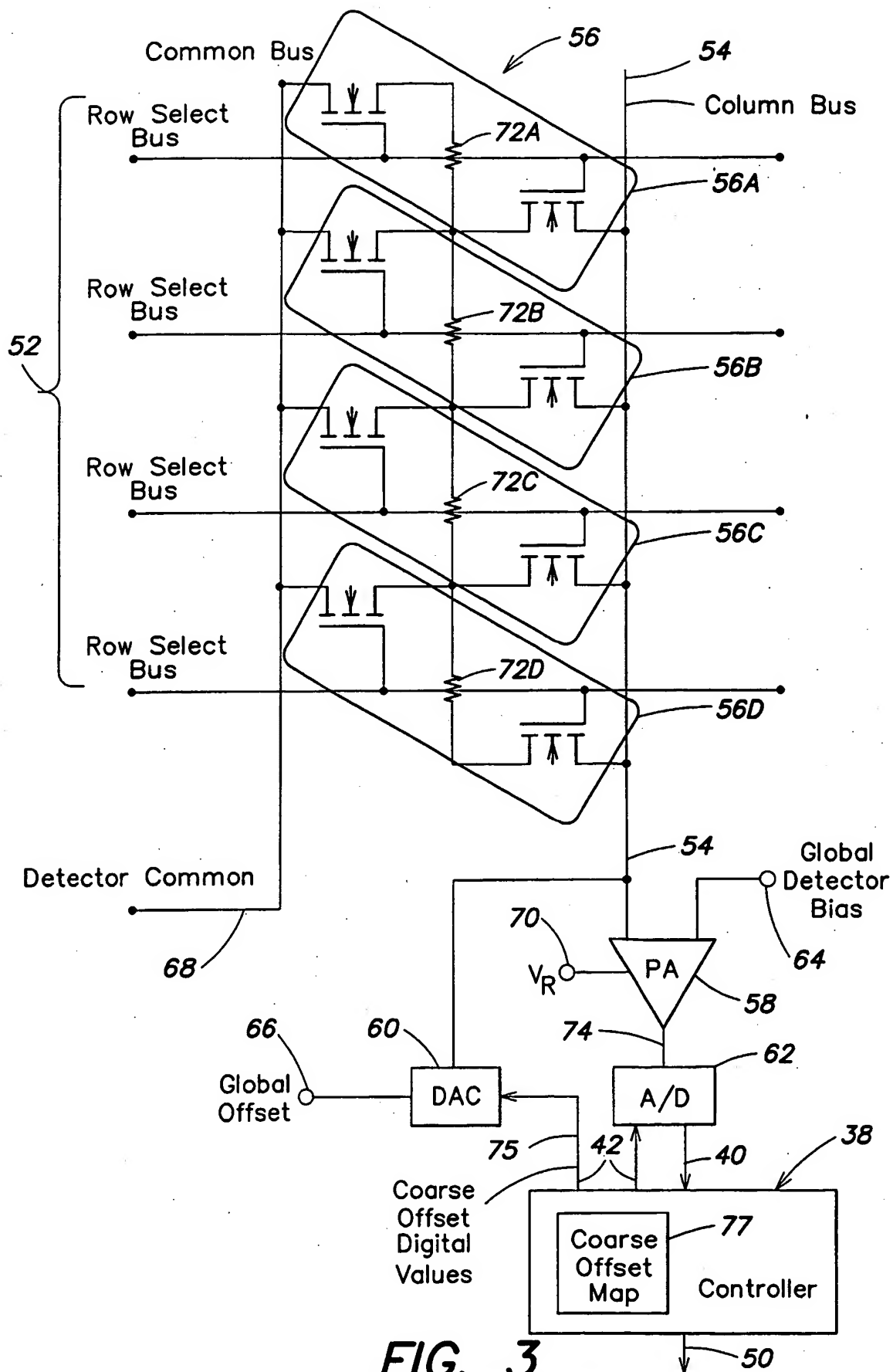


FIG. 3
SUBSTITUTE SHEET (RULE 26)

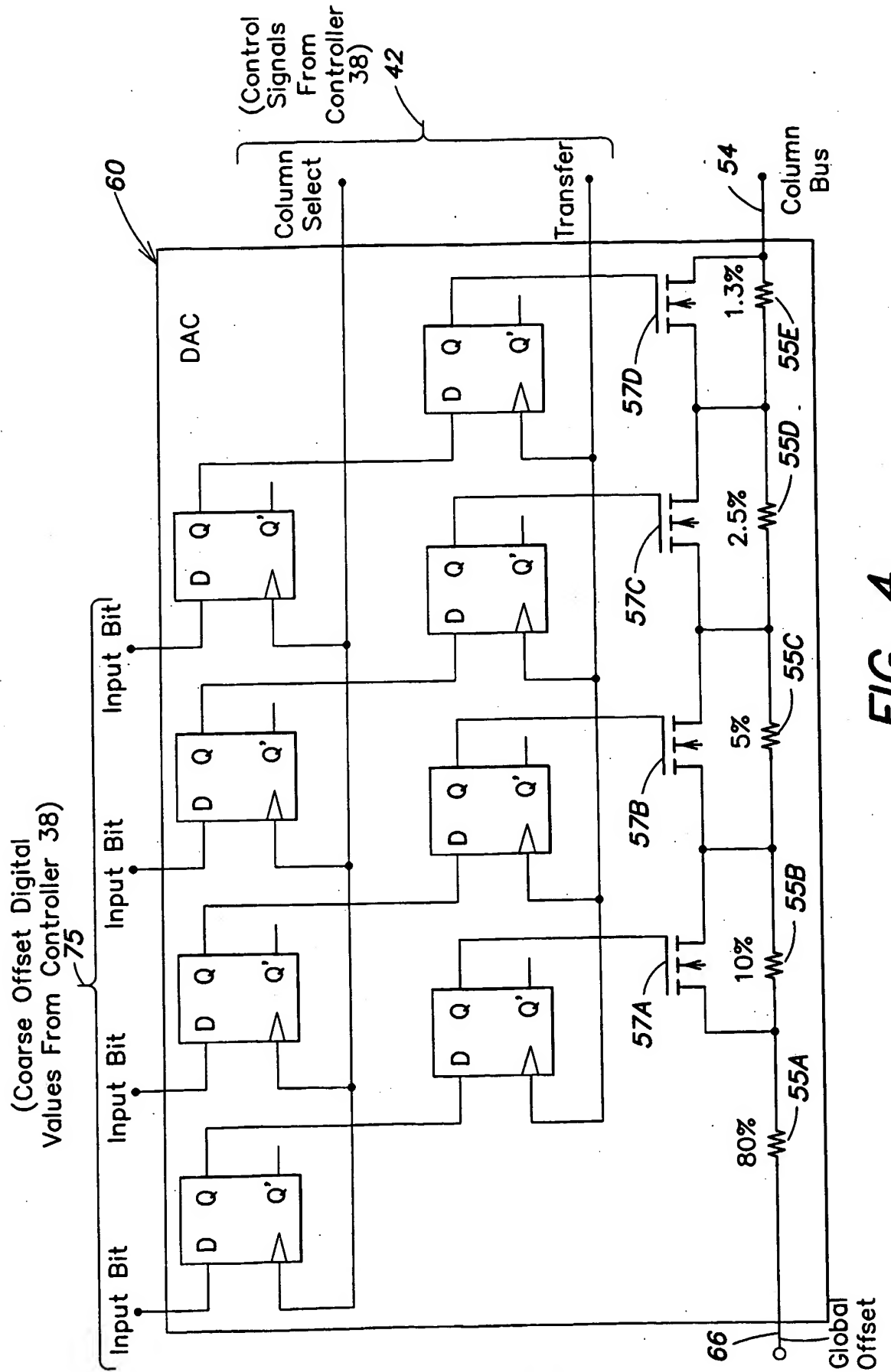


FIG. 4

SUBSTITUTE SHEET (RULE 26)

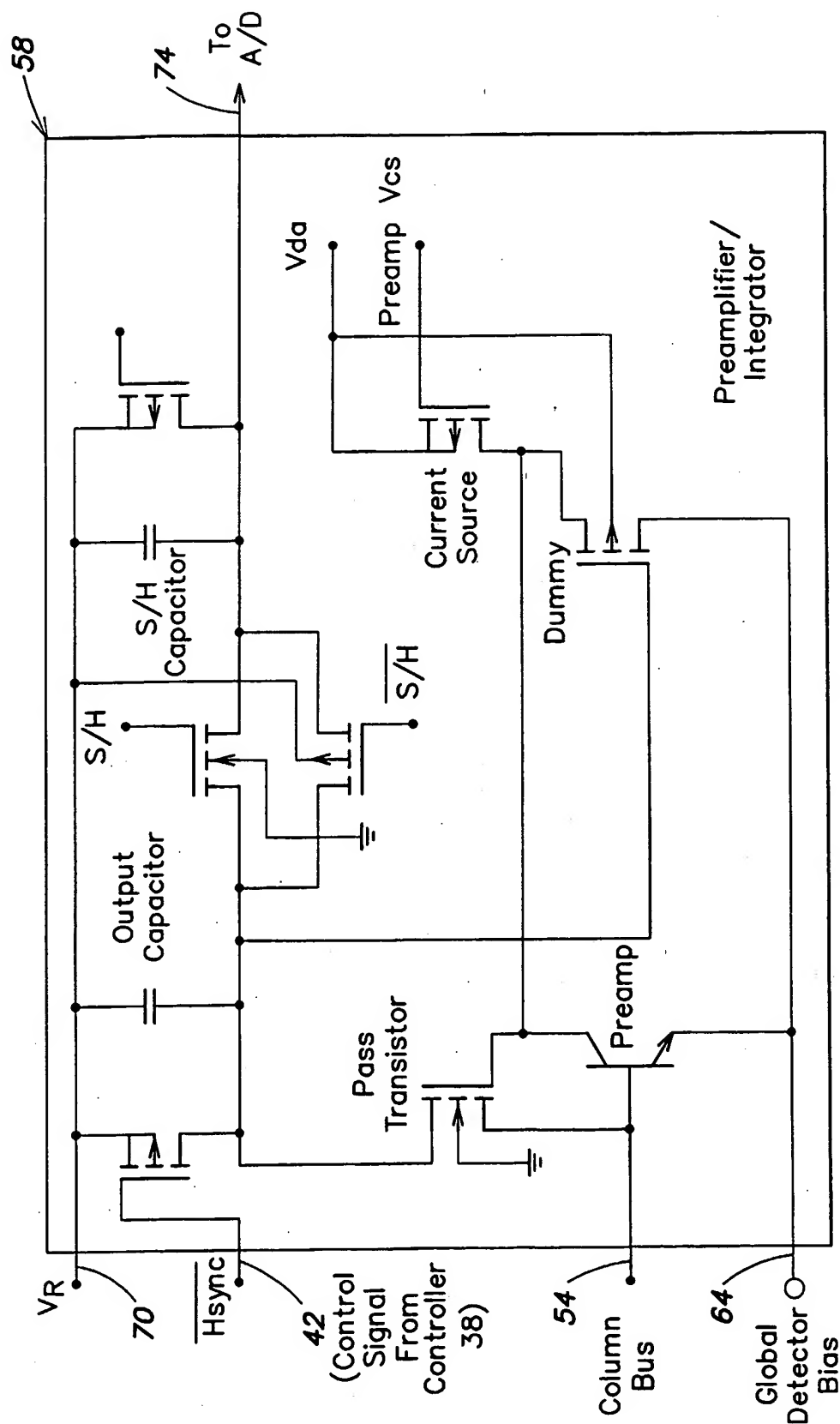


FIG. 5

SUBSTITUTE SHEET (RULE 26)

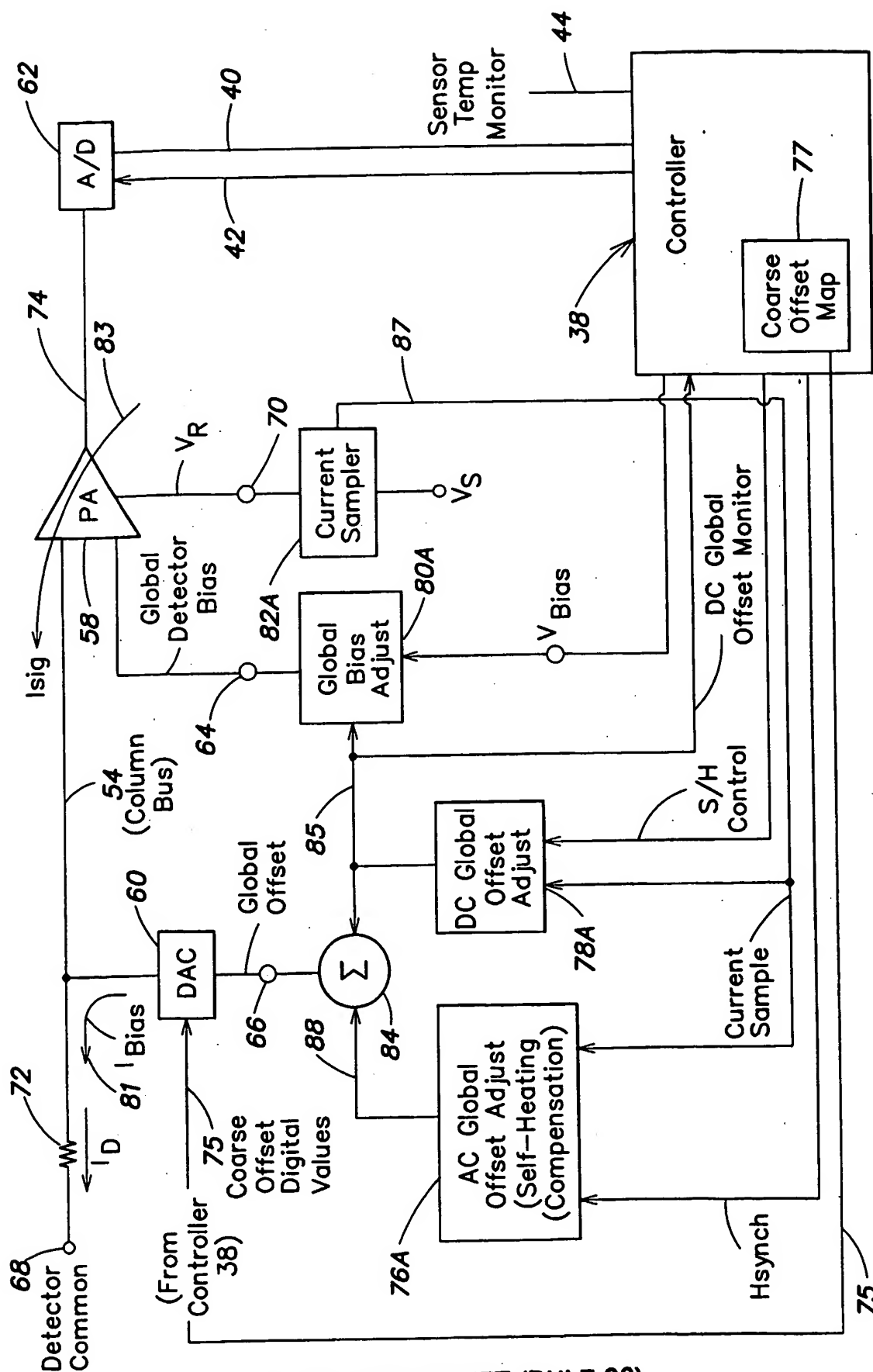


FIG. 6

SUBSTITUTE SHEET (RULE 26)

7/11

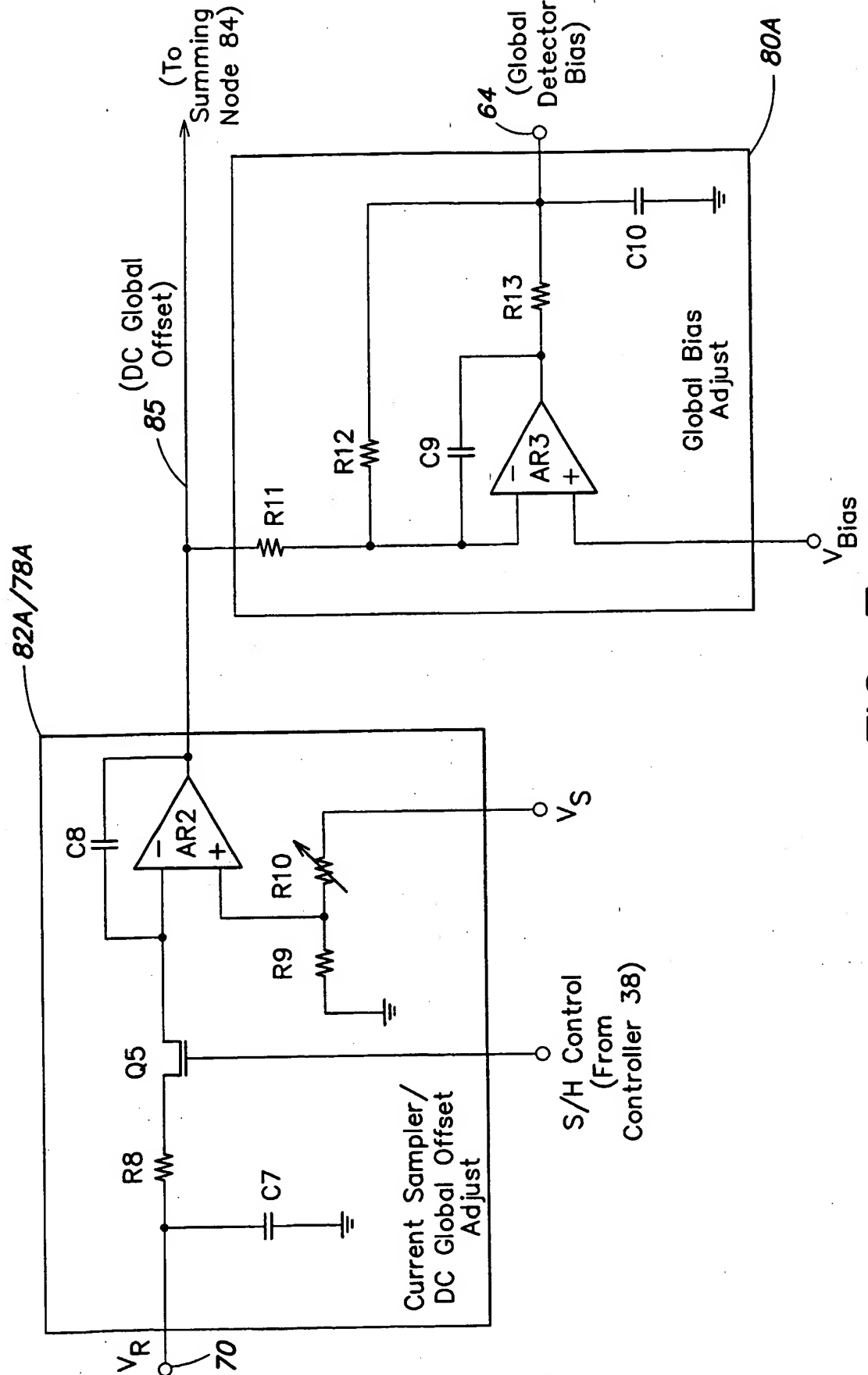
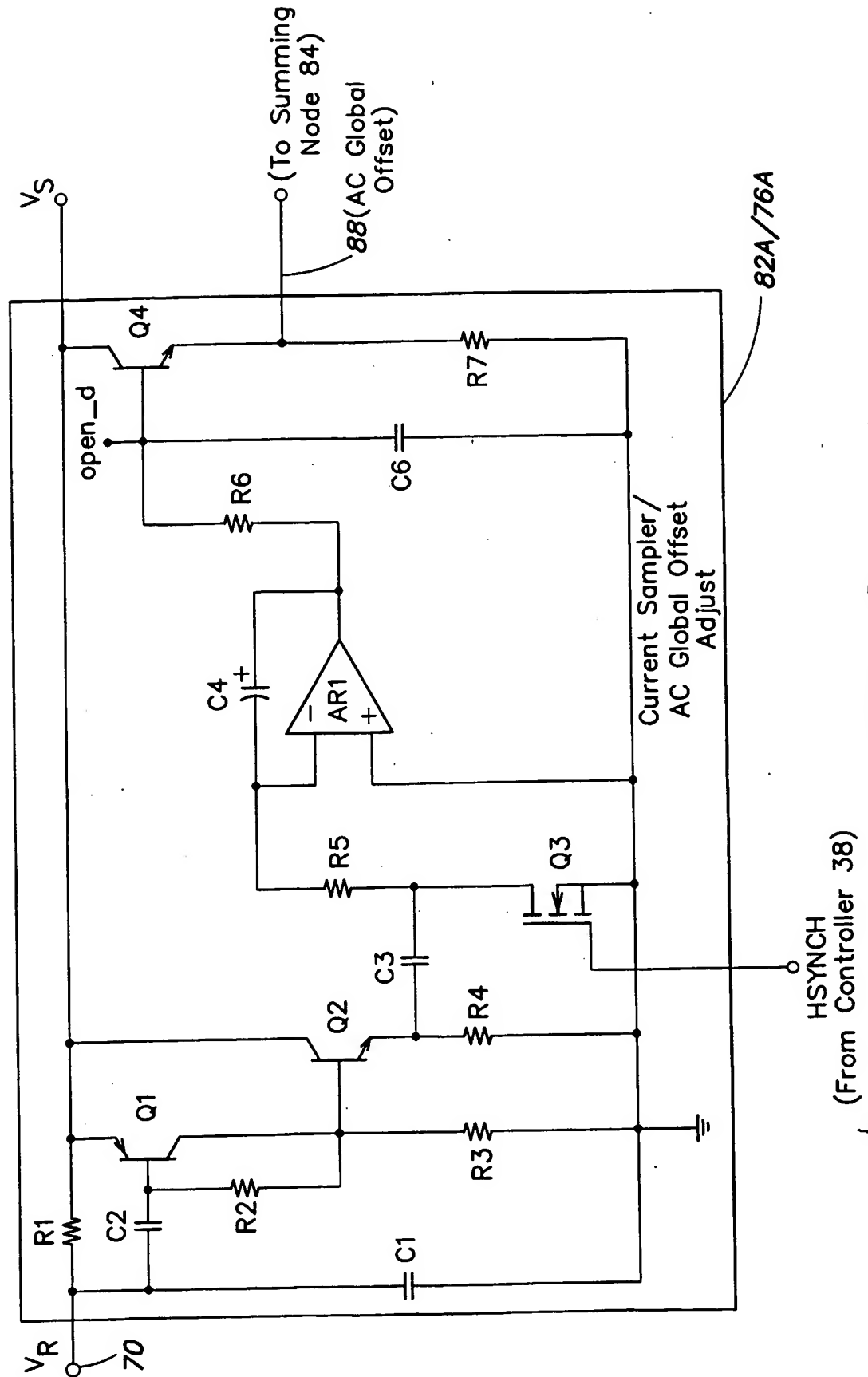


FIG. 7

SUBSTITUTE SHEET (RULE 26)



SUBSTITUTE SHEET (RULE 26)

9/11

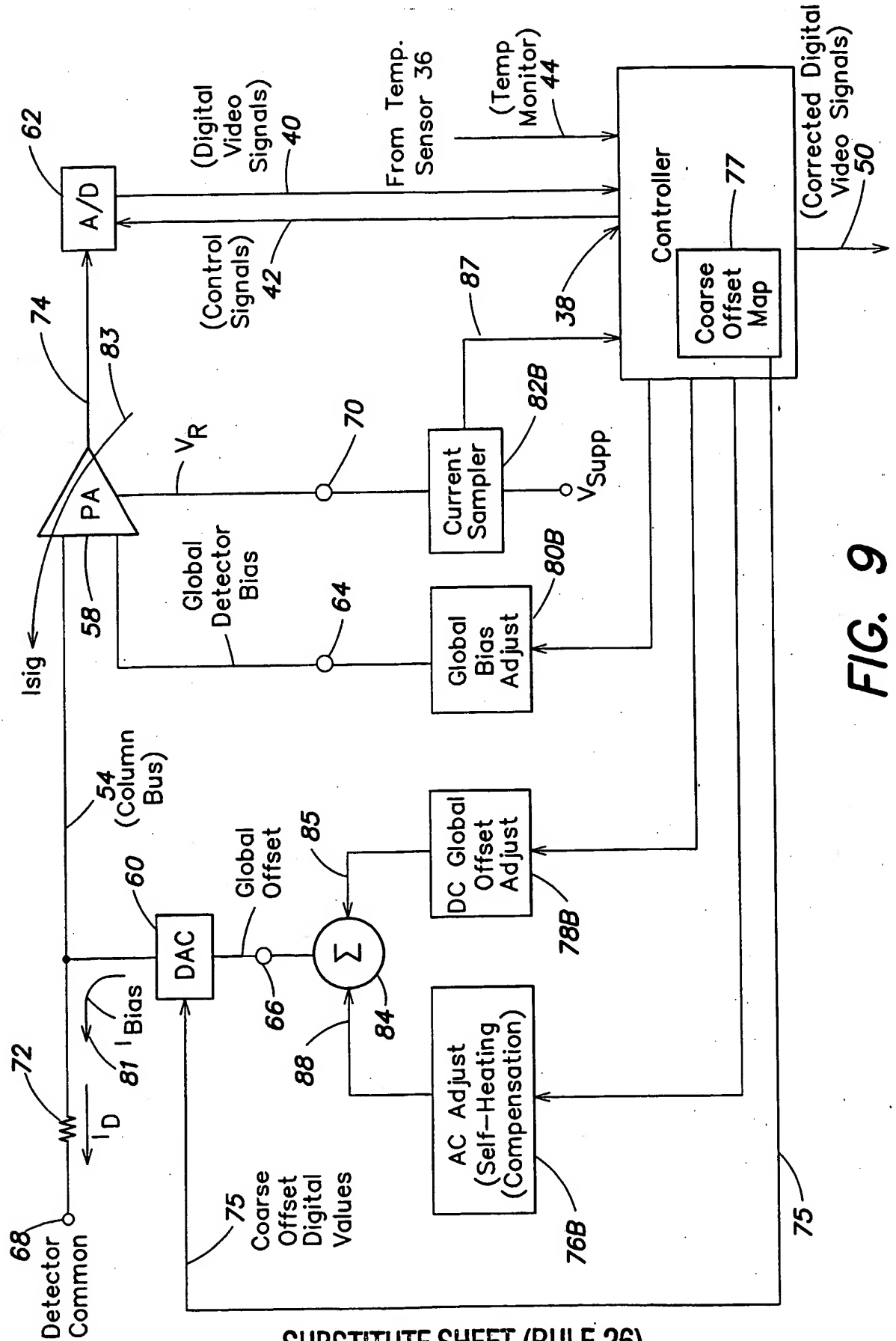


FIG. 9

SUBSTITUTE SHEET (RULE 26)

10/11

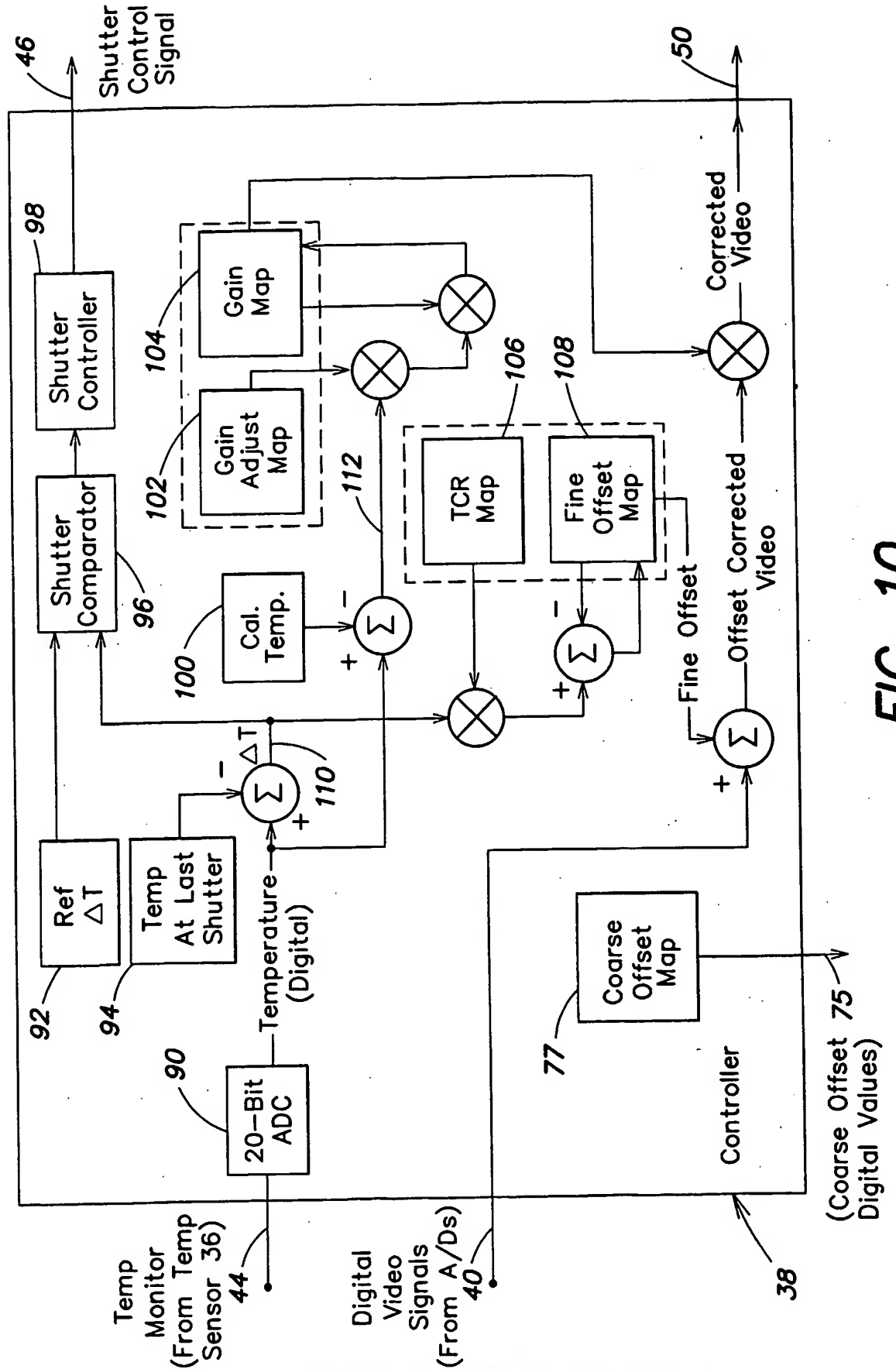


FIG. 10

SUBSTITUTE SHEET (RULE 26)

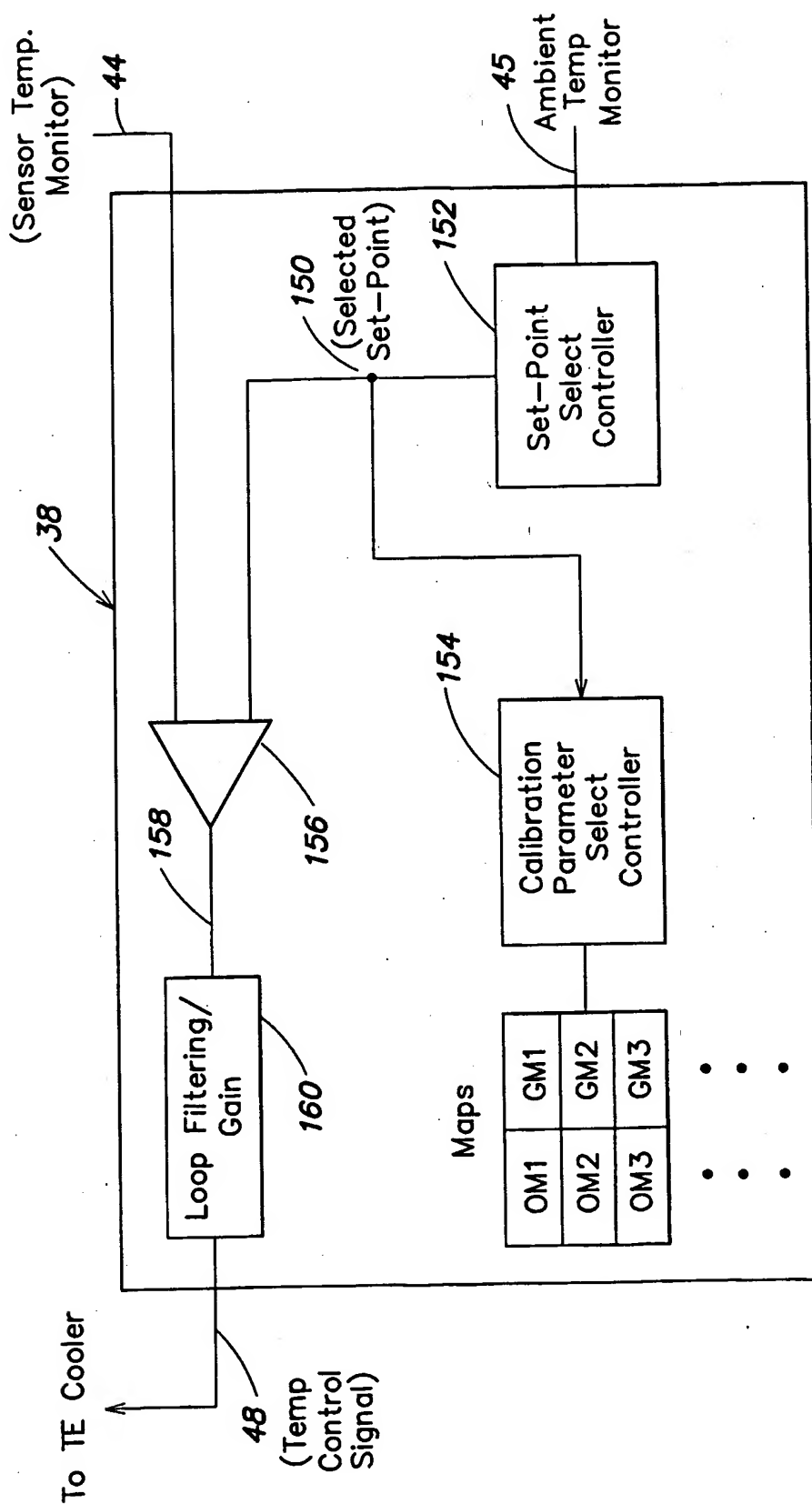


FIG. 11

INTERNATIONAL SEARCH REPORT

International Application No

PCT/US 01/13612

A. CLASSIFICATION OF SUBJECT MATTER
IPC 7 G01J5/20

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)
IPC 7 G01J

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

EPO-Internal

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X A X	WO 98 35212 A (INDIGO SYSTEMS CORP) 13 August 1998 (1998-08-13) page 16, line 2 - page 19, line 16; figures page 18, line 25 - line 27 page 18, line 28 - line 31 -----	1,4-6, 9-12 3,8 2,7

☐ Further documents are listed in the continuation of box C.☒ Patent family members are listed in annex.

* Special categories of cited documents:

- *A* document defining the general state of the art which is not considered to be of particular relevance
- *E* earlier document but published on or after the international filing date
- *L* document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)
- *O* document referring to an oral disclosure, use, exhibition or other means
- *P* document published prior to the international filing date but later than the priority date claimed

- *T* later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention
- *X* document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone
- *Y* document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art.
- *G* document member of the same patent family

Date of the actual completion of the international search

21 December 2001

Date of mailing of the international search report

07/01/2002

Name and mailing address of the ISA
European Patent Office, P.B. 5818 Patentlaan 2
NL - 2280 HV Rijswijk
Tel. (+31-70) 340-2040, Tx. 31 651 epo nl,
Fax: (+31-70) 340-3016

Authorized officer

Ramboer, P

INTERNATIONAL SEARCH REPORT

Information on patent family members

International Application No

PCT/US 01/13612

Patent document cited in search report		Publication date		Patent family member(s)	Publication date
WO 9835212	A	13-08-1998	US	5756999 A	26-05-1998
			US	6028309 A	22-02-2000
			AU	6263498 A	26-08-1998
			EP	1007920 A1	14-06-2000
			WO	9835212 A1	13-08-1998
<hr/>					

Form PCT/ISA/210 (patent family annex) (July 1992)

CORRECTED VERSION

(19) World Intellectual Property Organization
International Bureau



(43) International Publication Date
8 November 2001 (08.11.2001)

PCT

(10) International Publication Number
WO 01/084118 A3

(51) International Patent Classification⁷: G01J 5/20

(72) Inventor: BUTLER, Neal, R.; 144 School Street, Acton, MA 01710 (US).

(21) International Application Number: PCT/US01/13612

(74) Agent: MORRIS, James, H.; Wolf, Greenfield & Sacks, P.C., 600 Atlantic Avenue, Boston, MA 02210 (US).

(22) International Filing Date: 27 April 2001 (27.04.2001)

(81) Designated States (*national*): IL, JP.

(25) Filing Language: English

(84) Designated States (*regional*): European patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, TR).

(26) Publication Language: English

(30) Priority Data:
60/201,577 1 May 2000 (01.05.2000) US

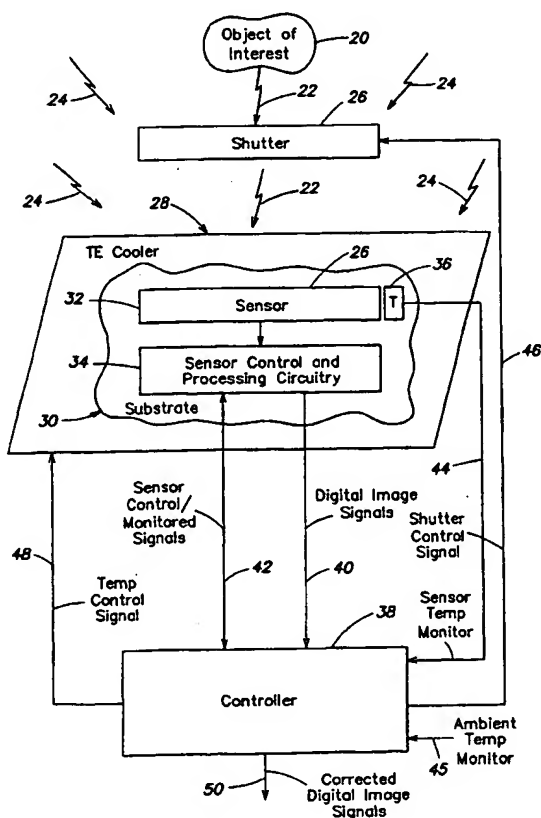
Published:
— with international search report

(71) Applicant: BAE SYSTEMS INFORMATION AND ELECTRONIC SYSTEMS INTEGRATION INC. [US/US]; 65 Spit Brook Road, Nashua, NH 03061 (US).

(88) Date of publication of the international search report:
4 April 2002

[Continued on next page]

(54) Title: METHODS AND APPARATUS FOR COMPENSATING A RADIATION SENSOR FOR TEMPERATURE VARIATIONS OF THE SENSOR



(57) Abstract: In one example, the radiation sensor is a thermal sensor having at least one property that varies as a function of temperature. The thermal sensor outputs signals based on thermal radiation of interest from a particular radiating body in its view. These signals may contain significant undesirable components due in part to changes in temperature of the sensor itself. Methods and apparatus of the invention compensate the sensor for temperature variations of the sensor that are not due to the radiation of interest, so as to significantly reduce undesirable components in the instantaneous signals output by the sensor. In one example, this is accomplished without thermally stabilizing the sensor itself (i.e., dynamic temperature compensation). In another example, the sensor is thermally stabilized selectively at various predetermined temperatures as a function of the ambient temperature in the proximity of the sensor.

WO 01/084118 A3



(48) Date of publication of this corrected version:

10 April 2003

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

(15) Information about Corrections:

see PCT Gazette No. 15/2003 of 10 April 2003, Section II

Previous Correction:

see PCT Gazette No. 05/2003 of 30 January 2003, Section II

5 This application claims the benefit of U.S. Provisional Application Serial No. 60/201,577, filed May 1, 2000, entitled AMBIENT TEMPERATURE OPERATION OF MICROBOLOMETER FOCAL PLANE ARRAYS, which application is hereby incorporated herein by reference.

The present invention generally relates to radiation sensors, and in particular, to compensating operating parameters and/or output signals of radiation sensors for changes in temperature of the sensors.

A radiation detector is a device that produces an output signal which is a function of an amount of radiation that is incident upon an active region of the radiation detector. Radiation detectors may be designed and constructed to be sensitive to particular regions of the electromagnetic spectrum. For example, infrared detectors are radiation detectors that are sensitive to radiation in the infrared region of the electromagnetic spectrum. One example of an infrared detector includes a thermal detector, which detects radiation based upon a change in the temperature of an active region of the detector due to absorption of radiation incident to the detector.

BNSDOCID: <WO_____018411BA3_IB>

One issue in connection with at least some types of radiation detectors is that often it may be challenging to separate those signals output by the detector that are actually due to radiation of interest incident to the detector from various undesirable components which may be present in the detector output signals. For example, detector
5 output signals may include various undesirable components due to variations in temperature of the detector itself that are not necessarily due to the radiation of interest.

In particular, temperature changes in the vicinity of the detector that may affect the temperature of the detector, sometimes referred to as ambient temperature variations (e.g., changes in temperature of a substrate on which the detector is fabricated, changes
10 in temperature of a package in which the detector is housed, average temperature changes in a scene of interest itself), in turn may cause undesirable components to be present in the detector output signals. In some cases, these undesirable components may be hundreds of times larger than the instantaneous signals resulting from the radiation of interest, thereby detrimentally reducing the dynamic range of the detector and/or
15 processing circuitry associated with the detector with respect to the radiation of interest.

In view of the foregoing, some conventional imaging systems employing imaging sensors comprising a number (e.g., array) of radiation detectors require some type of temperature stabilization of the detectors to reduce such undesirable components in the detector output signals. In particular, with respect to conventional thermal imaging
20 systems, it is generally thought to be impractical to operate such systems without active stabilization of the temperature of the detectors. In some cases, thermal stabilization components may include a thermoelectric cooler (hereinafter, "TE cooler") which is thermally coupled to the detectors (e.g., the substrate on which the detectors are fabricated is mounted on the TE cooler) to hold the detectors at a predetermined
25 temperature. Depending on the difference between the predetermined stabilization temperature and the actual ambient temperature in the vicinity of the detectors, the TE cooler may consume appreciable power resources of the imaging system.

30

Summary of the Invention

- 3 -

One embodiment of the invention is directed to a method of compensating a radiation sensor for changes in at least one operational characteristic of the sensor due to a temperature variation of the sensor. The method comprises an act of dynamically adjusting at least one operating parameter associated with the radiation sensor and/or at least one calibration parameter associated with the radiation sensor based on the temperature variation of the sensor.

According to one aspect of this embodiment, the at least one operational characteristic of the sensor that changes due to the temperature variation of the sensor includes a resistance of the sensor.

According to another aspect of this embodiment, the at least one operating parameter associated with the sensor includes at least one of a DC bias voltage applied to the sensor, a DC bias current applied to the sensor, and an AC bias waveform applied to the sensor.

According to another aspect of this embodiment, the sensor includes a plurality of radiation detectors, and the at least one calibration parameter associated with the sensor includes at least one of an offset error value for each radiation detector and a gain value for each radiation detector.

According to another aspect of this embodiment, the sensor includes a plurality of radiation detectors, and the at least one operational characteristic of the sensor that changes due to the temperature variation of the sensor includes at least one of an offset error variation and a gain variation.

Another embodiment of the invention is directed to an apparatus, comprising a controller to compensate a radiation sensor for changes in at least one operational characteristic of the sensor due to a temperature variation of the sensor. The controller dynamically adjusts at least one operating parameter associated with the radiation sensor and/or at least one calibration parameter associated with the radiation sensor based on the temperature variation of the sensor.

Brief Description of the Drawings

Fig. 1 is a diagram showing a portion of an imaging system according to one embodiment of the invention;

Fig. 2 is a diagram showing a portion of an integrated sensor array and some associated signal processing circuitry used in the imaging system of Fig. 1, according to one embodiment of the invention;

Fig. 3 is a diagram showing a more detailed view of a portion of the sensor array
5 illustrated in Fig. 2, according to one embodiment of the invention;

Fig. 4 is a diagram showing one example of a digital-to-analog converter used in the processing circuitry shown in Figs. 2 and 3, according to one embodiment of the invention;

Fig. 5 is a diagram showing one example of a preamplifier/integrator used in the
10 processing circuitry shown in Figs. 2 and 3, according to one embodiment of the invention;

Fig. 6 is a diagram showing a more detailed view of the portion of the imaging system shown in Fig. 3, illustrating one possible implementation of various temperature compensation features, according to one embodiment of the invention;

Fig. 7 is a diagram showing examples of a current sampler/DC global offset
15 adjust circuit and a global bias adjust circuit as analog circuit implementations of the temperature compensation features shown in Fig. 6, according to one embodiment of the invention;

Fig. 8 is a diagram showing an example of a current sampler/AC global offset
20 adjust circuit as an analog circuit implementation of a sensor self-heating temperature compensation feature shown in Fig. 6, according to one embodiment of the invention;

Fig. 9 is a diagram showing a more detailed view of the portion of the imaging system shown in Fig. 3, illustrating another implementation of various temperature compensation features, according to one embodiment of the invention;

Fig. 10 is a block-diagram showing one example of a portion of a compensation
25 algorithm implemented by a controller of the imaging system of Fig. 1, according to one embodiment of the invention; and

Fig. 11 is a diagram of a portion of a controller of the imaging system of Fig. 1, showing various components of a temperature stabilization feedback loop according to
30 one embodiment of the invention.

Detailed Description

As discussed above, a radiation sensor outputs signals based on radiation that impinges on the sensor. Such a sensor may be used in an imaging system that produces images (e.g., on a display) based on radiation incident to the sensor from a scene of interest. The sensor output signals, however, may contain significant undesirable components due in part to changes in temperature of the sensor itself that are not necessarily due to the radiation of interest. In some cases, these undesirable signal components may be hundreds of times larger than the instantaneous signals resulting from the radiation of interest in the scene being imaged, thereby detrimentally reducing the dynamic range of the sensor and/or processing circuitry associated with the sensor with respect to the radiation of interest.

With respect to undesirable signal components, changes in temperature of the sensor that are not related to the radiation of interest may have an average effect over time (i.e., a DC drift in the sensor output signals). Such changes in temperature may be related to ambient temperature variations, such as a change in temperature of a substrate on which the sensor is fabricated, a change in temperature of a package in which the sensor is housed, or a change in the average temperature of the scene of interest around the sensor. Additionally, Applicants have recognized that essentially instantaneous (i.e., AC) undesirable signal components may be observed due to "self-heating" of the sensor, for example, when a bias voltage initially is applied to the sensor and current begins to flow through the sensor, producing heat. Furthermore, individual detectors of a detector array constituting an imaging sensor each may respond differently to temperature variations, creating undesirable signal components due to detector non-uniformities.

In view of the foregoing, the present invention is directed generally to methods and apparatus for compensating operating parameters and/or output signals of a radiation sensor for temperature variations of the sensor that are not due to radiation of interest. The compensation provided by various embodiments of methods and apparatus of the invention significantly reduces undesirable components in the instantaneous signals output by the sensor. In one aspect of the present invention, the radiation sensor is an infrared thermal imaging sensor including an array of thermal detectors, such as bolometers. It should be appreciated, however, that the invention is not limited in this

- 6 -

respect, as various compensation methods, apparatus, and concepts discussed herein may be applied generally to a variety of sensors and detection devices.

In one embodiment, methods and apparatus of the invention provide compensation for temperature variations of a sensor without thermally stabilizing the sensor itself; in particular, the sensor is allowed to freely vary in temperature and is dynamically compensated for temperature variations. In one aspect of this embodiment, one or more operating and/or calibration parameters associated with the sensor are dynamically determined or updated based on temperature variations of the sensor, and used to dynamically compensate for changes in operational characteristics of the sensor due to the temperature variations of the sensor. Essentially, in one aspect, the methods and apparatus of this embodiment provide continuous thermal compensation feedback without thermal stabilization of the sensor through dynamic operating and/or calibration parameter adjustments.

Some examples of operating parameters associated with the sensor that may be dynamically adjusted based on sensor temperature variations according to one embodiment of the invention include, but are not limited to, an average (i.e., DC) bias current of the sensor, a bias voltage of the sensor, and a waveform and amplitude of an AC signal used to compensate for sensor self-heating. Additionally, for imaging sensors including an array of detectors, examples of calibration parameters that may be dynamically adjusted based on sensor temperature variations include individual detector offset and response (gain) coefficients that account for differences in operating characteristics from detector to detector.

The foregoing approach of temperature compensation without thermal stabilization constitutes a significant departure from conventional thermal imaging techniques, which generally require active stabilization of sensor temperature. Thus, methods and apparatus of the invention according to one embodiment facilitate the design of a thermal imaging system that does not necessarily require thermal stabilization components (e.g., a thermoelectric cooler), thereby providing for reduced system power consumption and potential production cost savings.

In another embodiment of the present invention, thermal stabilization components are employed to thermally stabilize a radiation sensor selectively at various predetermined temperatures as a function of the ambient temperature in the proximity of

- 7 -

the sensor. Although thermal stabilization components are employed in this embodiment, power consumption of these components is nonetheless significantly reduced according to the invention by dynamically selecting one of several predetermined stabilization temperatures that is in the vicinity of the measured ambient
5 temperature. In one aspect of this embodiment, various operating and calibration parameters associated with the sensor (e.g., as discussed above) initially are measured or determined at each of the different predetermined stabilization temperatures. During subsequent operation, these operating and calibration parameters are dynamically selected and utilized to compensate the sensor based on the corresponding stabilization
10 temperature in use.

Following below are more detailed descriptions of various concepts related to, and embodiments of, methods and apparatus according to the present invention for compensating a radiation sensor for temperature variations of the sensor. It should be appreciated that various aspects of the invention, as discussed above and outlined further
15 below, may be implemented in any of numerous ways, as the invention is not limited to any particular manner of implementation. Examples of specific implementations are provided for illustrative purposes only.

Fig. 1 is a diagram showing a portion of an imaging system according to one embodiment of the invention. Some of the basic components of the imaging system
20 shown in Fig. 1 include a shutter 26, a sensor 32, sensor control and processing circuitry 34, and a controller 38. In one aspect of the system of Fig. 1, the sensor 32 may comprise a thermal imaging sensor that responds primarily to infrared radiation, wherein the sensor includes an array of thermal detectors, such as bolometers. At least one operational characteristic of a bolometer that may be affected by temperature variations
25 of the bolometer itself include a resistance of the bolometer, as discussed in greater detail below.

According to yet another aspect of the imaging system shown in Fig. 1, the sensor 32 and the circuitry 34 may be monolithically integrated on a semiconductor substrate 30 along with a temperature sensor 36, which outputs a sensor temperature
30 signal 44 corresponding to the temperature of the sensor 32. Fig. 1 also shows that in one embodiment, the substrate 30 may be thermally coupled to (e.g., mounted on) a TE cooler 28 which provides thermal stabilization for the sensor 32. It should be

appreciated, however, that the invention is not limited in this respect, as other embodiments of the invention discussed further below do not necessarily require the TE cooler 28.

While not shown explicitly in Fig. 1, the substrate 30 including the sensor 32 and the circuitry 34, along with the TE cooler 28, may be housed together in a vacuum package having a window that allows radiation to pass through to the sensor 32. In embodiments of the invention that do not require the TE cooler 28, the vacuum package merely may house the substrate 30 including the sensor 32 and the circuitry 34.

In the system of Fig. 1, according to one embodiment, the controller 38 monitors the sensor temperature signal 44 output by the temperature sensor 36, receives digitized signals 40 output by the circuitry 34 (which represent signals output by the sensor 32), and exchanges various other sensor control and monitor signals 42 with the circuitry 34. Additionally, according to one embodiment, the controller 38 also may monitor an ambient temperature signal 45 corresponding to an ambient temperature outside the package housing the sensor 32. In various embodiments of the invention employing the TE cooler 28, the controller 38 also may output a temperature control signal 48 to the TE cooler 28 in response to one or more of the sensor temperature signal 44, the ambient temperature signal 45, or a sensor temperature as calculated based on an average value of the digitized output signals 40. Finally, as shown in Fig. 1, the controller 38 outputs a shutter control signal 46 to control the operation of the shutter 26, as discussed further below.

With respect to various functions of the controller 38, as well as other components of imaging systems according to various embodiments of the invention, it should be appreciated that the invention is not limited to any particular manner of implementation. For example, methods and apparatus for compensating a radiation sensor for temperature variations of the sensor as discussed herein may be implemented in hardware, software, or various combinations thereof. In particular, the controller 38 may include dedicated hardware to perform various functions and/or may include one or more processors programmed using microcode or software to execute various algorithms to perform various functions discussed herein. In this respect, it should be appreciated that the controller 38 also may include a variety of digital logic circuits and memory or storage circuits or devices, including volatile, programmable, and permanent memory

circuits or devices (e.g., RAM, ROM, EPROM, EEPROM). Such components are not necessarily explicitly indicated in each of the figures showing the controller 38.

As illustrated in Fig. 1, an object of interest 20 in a scene to be imaged emanates radiation 22. The radiation 22 constitutes the radiation of interest from which an image of the object of interest 20 is generated by the imaging system. Fig. 1 also illustrates background radiation 24, which may related to an average temperature of the scene to be imaged, and in some cases also may be related to the ambient temperature in the vicinity of the package housing the sensor 32. For thermal imaging systems in particular, at a given temperature of the sensor 32, this background radiation 24 may contribute to an average (i.e., DC) component of signals from the sensor 32, and hence may be compensated for (e.g., subtracted out of the signals) by the imaging system. Accordingly, it should be appreciated that the instantaneous signals of interest output by the sensor 32 typically may be considered as essentially time-varying (i.e., essentially AC components) with respect to an average DC signal component. More specifically, in thermal imaging systems, the signals of interest output by the sensor 32 correspond to the radiation 22 from one or more objects having a temperature different than that of the average scene temperature.

Fig. 2 is a diagram showing a portion of an integrated sensor including an array of detectors and some associated signal processing circuitry used in the imaging system of Fig. 1, according to one embodiment of the invention. In particular, Fig. 2 illustrates a portion of the sensor 32, showing a four-by-four array of detector unit cells arranged in rows and columns. In Fig. 2, a first column 56 of detector unit cells is particularly identified, including four detector unit cells 56A, 56B, 56C, and 56D. According to one embodiment, each row of the sensor 32 may be selected by a corresponding row select signal 52, and each column of unit cells is associated with a common column bus 54, on which each of the unit cells of the column outputs a signal.

From Fig. 2, it may be appreciated that for each row of the sensor 32 that is selected via the row select signals 52, each column bus 54 carries one signal corresponding to a respective detector unit cell of the selected row. In particular, according to one embodiment of the invention, each row of the sensor 32 is sequentially selected (e.g., the row select signals may be derived from control signals output by the controller 38 shown in Fig. 1), and the respective detector unit cells of the selected row

- 10 -

output a signal on a corresponding column bus 54. Additionally, the column busses 54 may be "enabled" or activated with a particular timing to pass the output signals from the selected row of unit cells onto the processing circuitry 34 (e.g., again via control signals output by the controller 38). In this manner, rows of detector unit cells may be scanned in a manner similar to that of a television video signal (i.e., a raster scan). For simplicity, various row select and column bus enable circuitry is not illustrated in Fig. 2, and it should be appreciated that such circuitry may be implemented in a variety of manners.

Fig. 2 also shows a portion of the sensor control and processing circuitry 34 that is integrated with the sensor 32. In particular, Fig. 2 shows that each column bus 54 of the sensor 32 is coupled to a preamplifier/integrator 58 (labeled in Fig. 2 as "PA"). Each of the PAs 58 also receives as an input a global detector bias 64, which provides a common DC bias voltage for all of the detector unit cells of the sensor 32, as discussed further below. Additionally, Fig. 2 shows that the PAs 58 are each coupled to a common supply voltage 70 (labeled in Fig. 2 as " V_R "), which provides a common source of current for the PAs 58 to drive respective selected detector unit cells of the sensor 32. The instantaneous current drawn from the voltage V_R by a given preamplifier/integrator 58 and supplied to a selected detector unit cell when a scene is actively being viewed preferably constitutes the instantaneous signal of interest from the selected detector, as also discussed further below.

In Fig. 2, each column bus 54 of the sensor 32 is also coupled to a digital-to-analog converter 60 (labeled in Fig. 2 as "DAC") included in the sensor control and processing circuitry 34. Each DAC 60 is in turn coupled to a common or "global" offset 66. The global offset 66 may be a voltage or current applied to all of the DACs 60 to ultimately provide a bias current to each selected detector unit cell via the column busses 54. As discussed further below in connection with Figs. 3 and 4, each DAC 60 is controlled by the controller 38 to provide a coarse offset adjustment to the bias current supplied to each selected detector unit cell, to compensate for detector non-uniformities (i.e., non-uniform responses from detector to detector).

Additionally, Fig. 2 shows that the output of each PA 58 is coupled to an analog-to-digital converter 62 (labeled in Fig. 2 as "A/D"), which converts the analog signal output by each PA to a digital signal 40. At least one example of an analog-to-digital converter implementation for the A/Ds 62 suitable for purposes of the present invention

RECTIFIED SHEET (RULE 91)

- 11 -

is provided in U.S. Patent No. 6,225,937, issued May 1, 2001, and entitled "METASTABILITY RESOLVED MONOLITHIC ANALOG-TO-DIGITAL CONVERTER," which patent is hereby incorporated herein by reference. It should be appreciated, however, that the present invention is not limited to the analog-to-digital converter implementations discussed in this patent, as other implementations are possible.

While not explicitly shown in Fig. 2 (again for purposes of simplicity), the A/Ds 62 are sequentially enabled via control signals output by the controller 38 shown in Fig. 1, so that each digital signal may be individually output from a corresponding A/D as the signal 40, and thereafter individually processed and/or stored in memory by the controller 38. Accordingly, it should be appreciated that each row of the sensor is sequentially enabled to obtain a set of "parallel" signals corresponding to the unit cells of the selected row, these signals are converted by the A/Ds 62 to a set of parallel digital signals, and then each signal from the set of digital signals is sequentially passed onto the controller 38 for individual processing and/or storage.

Fig. 3 is a diagram showing a more detailed view of a portion of the sensor 32 illustrated in Fig. 2, according to one embodiment of the invention. In particular, Fig. 3 shows in greater detail the four unit cells 56A, 56B, 56C, and 56D of the column 56 of the sensor 32. Fig. 3 also shows the PA 58, the DAC 60 and the A/D 62 associated with the column 56. As can be seen in Fig. 3, according to one embodiment of the invention, each detector unit cell includes two transistors each having a gate coupled to the same row select bus. Each unit cell also includes a detector, illustrated symbolically as the resistors 72A, 72B, 72C, and 72D respectively in the unit cells 56A, 56B, 56C, and 56D. Upon the activation of a row select signal for a particular row, one transistor of the unit cell connects one terminal of the detector to a detector common 68 (e.g., a ground potential), and the other transistor of the unit cell connects the other terminal of the detector to the column bus 54. Fig. 3 also illustrates that the controller 38 includes a coarse offset map 77 that provides the DAC 60 for the column 56 with coarse offset digital values 75 for each of the unit cells of the column 56. The coarse offset digital values 75 control the DAC 60 to adjust the global bias current provided by the global offset 66, so as to compensate for detector non-uniformities, as discussed further below.

- 12 -

Fig. 4 is a diagram showing one example of the DACs 60 used in the sensor processing circuitry 34 shown in Figs. 2 and 3, according to one embodiment of the invention. Other examples of digital-to-analog converter implementations for the DACs 60 suitable for purposes of the present invention are provided in U.S. patent application
5 Serial No. 08/981,109, filed December 17, 1997, and entitled "DIGITAL OFFSET CORRECTOR," which application is hereby incorporated herein by reference. It should be appreciated, however, that the present invention is not limited to the examples of DACs discussed in this application, nor to the exemplary DAC illustrated in Fig. 4, as other implementations are possible.

10 Essentially, the DAC 60 shown in Fig. 4 is used to incrementally adjust the value of a bias resistor coupled between a column bus 54 and the global offset 66, so as to adjust a DC bias current provided to each of the detectors of the sensor 32. In Fig. 4, this bias resistor is shown schematically in five parts for purposes of illustration, as the resistors 55A, 55B, 55C, 55D, and 55E. Different parts of the bias resistor are
15 selectively "bypassed" to change the overall bias resistance by activating one or more of bypass transistors 57A, 57B, 57C, and 57D via a corresponding one of the input bits of the coarse offset digital values 75. For each detector of the sensor 32, the controller 38 stores a coarse offset digital value in a coarse offset map 77 (e.g., shown in Fig. 3). This offset value corresponds to an adjustment to the bias resistance that is required for the
20 particular detector so as to compensate for inherent non-uniformities amongst the detectors, as discussed further below.

Fig. 5 is a diagram showing one example of the PAs 58 used in the processing circuitry 34 shown in Figs. 2 and 3, according to one embodiment of the invention. Other examples of preamplifier/integrator implementations for the PAs 58 suitable for purposes
25 of the present invention are provided in U.S. patent application Serial No. 09/011,942, filed February 20, 1998, and entitled "BOLOMETRIC FOCAL PLANE ARRAY," and U.S. patent application Serial No. 09/051,180, filed April 3, 1998, and entitled "UNCOOLED FOCAL PLANE ARRAY SENSOR," which applications are hereby incorporated herein by reference. It should be appreciated, however, that the present
30 invention is not limited to the examples of PAs discussed in these applications, nor to the exemplary PA illustrated in Fig. 5, as other implementations are possible.

- 13 -

According to one embodiment, as can be seen from the exemplary circuit of Fig. 5, the column bus 54 is actually biased at one V_{be} (i.e., approximately 0.7 Volts) above the global detector bias 64, due to the base-emitter junction of the preamp transistor. Fig. 5 also illustrates that the supply voltage 70 (V_R) supplies current to the column bus 54 via the pass transistor, and the output capacitor is charged to a voltage representing this current, which voltage is ultimately provided as the signal 74 to the A/D 62.

With reference again to Figs. 2 and 3, according to one embodiment of the invention, the individual detectors of the sensor 32 may be thermal detectors that detect primarily infrared radiation. Generally, a thermal detector detects radiation based upon a change in the temperature of an active region of the detector due to absorption of radiation of interest incident to the detector. Some examples of thermal detectors include, but are not limited to, pyroelectric devices, thermocouples, diode-based devices, and resistive devices, such as bolometers.

In particular, according to one embodiment of the invention, the detectors of the unit cells of the sensor 32 (e.g., the detectors 72A, 72B, 72C, and 72C of the unit cells 56A, 56B, 56C, and 56D shown in Fig. 3) may be bolometers, wherein each bolometer includes an infrared energy receiving surface that is made of a material having a resistivity that changes as its temperature changes, in response to the infrared energy impinging on and being absorbed by the material. Thus, as the bolometer absorbs radiation, both its temperature and electrical resistance change.

A measure of radiation absorbed by a bolometer can be made by measuring changes in its electrical resistance. For example, by placing the bolometer in series with a voltage supply (i.e., D.C. coupling the bolometer), the current in the bolometer varies in accordance with the amount of infrared energy incident to the bolometer. Accordingly, as shown in Fig. 3, a preamplifier / integrator (PA) 58 is connected to a voltage supply 70 (V_R) to provide current to a particular selected bolometer, and is serially connected to the bolometer so as to produce an output signal 74 representative of the incident infrared energy. As discussed above, the sensor 32 including an array of such bolometers produces a plurality of output signals that are ultimately fed to the controller 38, which processes the signals to provide an electronic image of the source of the infrared energy.

- 14 -

One significant issue related to bolometers is that various operational characteristics of bolometers (in addition to the sensitivity of its active area to incident radiation and corresponding changes in bolometer resistance due to the incident radiation of interest) are functions of the temperature of the bolometer itself. As a result, in some cases it may be challenging to separate signals of interest due to incident radiation from undesirable signal components due to temperature variations of the bolometer itself.

Preliminarily, it should be appreciated that gradual or steady state changes in temperature of the bolometer itself (e.g., due to changes in temperature in the vicinity of the bolometer) alter the steady state resistance of the bolometer; hence, one operational characteristic of the bolometer that changes as a function of bolometer temperature variations is its resistance. Such changes in steady state resistance due to bolometer temperature variations may be significantly larger (e.g., up to hundreds of times larger) than instantaneous changes in bolometer resistance due to incident radiation of interest. As a result, the effect of bolometer steady state temperature variations may significantly degrade the dynamic range and signal-to-noise ratio of bolometer output signals with respect to the radiation of interest.

Accordingly, as discussed above, imaging systems employing thermal sensors including bolometers typically require some type of thermal stabilization mechanism, as illustrated for example by the TE cooler 28 shown in Fig. 1. Such thermal stabilization mechanisms generally are employed to maintain the sensor at a predetermined temperature in an effort to minimize any changes in steady state resistance due to steady state changes in bolometer temperature. With reference again for the moment to Fig. 3, once the bolometer array sensor is thermally stabilized, the bolometers may be appropriately biased such that average output signals from the bolometers, once amplified by the PA 58, fall approximately in the middle of the available range of the A/D 62. This type of biasing generally affords the maximum dynamic range for bolometer output signals corresponding to radiation of interest within the performance limitations of the PA 58 and the A/D 62.

However, as discussed further below, Applicants have recognized that, as an alternative to thermal stabilization (or in addition to some degree of thermal stabilization) of bolometer array sensors, various operating and/or calibration parameters of the bolometers may be varied to compensate for steady state resistance changes

- 15 -

resulting from temperature variations of the bolometer. Accordingly, one embodiment of the present invention is directed to methods and apparatus for compensating operating parameters and/or output signals of a radiation sensor including an array of bolometers for temperature variations of the bolometers that are not due to radiation of interest, without necessarily employing thermal stabilization techniques for the sensor (e.g., without using a TE cooler). In one aspect, the methods and apparatus of this embodiment allow the temperature of the sensor to freely vary, and provide continuous thermal compensation feedback through dynamic adjustments to various operating and calibration parameters associated with the sensor. For purposes of this disclosure, “operating parameters” associated with a sensor generally refer to signals applied to the sensor during normal operation of the sensor to bias the sensor, while “calibration parameters” associated with a sensor generally refer to various parameters that may be used for processing output signals from the sensor to adjust for non-uniformities amongst individual radiation detectors of the sensor. Of course, it should be appreciated that the various compensation concepts discussed herein relating to sensors including bolometers may be applied more generally to sensors employing other types of radiation detectors as well.

More specifically, Applicants have appreciated that by varying one or both of the bolometer DC bias current and DC bias voltage in response to bolometer temperature variations so as to compensate for changes in steady state resistance, a suitable dynamic range and signal-to-noise ratio of bolometer output signals may be maintained. Additionally, Applicants have appreciated that by varying both of the bolometer bias current and bias voltage in a complementary manner, an essentially constant bias power may be maintained. By maintaining an essentially constant bias power, changes in the bolometer bias voltage or current themselves do not significantly contribute to or exacerbate changes in the bolometer temperature.

In addition to changes in steady state resistance due to steady state or gradual changes in bolometer temperature, Applicant's have also identified a bolometer “self-heating” effect that may change bolometer temperature locally on a relatively instantaneous time scale, irrespective of whether or not thermal stabilization techniques are employed to stabilize the steady state temperature of the sensor. This self-heating effect also may contribute to undesirable components in output signals from the

- 18 -

Yet another operating characteristic of a sensor including a bolometer array that may change as a function of temperature relates to a response or "gain" of each bolometer in the array. For example, the response to radiation of interest of one bolometer compared to another bolometer at a given array temperature (referred to hereafter as a "calibration temperature") may be different. This variation in response from bolometer to bolometer at a given calibration temperature is referred to for purposes of this disclosure as "gain error." Since a bolometer essentially measures the temperature of an object of interest relative to an average temperature of the scene being imaged, the gain of a bolometer may be expressed as $(\Delta V_{\text{bol}}/\Delta T_{\text{obj}})_{T_{\text{cal}}}$, where V_{bol} indicates the output digital voltage from an A/D 62 representing a signal of interest from a selected bolometer, T_{obj} indicates the temperature of the object of interest in the scene that emits radiation incident to the bolometer, and T_{cal} indicates the calibration temperature at which the bolometer array is held to measure the gain. Accordingly, each bolometer may be associated with a particular gain value, and a set of gain values for a sensor including an array of bolometers at a particular calibration temperature is referred to herein as a "gain map." The gain values of the gain map are used as calibration parameters, in a manner similar to that of the offset error values of the offset map discussed above, to adjust output signals of an array relative to each other.

Similar to offset errors, the gain or response of each bolometer in an array may change as the temperature of the array varies (e.g., from the calibration temperature). Additionally, the change in bolometer gain due to a change in array temperature may be different from bolometer to bolometer. Accordingly, another operational characteristic of a bolometer array that may change as a function of temperature is referred to herein as "gain variation." Again, gain variation for each bolometer may be thought of as a change in the gain value of the bolometer due to a change in array temperature, and may be expressed for purposes of the following discussion as a "gain variation function."

As with the TCR discussed above, it should be appreciated that the gain variation function of the bolometers is not necessarily a linear function of sensor temperature over a wide temperature range; hence, according to various embodiments, a nonlinear function, or suitable linear or piece-wise linear approximations for the gain variation function over a particular range of temperatures, may be derived and employed to compensate for gain variation. For example, according to one embodiment, a single gain

- 16 -

bolometer. In particular, Applicant's have recognized that when a bias voltage or current initially is applied to the bolometer (e.g., when a particular row is selected and the column busses are enabled in Fig. 2), current begins to flow through the bolometer, producing heat. This local heat produced by the bolometer itself in turn changes the resistance of the bolometer, independently of the radiation of interest incident to the
5 bolometer.

In one aspect of the bolometer self-heating effect, the initial flow of current through one bolometer as the bolometer is enabled, followed by the bolometer being disabled and another bolometer being enabled (e.g., according to the scanning process
10 discussed above in connection with Fig. 2), may be approximated by a saw tooth waveform. Accordingly, the bolometer self-heating effect may be thought of as contributing an undesirable time-varying (i.e., AC) waveform component to the bolometer output signals. The magnitude (amplitude) of this undesirable waveform component also may be a function of the steady state bolometer temperature. In view of
15 the foregoing, Applicant's have recognized that by applying a time-varying waveform that is essentially the inverse of the undesirable "self-heating" waveform to one of the bolometer bias current or bias voltage, the self-heating effect can be significantly reduced. According to one embodiment of the invention, the amplitude of such a time-varying compensation waveform is dynamically adjusted as an operating parameter
20 based on variations in the steady state temperature of the bolometer array.

Other examples of operational characteristics of a sensor including an array of bolometers that may change as a function of temperature variations of the sensor relate to non-uniformities amongst the bolometers. For example, the nominal resistance of one bolometer compared to another at a given array temperature may be different (assuming
25 both bolometers receive the same incident radiation, or view a "control" or "reference source"). Given an array of such bolometers, each bolometer may have a different nominal resistance at a given array temperature and viewing a given reference source. This variation in nominal resistance from bolometer to bolometer, with reference to an average nominal resistance of all of the bolometers, is referred to for purposes of this
30 disclosure as an "offset error." Accordingly, each bolometer may be associated with a particular resistance value that reflects that bolometer's offset error. It should be appreciated, however, that this resistance value may be converted to any convenient unit

- 17 -

of measure. For example, since the A/D 62 shown in the figures outputs digital voltage values, for purposes of the following discussion the offset error of each bolometer may be treated as a differential voltage V_{off} corresponding to the offset resistance value. A set of offset error values (e.g., voltages V_{off}) for an array of bolometers that are used as calibration parameters to adjust output signals of an array relative to each other is referred to herein as an "offset map."

Viewing the same reference source, the offset error of each bolometer in an array may change as the temperature of the array varies. Additionally, the change in offset error due to a change in array temperature may be different from bolometer to bolometer. Accordingly, one operational characteristic of a sensor including a bolometer array that may change as a function of temperature is referred to herein as "offset error variation." Again, an offset error variation for each bolometer may be thought of as a change in the offset resistance value of the bolometer due to a change in array temperature, and may be expressed for purposes of the following discussion as a temperature coefficient of resistance (TCR) function dV_{off}/dT_s (or $\Delta V_{\text{off}}/\Delta T_s$), where V_{off} represents the offset resistance and T_s indicates the sensor temperature (i.e., the temperature of the bolometer array).

It should be appreciated that the TCR of the bolometers is not necessarily a linear function of sensor temperature over a wide range of temperatures. However, according to various embodiments of the invention, either a nonlinear function for dV_{off}/dT_s , or suitable linear or piece-wise linear approximations for TCR within a particular range of temperatures ($\Delta V_{\text{off}}/\Delta T_s$), may be derived and employed to compensate for offset error variation. For example, according to one embodiment, one TCR value is derived for each bolometer over an anticipated operating temperature range, wherein an essentially linear TCR dependence on temperature is assumed over this temperature range. A set of such TCR values for the bolometer array (i.e., a "TCR map") subsequently is used to dynamically adjust the corresponding offset error calibration parameters of the respective bolometers, as maintained in an offset map. In other embodiments, nonlinear TCR functions, or interpolation of piece-wise linear approximations for TCR over multiple temperature ranges, may be similarly used to dynamically adjust the offset error calibration parameters stored in the offset map.

- 19 -

adjustment factor that multiplies the gain value of a bolometer based on a difference between a measured sensor temperature and the calibration temperature at which the gain values for the array were originally obtained is derived for each bolometer over an anticipated operating temperature range (i.e., a linear dependence of gain variation on temperature is assumed over this temperature range). A set of such gain adjustment factors for the bolometer array (i.e., a "gain adjust map") subsequently is used to dynamically adjust the gain values (gain calibration parameters) stored in the gain map. In other embodiments, nonlinear gain variation functions, or interpolation of piece-wise linear approximations for gain variation functions, may be similarly used to dynamically adjust the gain calibration parameters stored in the gain map.

In sum, Applicants have identified a number of operating and calibration parameters associated with a sensor including a bolometer array that may be dynamically adjusted as a function of sensor temperature, so as to compensate for changes in operational characteristics of the individual bolometers of the sensor due to temperature variations of the sensor. As outlined immediately above, these parameters may include, but are not necessarily limited to, a DC bias voltage, a DC bias current, and an AC self-heating compensation waveform applied to the bolometers (operating parameters), as well as individual entries of an offset map and a gain map that correct for non-uniformities amongst the bolometers (calibration parameters).

According to various embodiments of the invention, the operating parameters discussed above (i.e., DC bias voltage, DC bias current, and AC self-heating compensation waveform) are "globally" applied to all of the individual bolometers of the sensor, and one or more of these operating parameters may be dynamically adjusted in response to temperature variations of the sensor via analog or digital feedback loop implementations. Additionally, according to various embodiments of the invention, the calibration parameters of one or both of the offset and gain maps discussed above, either alone or in combination with one or more of the operating parameters, may be dynamically adjusted based on temperature variations of the sensor on a bolometer by bolometer basis, using nonlinear offset and gain variation functions, interpolations of piece-wise linear approximations of offset and gain variation, or linear approximations of offset and gain variation. The foregoing concepts are discussed in turn in greater detail below, in connection with Figs. 6-10.

- 20 -

Fig. 6 is a diagram showing a more detailed view of the portion of the imaging system shown in Fig. 3, illustrating one possible implementation of various temperature compensation features, according to one embodiment of the invention. In particular, Fig. 6 demonstrates some basic elements of one example of a primarily analog circuit implementation for dynamic control of various operating parameters associated with a sensor. Of course, it should be appreciated that the invention is not limited to the implementation outlined in Fig. 6, as other implementations are possible, as discussed further below.

In Fig. 6, a generic selected or enabled detector of the sensor 32 (e.g., see Figs. 2 and 3) is shown for purposes of illustration as the resistor 72 coupled to the detector common 68. As discussed above in connection with Figs. 2 and 3, each enabled detector of a selected row is coupled to a corresponding DAC 60 and PA 58 via the column bus 54. Accordingly, Fig. 6 shows the DAC 60 and the PA 58 coupled to the generic detector 72 via the column bus 54. Also as in Figs. 2 and 3, Fig. 6 shows that the DAC 60 receives a global offset 66, and the PA 58 receives a global detector bias 64 and a reference supply voltage V_R 70. Fig 6 also illustrates the A/D 62 and the controller 38, which process digital signals representing signals output by the detector 72 on the column bus 54.

As discussed above in connection with Figs. 2 and 3, according to one embodiment of the invention, the global offset 66, the global detector bias 64, and the voltage V_R 70 are applied similarly to each DAC 60 and each PA 58 associated with the sensor, such that these signals essentially are "common" to all detectors of the array. Hence, although Fig. 6 shows only one DAC and one PA, it should be appreciated that the global offset 66, the global detector bias 64, the voltage V_R 70 may be simultaneously applied to multiple DACs and PAs associated with the sensor.

As illustrated in Fig. 6, the global offset 66, via the DAC 60, determines a bias current I_{BIAS} 81 through the detector 72, while the supply voltage V_R 70 provides a power source to the PA 58 to allow a signal current I_{sig} 83 to flow through the detector 72 in response to radiation of interest incident to the detector. The total current through the detector 72 is indicated in Fig. 6 as I_D . The global detector bias 64 provides a bias voltage for the detector 72 via the PA 58; essentially, as discussed above in connection

- 21 -

with Fig. 5, the PA 58 maintains the column bus 54 at a potential approximately 0.7 Volts above the global detector bias 64.

In general, as discussed above, the bias current and the bias voltage for the detector 72 are selected such that average output signals from the detector, once
5 amplified by the PA 58, fall approximately in the middle of the available range of the A/D 62. This type of biasing generally affords the maximum dynamic range for detector output signals corresponding to radiation of interest within the performance limitations of the PA 58 and the A/D 62. In some cases, the bias current I_{BIAS} 81 required to
10 accomplish this may be significantly greater than the typical signal current I_{sig} 83 expected from the detector. For example, in some cases it may result that I_{BIAS} constitutes as much as approximately 99% of the current I_D through the detector, while I_{sig} constitutes merely approximately 1% of the current I_D . It should be appreciated, however, that these exemplary values are provided for purposes of illustration only, and that the invention is not limited in this respect.

15 Fig. 6 also shows various circuitry coupled to the global offset 66, the global detector bias 64, and the supply voltage 70 that is used in a feedback loop configuration to dynamically adjust one or both of the global offset 66 (and hence the detector bias current I_{BIAS} 81) and the global detector bias 64 based on temperature variations of the detector 72. In particular, Fig. 6 shows a current sampler 82A which measures the
20 current being drawn by the PA 58 from the supply voltage V_R 70 to provide the signal current I_{sig} 83 to the detectors of the sensor. As shown in Fig. 6, the current sampler 82A is inserted between a voltage source V_S and a supply voltage terminal of the PA that receives the supply voltage V_R 70. Essentially, the current sampler 82A provides a measure of an instantaneous signal current being drawn by enabled detectors of the
25 sensor; recall that, according to one embodiment, the supply voltage V_R 70 is applied to all of the PAs 58 (e.g., the supply voltage terminals to each of the PAs are tied together), and each PA in turn provides signal current to a corresponding enabled detector of a selected row. Thus, at any given time, the current sampler in this embodiment provides an indication of the total instantaneous signal current being drawn by a selected row of
30 detectors.

Averaged over time, the current measured by the current sampler 82A shown in Fig. 6 may provide an indication of temperature variations of the detector 72 not due to

- 22 -

the radiation of interest. In particular, as discussed above in connection with bolometers, changes in bolometer temperature affect the resistance of the bolometer, which in turn affects the signal current 83 being drawn by the bolometer. Hence, according to one embodiment, an output 87 of the current sampler 82A may be used as an input (or "error signal") to a feedback control loop as an indication of temperature variations of the detector 72.

As illustrated in Fig. 6, the output 87 of the current sampler 82A is coupled to a DC global offset adjust controller 78A and an AC global offset adjust controller 76A. According to one embodiment, the DC global offset adjust controller 78A dynamically varies a DC component of the global offset 66 (and hence a DC component of the detector bias current I_{BIAS} 81) in response to temperature variations of the detector 72, as reflected in the output 87 of the current sampler 82A. Similarly, according to one embodiment, the AC global offset adjust controller 76A dynamically varies an AC component of the global offset 66 (and hence an AC component of the detector bias current I_{BIAS} 81) in response to instantaneous temperature variations of the detector 72 that are not related to radiation of interest, incident on the detector, as reflected in the output 87 of the current sampler 82A.

In particular, according to one embodiment, the AC global offset adjust controller 76A of Fig. 6 provides a dynamically adjusted time-varying waveform that compensates for self-heating effects of the detector 72. More specifically, as discussed above and in greater detail below in connection with Fig. 8, as a bias is initially applied to an enabled detector, the output 87 of the current sampler 82A indicates an instantaneous current component related to the initial flow of current through the detector, which begins to produce local heat. In response, the AC global offset adjust controller 76A provides an AC component to the detector bias current I_{BIAS} 81 (e.g., a saw tooth or other time-varying waveform) to compensate for this effect. As illustrated in Fig. 6, according to one embodiment, an output 88 of the AC global offset adjust controller 76A is summed with an output 85 of the DC global offset adjust controller 78A at a summing node 84 to provide the global offset 66.

Fig. 6 also shows that the output 85 of the DC global offset adjust controller 78A is coupled to a global bias adjust controller 80A. According to one embodiment, the global bias adjust controller 80A dynamically adjusts the global detector bias 64 (i.e., the

- 23 -

DC bias voltage applied to the detector 72) based on changes in the DC component of the detector bias current I_{BIAS} 81, as provided by the DC global offset adjust controller 78A. In this manner, the DC global offset adjust controller 78A and the global bias adjust controller 80A maintain an essentially constant bias power for the detector 72.

5 In the embodiment of Fig. 6, the controller 38 may provide various signals to the global bias adjust controller 80A, the DC global offset adjust controller 78A, and the AC global offset adjust controller 76A to facilitate operation of these devices. For example, the controller 38 may provide an HSYNCH signal to the AC global offset adjust controller 76A, so as to control timing of the AC compensation waveform with respect to
10 selection of consecutive rows of detectors in the sensor (e.g., similar to raster scanning, as discussed above). Likewise, the controller 38 also may provide a sample/hold (S/H) control signal to the DC global offset adjust controller 78A, so as to temporarily disable active feedback control of the global offset 66 for various calibration purposes, as discussed further below.

15 Additionally, the controller 38 may provide a bias voltage V_{BIAS} to the global bias adjust controller 80A, which is adjusted by the global bias adjust controller 80A as discussed above to provide the global detector bias 64. For example, in one embodiment, the controller may include (or be associated with) a digital-to-analog converter (not shown in Fig. 6), which receives a digital signal from the controller 38
20 corresponding to a desired bias voltage, and outputs an analog value for the voltage V_{BIAS} .

In the embodiment of Fig. 6, the controller 38 also may monitor the output 85 of the DC global offset adjust controller 78A, which as discussed above is related to the DC component of the detector bias current I_{BIAS} 81. According to one aspect of this
25 embodiment, the controller 38 may use the output 85 as an indication of the temperature of the sensor 32, by calibrating the output 85 based on measurements of sensor temperature. Alternatively, as discussed above in connection with Fig. 1, the controller 38 may directly monitor sensor temperature by receiving as an input a sensor temperature signal 44 output by a temperature sensor located in proximity of the sensor
30 32. In some radiometry applications in which measurements of absolute temperature of objects of interest in a scene are desired, the measurement of sensor temperature provided by either the output 85 of the DC global offset adjust controller 78A or the

- 24 -

sensor temperature signal 44 may be used in radiometric calculations to provide the required level of accuracy for radiometry measurements. It should be appreciated that one or both of the output 85 and the sensor temperature signal 44 may be input to the controller 38 as analog signals and converted, for example, by an analog-to-digital converter in the controller 38 (not shown in Fig. 6) to provide digital representations of these signals.

Finally, Fig. 6 shows that the controller 38 contains a coarse offset map 77 which includes coarse offset digital values 75 that are used to control the DAC 60, so to provide adjustments to the detector bias current I_{BIAS} 81 on a detector-by-detector basis, as discussed briefly above in connection with Fig. 3. These adjustments relate to non-uniformities amongst the detectors of the sensor, and are discussed in greater detail below in connection with Fig. 10.

Fig. 7 is a diagram showing examples of analog circuit implementations for the current sampler, DC global offset adjust controller, and global bias adjust controller of Fig. 6, according to one embodiment of the invention. It should be appreciated that these examples are provided for purposes of illustration only, and that the invention is not limited to the particular circuits shown in Fig. 7. In Fig. 7, the current sampler 82A and the DC global offset adjust controller 78A are implemented in a circuit that performs both functions. In particular, resistors R9 and R10 form an adjustable voltage divider, which places a portion of the source voltage V_S on the non-inverting input of amplifier AR2. Accordingly, this voltage also appears on the inverting input of AR2. Resistor R8 hence essentially provides the current sampling function; as the average current drawn from the supply voltage V_R 70 changes due to temperature variations of the sensor, the current flowing through the resistor R8 changes. The amplifier AR2 in turn varies the output current 85 provided to the summing node 84 shown in Fig. 6 based on the changes in current through R8. Transistor Q5 is controlled by the S/H control signal from the controller 38; when the transistor Q5 is "disabled," the resistor R8 is disconnected from the amplifier AR2, and the capacitor C8 serves as a hold capacitor. When the transistor Q5 is "enabled", resistor R8 and capacitor C8 determine the response time of the DC global offset adjust feedback loop; according to one embodiment, values for these components are selected such that the response time of the loop is several image frames (e.g., several scans of the sensor) so as to reduce image artifacts. Capacitor C7 provides

- 25 -

a low impedance to AC signal components in the average current drawn from the supply voltage V_R 70, so that these components do not significantly affect the DC global offset adjust feedback loop.

In Fig. 7, the global bias adjust controller 80A is implemented by a circuit including amplifier AR3, which samples the DC current output 85. The resistors R11, R12, and R13 and the capacitors C9 and C10 provide gain and filtering of the sampled signal. In the exemplary circuit shown in Fig. 7, increases in the output current 85 (corresponding to increases in the detector bias current I_{BIAS}) cause some proportional decrease in the global detector bias 64. Hence, the circuits shown in Fig. 7 tend to act so as to keep a sum of the detector bias current and bias voltage constant, rather than keeping the product of the bias current and voltage constant (so as to maintain essentially constant detector power). However, over a relatively limited or small range of detector powers, regulating the sum rather than the product of detector bias current and voltage provides adequate control of detector power according to this embodiment.

Fig. 8 is a diagram showing an example of an analog circuit implementation for the current sampler and AC global offset adjust controller of Fig. 6, according to one embodiment of the invention. It should be appreciated that these examples are provided for purposes of illustration only, and that the invention is not limited to the particular circuit shown in Fig. 8. Similar to Fig. 7, in Fig. 8 the current sampler 82A and the AC global offset adjust controller 76A are implemented in a circuit that performs both functions. In particular, in Fig. 8, R1 is a low value (e.g., 10 Ohm) resistor, and the voltage drop across R1 is a measure of the average current drawn by bolometers of the array. Capacitor C1 is a high frequency bypass for resistor R1. A high gain AC amplifier comprising C2, Q1, Q2, R2, R3 and R4 amplify the AC (instantaneous) component of the current drawn by a row of detectors coupled to the supply voltage V_R 70. The amplified AC component is then detected by a synchronous rectifier comprising C3 and Q3. The output of the synchronous rectifier is integrated by AR1, R5, and C4. The output voltage of the integrator controls the current through resistor R6. Capacitor C6 is periodically reset to a high voltage at an appropriate time by an analog switch connected to the point labeled open_d. When the voltage at open_d is not applied, capacitor C6 discharges at a rate determined by the current through R6, thereby generating an essentially saw tooth waveform. The waveform generated by this process

- 26 -

is then provided as an output 88 via transistor Q4, and ultimately is AC coupled into the summing node 84 shown in Fig. 6. The polarity of the feedback loop represented by the circuit in Fig. 8 is selected such that the AC component of the average current drawn by the bolometers from the supply voltage V_R 70 is reduced to approximately zero during the initial bias time of the detectors, thereby compensating for the self-heating effects discussed above.

Fig. 9 is a diagram similar to Fig. 6 showing a more detailed view of the portion of the imaging system shown in Fig. 3, illustrating another possible implementation of various temperature compensation features, according to one embodiment of the invention. In particular, Fig. 9 demonstrates some basic elements of one example of a primarily digital implementation for dynamic control of various operating parameters associated with a sensor.

In the embodiment of Fig. 9, essentially the controller 38 monitors various input signals and outputs various signals so as to implement closed feedback loop control of detector bias current and bias voltage in a manner similar to that discussed above in connection with Fig. 6. In particular, it should be appreciated that the controller 38 may be programmed in a variety of manners so as to execute one or more algorithms to implement such control. In one aspect of this embodiment, the controller 38 may include a number of analog-to-digital converters (not explicitly shown in Fig. 9) to digitize one or more signals input to the controller that are not already in digital form; for example, while the signals 40 received by the controller 38 from the A/D 62 are in digital form, the controller 38 may include one or more analog-to-digital converters to convert the output 87 from the current sampler 82B or the sensor temperature signal 44 to digital form. Similarly, according to one embodiment, the AC global offset adjust controller 76B, the DC global offset adjust controller 78B and the global bias adjust controller 80B each may include a digital-to-analog converter that receives digital output signals from the controller 38 and converts these signals to an analog voltage or current.

The embodiment of Fig. 9 provides a significantly versatile solution to feedback control of the various sensor operating parameters based on temperature variations of the sensor. For example, the controller 38 may monitor the average steady state temperature of the sensor by either monitoring the sensor temperature signal 44, the output 87 of the

RECTIFIED SHEET (RULE 91)

- 27 -

current sampler 82B, or periodically calculating an average detector output signal based on any number of the individually sampled digital detector output signals provided by the A/D 62, and monitoring any changes in this calculated signal. Any of these approaches may provide an input or "error signal" to the feedback loop. Additionally, 5 the controller may monitor instantaneous changes in the current drawn by detectors of the sensor from the supply voltage V_R 70 by sampling the output 87 of the current sampler 82B at an appropriate rate to acquire and store data related to detector self-heating.

Based on any of the foregoing sampled input signals, the controller 38 may 10 flexibly control one or more of the AC global offset adjust controller 76A, the DC global offset adjust controller 78B and the global bias adjust 80B by merely outputting a digital value to these devices corresponding to the desired control. In particular, the controller 38 may be specifically programmed such that the DC global offset adjust controller dynamically maintains an appropriate bias current for the detectors based on measured 15 temperature variations of the sensor, the global bias adjust controller 80B dynamically adjusts the global detector bias such that a product of the detector bias current and bias voltage remains essentially constant (so as to maintain an essentially constant detector power), and a timing and amplitude of a time-varying waveform generated by the AC global offset adjust controller 76B is dynamically adjusted based on the data acquired by 20 sampling the output 87 of the current sampler 82B.

Fig. 10 is a block diagram showing a more detailed view of a portion of the controller 38, illustrating one possible implementation of various temperature compensation features relating to calibration parameters associated with the sensor, according to one embodiment of the invention. In particular, Fig. 10 demonstrates some 25 basic elements of one example of a calibration parameter compensation algorithm implemented by the controller 38. Of course, it should be appreciated that the invention is not limited to the algorithmic implementation outlined in Fig. 10, as other algorithmic implementations are possible, as discussed further below.

As discussed above, a number of calibration parameters associated with a sensor 30 including a detector array may be dynamically adjusted as a function of sensor temperature, so as to compensate for changes in operational characteristics of the sensor due to temperature variations of the sensor. These calibration parameters may include,

- 28 -

but are not necessarily limited to, individual entries in an offset map and a gain map that correct for non-uniformities amongst the detectors. Some of the operational characteristics of the sensor that change due to temperature variations of the sensor relate to changes in the offset error and gain of individual detectors; these changes were referred to earlier as "offset variation" and "gain variation." According to one embodiment of the invention, such offset variation and gain variation with sensor temperature necessitate dynamic adjustments of the calibration parameters constituting the offset and gain maps when thermal stabilization of the sensor is not employed (e.g., a TE cooler is not used in the system). According to another embodiment, even if thermal stabilization of the sensor is employed, dynamic adjustments of calibration parameters also may be employed to improve accuracy and reliability of the imaging system.

In view of the foregoing, according to various embodiments of the invention, the calibration parameters contained in one or both of the offset and gain maps, either alone or in combination with one or more of the operating parameters discussed above, may be dynamically adjusted based on temperature variations of the sensor on a detector by detector basis. Such adjustments may be accomplished using nonlinear offset and gain variation functions, interpolations of piece-wise linear approximations of offset and gain variation, or linear approximations of offset and gain variation.

In particular, Fig. 10 illustrates an example of a dynamic calibration parameter adjustment algorithm based on linear approximations of offset and gain variation, according to one embodiment of the invention. In particular, according to one embodiment, an initial sensor calibration procedure is executed to obtain a number of calibration parameters related to a coarse offset error, a fine offset error, and a gain for each detector of a sensor. As illustrated in Fig. 10, these parameters are stored respectively in a coarse offset map 77, a fine offset map 108, and a gain map 104.

Additionally, during the calibration procedure, a number of adjustment values are determined that are used subsequently during normal operation to dynamically adjust at least some of the calibration parameters based on changes in sensor temperature. In particular, during the calibration procedure, according to one embodiment, a TCR (temperature coefficient of resistance) value and a gain adjustment factor is determined for each detector of a sensor as a linear approximation of offset error variation and gain

- 29 -

variation, respectively. As also illustrated in Fig. 10, these adjustment values are stored respectively in a TCR map 106 and a gain adjust map 102.

An exemplary calibration procedure to obtain the calibration parameters and determine the adjustment values discussed immediately above is executed as follows, with reference to Figs. 1, 2, 3, and 10. It should be appreciated that this exemplary procedure is provided here for purposes of illustration only, and that the invention is not limited to this particular calibration procedure. Additionally, it should be appreciated that while the calibration procedure outlined below employs two offset maps (namely, a coarse offset map and a fine offset map) to store offset error calibration parameters, the invention is not limited to employing any particular number of offset and gain maps, as numerous implementations of the various concepts discussed herein relating to dynamic adjustment of sensor calibration parameters are possible.

In one exemplary calibration procedure according to the invention, based on a particular temperature range over which it is anticipated that the sensor 32 will be operated, the sensor initially is thermally stabilized at a first temperature within this range, referred to as T_{cal} . Additionally, the shutter 26 shown in Fig. 1 may be positioned so as to essentially block radiation from a scene from impinging on the sensor 32 (i.e., the controller 38 may control the shutter control signal 46 to appropriately activate the shutter and block incident radiation). Alternatively, the sensor 32 may be aimed at a standardized radiating black body at a known temperature to provide a controlled input to the sensor 32.

Once the sensor is thermally stabilized with no input (i.e., shutter closed) or a controlled input, an initial global bias current and global bias voltage is applied to the sensor (e.g., via the global offset 66 and the global detector bias 64, common to all of the detectors), and the controller 38 begins to sequentially read digitized output values from each detector of the sensor via the A/Ds 62. Typically, many of the individual detector digitized output values initially are either significantly above or below a mid-scale value of the A/Ds 62. The variation in these outputs reflects the offset error of the individual detectors at the temperature T_{cal} . The controller 38 scans the sensor a number of times, and with each scan adjusts and applies a coarse offset digital value 75 for each detector (maintained in the coarse offset map 77) to an appropriate one of the DACs 60, so to adjust the individual detector bias current such that each detector output approximates a

- 30 -

mid-scale value of the A/Ds 62. In this manner, the controller 38 executes a coarse offset calibration, or coarse "zeroing" of the sensor on an detector-by-detector basis. The final coarse offset digital values 75 that accomplishes this coarse zeroing are stored in the coarse offset map 77. This process is referred to as "coarse" offset calibration because, according to one embodiment, the number of bits employed by the DACs 60 to make adjustments to the individual detector bias currents so as to bring the respective digitized detector output signals to approximately mid-scale of the A/Ds 62 typically is less than the number of bits used by the A/Ds 62 to digitize the amplified detector output signals.

Once the coarse offset calibration is completed, typically the individual detector signals are still not quite at a mid-scale value of the A/Ds 62. Accordingly, the controller 38 repeats the scanning process at T_{cal} to compile a fine offset map 108, as shown in Fig. 10. Essentially, the controller 38 acquires several digital output samples from each detector (corrected for coarse offset) via the A/Ds 62, averages the samples, and stores this average as a calibration parameter for each detector in the fine offset map 108. During normal operation of the sensor (i.e., after the initial calibration procedure is completed), the respective fine offset values are used to make fine adjustments to the sampled digital outputs of corresponding detectors so as to further compensate for non-uniformities amongst the detectors.

Next, while the sensor temperature is still maintained at T_{cal} , the sensor 32 is aimed at a standardized black body radiating at a first known object temperature, T_{obj1} . Again, the controller 38 scans the array, applies the coarse and fine offset calibration parameters to each detector, and records the digitized output signal of each detector at T_{obj1} . Subsequently, the sensor 32 is aimed at a standardized black body radiating at a second known object temperature T_{obj2} , and the controller 38 again scans the array, applies the coarse and fine offset parameters to each detector, and records the digitized output signal of each detector at T_{obj2} . The controller 38 then calculates the gain of each detector by dividing the difference in digitized output signals of each detector at the two object temperatures by the difference in object temperatures ΔT_{obj} , and stores this calibration parameter for the detector as an entry in the gain map 104 shown in Fig. 10. During normal operation (i.e., after the initial calibration procedure is completed), this gain value is used as a calibration parameter to make adjustments to the sampled digital

- 31 -

output signals of the detector so as to further compensate for non-uniformities amongst the detectors.

At this point in the exemplary calibration procedure, the temperature T_{cal} at which the sensor is initially stabilized is changed to a new temperature, T_{cal2} , so that the controller 38 may determine the adjustment factors (i.e., TCRs and gain adjustment factors) that are ultimately used as linear approximations of offset error variation and gain variation in the embodiment of Fig. 10 to compensate (e.g., dynamically adjust) the individual calibration parameters of the fine offset map 108 and the gain map 104 based on temperature variations of the sensor. It should be appreciated that offset error and gain for a given type of detector do not necessarily vary similarly with temperature variations of the sensor; for example, with respect to bolometers, offset error variation generally is significantly more sensitive than gain variation as a function of sensor temperature. Accordingly, the choice of a particular second sensor stabilization temperature T_{cal2} for the calibration procedure may depend on the degree of accuracy desired by the linear approximations of offset error variation and gain variation for a given anticipated operating temperature range of the sensor. Notwithstanding the particular choice of T_{cal2} , the determination of the various (e.g., TCR and gain) adjustment factors may be understood conceptually as follows.

At T_{cal2} , the controller 38 repeats the procedure discussed above for obtaining fine offset values (i.e., with the shutter closed or with the sensor viewing a standardized black body radiating at a known temperature) to compile a new set of fine offset values at the sensor temperature T_{cal2} . The controller then calculates the TCR value for each detector by dividing the difference in fine offset values at T_{cal} and T_{cal2} for each detector by the temperature difference between T_{cal} and T_{cal2} , and stores the TCR values for respective detectors in the TCR map 106 shown in Fig. 10. In this embodiment, as discussed above, each TCR value may be thought of conceptually in units of $\Delta V_{off}/\Delta T_s$, where ΔV_{off} represents the difference in fine offset values for a given detector, and ΔT_s indicates the variation in sensor temperature (i.e., $|T_{cal2} - T_{cal}|$).

Similarly, at T_{cal2} , the controller 38 repeats the procedure discussed above for obtaining gain values (i.e., using two standardized black bodies radiating at different known temperatures T_{obj1} and T_{obj2}) to compile a new set of gain values at the sensor temperature T_{cal2} . The controller then calculates the gain adjustment factor for each

detector by taking the ratio of the gain values at T_{cal} and T_{cal2} , and dividing the ratio by the temperature difference between T_{cal} and T_{cal2} . This gain adjustment factor for each detector is then stored in the gain adjust map 102 shown in Fig. 10. In this embodiment, each gain adjustment factor of the gain adjust map 102 may be thought of conceptually
5 as a gain multiplier divided by $|T_{cal2} - T_{cal}|$.

Once the controller 38 has completed building the various maps discussed above, the exemplary calibration procedure is essentially completed, and thereafter the imaging system may be operated without necessarily requiring thermal stabilization of the sensor 32, according to one embodiment of the invention. In particular, according to one aspect
10 of this embodiment, the controller 38 may dynamically update the calibration parameters of the fine offset map 108 using the corresponding TCR values of the TCR map 106, and may dynamically update the calibration parameters of the gain map 104 using the corresponding gain adjustment factors of the gain adjust map 102, by evaluating temperature variations of the sensor 32 based on a variety of criteria.

For example, according to one embodiment of the invention, the controller may periodically operate the shutter 26 via a shutter controller 98 (that outputs the shutter control signal 46) to block incident radiation to the sensor 32, at which time the controller recalculates (i.e., updates) each of the calibration parameters of the fine offset map 108 by scanning the sensor, as discussed above. In one aspect of this embodiment,
15 the periodic operation of the shutter to perform this procedure may be based on a predetermined time interval. In yet another aspect, as illustrated in Fig. 10, the operation of the shutter may be based on a difference in sensor temperature from the last operation of the shutter.

More specifically, as illustrated in the embodiment of Fig. 10, the sensor temperature signal 44 output by the temperature sensor 36 shown in Fig. 1 is digitized by
25 an analog-to-digital converter 90, and the controller 38 maintains a record 94 of the digitized sensor temperature at each shutter operation. The controller 38 also may be programmed with a predetermined threshold temperature difference value 92, which may be used to activate the shutter. In particular, in the embodiment of Fig. 10, the shutter
30 comparator 96 compares the predetermined threshold temperature difference value 92 to the difference 110 (ΔT) between the present digitized sensor temperature and the record 94 of the sensor temperature at the last shutter operation; if this difference 110 exceeds

the value 92, the shutter comparator 96 activates the shutter controller 98 so as to operate the shutter 26, at which point the controller 38 updates the fine offset map 108 by scanning the sensor as discussed above. In this manner, the fine offset map 108 is periodically updated based on sensor temperature variations.

5 Between shutter operations (i.e., between updates of the fine offset map 108 by a sensor rescan), the controller 38 may nonetheless continually adjust and update both the fine offset map 108 and the gain map based on the difference between a present sensor temperature and the sensor temperature at the previous shutter operation. For example, as illustrated in Fig. 10, the temperature difference 110 between the present sensor
10 temperature and the sensor temperature at the previous shutter operation may be used to multiply individual entries of the TCR map 106, which are then used to update the individual entries in the fine offset map 108. Similarly, a signal 112 representing the difference between the present sensor temperature and the calibration temperature 100 (i.e., T_{cal}) may be used to multiply individual entries of the gain adjust map 102, which
15 are then used to update the individual entries in the gain map 104. In this manner, the frequency of shutter operations to update the fine offset map 108 by a sensor rescan may be reduced (e.g., the predetermined threshold temperature difference value 92 may be set at a higher value).

While the embodiment discussed above in connection with Fig. 10 discusses
20 updates to a fine offset map to dynamically adjust offset error calibration parameters for offset error variation, it should be appreciated that the invention is not limited in this respect. Namely, in other embodiments, compensation algorithms for dynamic adjustment of offset error calibration parameters may perform such adjustments using the coarse offset map 77 shown in Fig. 10, or both the coarse offset map 77 and the fine
25 offset map 108. Alternatively, as discussed above, compensation algorithms for dynamic adjustment of offset error calibration parameters according to other embodiments of the invention may compile, maintain, and update a single offset map based on the general concepts discussed above.

Additionally, while the embodiment discussed above in connection with Fig. 10
30 involves linear approximations of offset error variation and gain variation to dynamically adjust the calibration parameters of the fine offset map and the gain map using a TCR map and a gain adjust map, respectively, it should be appreciated that the invention is not

- 34 -

limited in this respect. Namely, the general concepts discussed above may be employed to implement compensation algorithms according to other embodiments of the invention that use interpolation of piece-wise linear approximations of offset error variation and gain variation to compensate for these variations. Moreover, the general concepts
5 discussed above may be employed to implement compensation algorithms according to other embodiments of the invention that determine and utilize offset error variation and gain variation as nonlinear functions of sensor temperature to compensate for these variations. Furthermore, it should be appreciated that according to yet other embodiments, one of a nonlinear function, interpolation of piece-wise linear
10 approximations, or a linear approximation may be employed by a compensation algorithm to compensate for offset error variation, while a different one of a nonlinear function, interpolation of piece-wise linear approximations, or a linear approximation may be employed by the compensation algorithm to compensate for gain variation.

For example, regarding nonlinear functions for offset error variation and gain
15 variation, according to one embodiment of the invention, a significant number of offset maps and gain maps may be compiled by the controller 38 (as discussed above) at a number of different sensor calibration temperatures. Essentially, each offset map and each gain map provides a "sample" of a nonlinear function of offset error variation and gain variation, respectively. Accordingly, it should be appreciated that the greater
20 number of samples acquired (i.e., the greater number of offset and gain maps compiled by the controller 38), the more accurate the sampled representation of the functions are. While in some cases the compilation of several offset and gain maps during a calibration procedure may prove to be a memory and computation intensive process, this scheme may nonetheless provide a viable and effective alternative for precision compensation of
25 offset error variation and gain variation. During normal operation following such a calibration procedure, the particular offset and gain map that the controller 38 uses at any given time to adjust the digitized output signals of respective detectors of the sensor may be selected as a function of the present sensor temperature (e.g., as measured via the sensor temperature signal 44).

30 Alternatively, another embodiment of the invention relates to dynamic compensation of calibration parameters by interpolation of piece-wise linear approximation of offset error variation and gain variation. In this embodiment, similar to

- 35 -

the nonlinear function embodiment discussed immediately above, a smaller number (e.g., two to five) of offset maps or TCR maps, as well as gain maps, may be compiled by the controller 38 at a number of different sensor calibration temperatures throughout an anticipated temperature operating range for the sensor. Using a smaller number of maps or “samples” of the respective variation functions essentially creates a piece-wise linear approximation of the functions. In particular TCR maps may be compiled at different temperature sub-ranges of an overall anticipated operating range to provide interpolations of piece-wise linear approximations of offset error variation.

In this embodiment, once such maps are compiled during a calibration procedure, they may be employed during normal operation again based on a measured present sensor temperature. For example, two gain maps and two TCR maps may be selected, wherein one of each type of map was compiled at or near a calibration temperature close to but below the present sensor temperature, and the other of each type of map was compiled at a calibration temperature close to but above the present sensor temperature. The controller 38 may then calculate the difference between corresponding entries of the two gain maps and the two TCR maps, and determine an interpolated adjustment value for each of gain and offset based on the present sensor temperature and the ΔT_{cal} between the two maps of each type (ΔT_{cal} would be “weighted” by the present sensor temperature). These interpolated adjustment values may then be applied to respective entries of each of the offset map and gain map, as discussed above.

In yet another embodiment of the present invention, with reference again to Fig. 1, thermal stabilization components (e.g., the TE cooler 28) are employed to thermally stabilize the sensor 32 selectively at various predetermined temperatures as a function of the ambient temperature in the proximity of the sensor, as indicated by the ambient temperature signal 45. Although thermal stabilization components are employed in this embodiment, power consumption of these components is nonetheless significantly reduced according to the invention by dynamically selecting one of several predetermined stabilization temperatures that is in the vicinity of the measured ambient temperature.

For example, with respect to TE coolers, the power consumption of a TE cooler generally is a function approximately of the square of the temperature difference between the ambient temperature in proximity of the TE cooler and the desired (set-point)

temperature of the TE cooler. Accordingly, power consumption of the TE cooler may be significantly reduced if the difference between the TE cooler set point and the ambient temperature is reduced. Additionally, in Fig. 1, generally the electronic signals through the sensor itself warms the sensor to some temperature above the ambient temperature in proximity of the sensor (e.g., approximately 10 to 20 degrees Celsius above ambient).
5 According to one embodiment of the invention, the foregoing factors are taken into consideration to strategically reduce power consumption of a TE cooler thermally coupled to a sensor during operation of the sensor.

In one aspect of this embodiment, a number of sensor temperature/TE cooler set-
10 points are predetermined based on an anticipated ambient temperature operating range over which the sensor will be used. For example, according to one embodiment, the ambient temperature range over which the sensor may be used is from approximately -40 degrees Celsius to +60 degrees Celsius (i.e., an approximately 100 degree Celsius range). This temperature range is then divided into a number of sub-ranges, for
15 example, three sub-ranges of approximately 30 degrees Celsius each. Within each of these sub-ranges, a sensor temperature/TE cooler set-point is chosen that approximately minimizes the power consumption of the TE cooler over the sub-range. For example, according to one embodiment, a set-point for each sub-range is chosen by taking the center temperature within the range and adding approximately 10 degrees to it (to
20 account for electronic signal "warm-up" of the sensor).

Once the TE cooler set-points are identified (i.e., in the above example, three predetermined set-points are chosen), various operating and calibration parameters associated with the sensor initially are measured or determined during a calibration procedure (e.g., as discussed above), wherein each of the predetermined TE cooler set-
25 points serves as a different calibration temperature. For example, in the above scenario using three predetermined set-points, during a calibration procedure one offset map and one gain map would be compiled at each set-point, for a total of three offset maps and three gain maps. Additionally, at each TE cooler set-point, an optimum global offset (detector bias current), global detector bias (detector bias voltage), and self-heating
30 compensation waveform may be determined.

According to one aspect of this embodiment, during subsequent operation of the sensor after such a calibration procedure, the controller 38 continuously monitors the

- 37 -

ambient temperature, and selects one of the TE cooler set-points that will significantly reduce power consumption of the TE cooler based on the difference between the ambient temperature and the selected set-point. Fig. 11 is a diagram of a portion of the controller 38, showing various components of a temperature stabilization feedback loop according to one embodiment of the invention. In Fig. 11, a set-point select controller 152 monitors the ambient temperature signal 45, and outputs the selected set-point 150 based on the available set-points and the monitored ambient temperature. An amplifier/comparator 156 compares the selected set-point 150 to the present sensor temperature 44 to produce an error signal 158 for the temperature stabilization feedback loop. This error signal 158 is further processed by various conditioning circuitry 160 that provides loop filtering and gain and outputs the temperature control signal 48 to the TE cooler.

In Fig. 11, the set-point select controller 152 also provides the selected set-point 150 to a calibration parameter select controller 154, which then selects the appropriate offset and gain maps (shown in Fig. 11 in the map table with entries OM1, OM2, OM3, GM1, GM2, GM3, etc.) to be used by the controller 38 as calibration parameters. While not shown explicitly in Fig. 11, according to one embodiment, the calibration parameter select controller 154 also may indicate or select the appropriate operating parameters (e.g. bias current and voltage and self-heating compensation waveform) that the controller 38 applies to the sensor at respective TE cooler set-points.

In accordance with the invention, feedback temperature control may be provided in response to any combination of one or more of sensor temperature monitor 44, ambient temperature monitor 45, and a subset of or all of the digital image signals 40.

Compensation of the sensor can be provided in response to any combination of a temperature variation of the sensor, a change in the ambient temperature of the environment (but not the chip), and a change in the digital output of the sensor (but not in the chip). This compensation can be provided continuously, only when the shutter is being calibrated, or only when the shutter is not being calibrated.

Having thus described at least one illustrative embodiment of the invention, various alterations, modifications, and improvements will readily occur to those skilled in the art. Such alterations, modifications, and improvements are intended to be part of this disclosure, and are intended to be within the spirit and scope of the invention.

- 38 -

Accordingly, the foregoing description is by way of example only and is limited only as defined in the following claims and the equivalents thereto.

What is claimed is:

CLAIMS

1. A method of compensating a radiation sensor for changes in at least one
5 operational characteristic of the sensor due to a temperature variation of the sensor,
comprising an act of:

dynamically adjusting at least one of at least one operating parameter associated
with the radiation sensor and at least one calibration parameter associated with the
radiation sensor based on the temperature variation of the sensor.

10

2. The method of claim 1, wherein the at least one operational characteristic
of the sensor that changes due to the temperature variation of the sensor includes a
resistance of the sensor.

15

3. The method of claim 1, wherein the at least one operating parameter
associated with the sensor includes at least one of a DC bias voltage applied to the
sensor, a DC bias current applied to the sensor, and an AC bias waveform applied to the
sensor.

20

4. The method of claim 1, wherein the sensor includes a plurality of
radiation detectors, and wherein the at least one calibration parameter associated with the
sensor includes at least one of an offset error value for each radiation detector and a gain
value for each radiation detector.

25

5. The method of claim 4, wherein the at least one operational characteristic
of the sensor that changes due to the temperature variation of the sensor includes at least
one of an offset error variation and a gain variation.

30

6. An apparatus, comprising:
a controller to compensate a radiation sensor for changes in at least one
operational characteristic of the sensor due to a temperature variation of the sensor, the
controller dynamically adjusting at least one of at least one operating parameter

- 40 -

associated with the radiation sensor and at least one calibration parameter associated with the radiation sensor based on the temperature variation of the sensor.

7. The apparatus of claim 6, wherein the at least one operational
5 characteristic of the sensor that changes due to the temperature variation of the sensor includes a resistance of the sensor.

8. The apparatus of claim 6, wherein the at least one operating parameter
includes at least one of a DC bias voltage applied to the sensor, a DC bias current applied
10 to the sensor, and an AC bias waveform applied to the sensor.

9. The apparatus of claim 6, wherein the sensor includes a plurality of
radiation detectors, and wherein the at least one calibration parameter associated with the
sensor includes at least one of an offset error value for each radiation detector and a gain
15 value for each radiation detector.

10. The apparatus of claim 9, wherein the at least one operational
characteristic of the sensor that changes due to the temperature variation of the sensor
includes at least one of an offset error variation and a gain variation.

20

11. A method of compensating a radiation sensor for changes in at least one
operational characteristic of the sensor due to a temperature variation of
the sensor, comprising:

dynamically adjusting at least one operating parameter associated with the
25 radiation sensor or at least one calibration parameter associated with the radiation sensor
based on the temperature variation of the sensor.

12. An apparatus, comprising:

a controller to compensate a radiation sensor for changes in at least one
30 operational characteristic of the sensor due to a temperature variation of the sensor, the
controller dynamically adjusting at least one operating parameter associated with the

- 41 -

radiation sensor or at least one calibration parameter associated with the radiation sensor based on the temperature variation of the sensor.

1/11

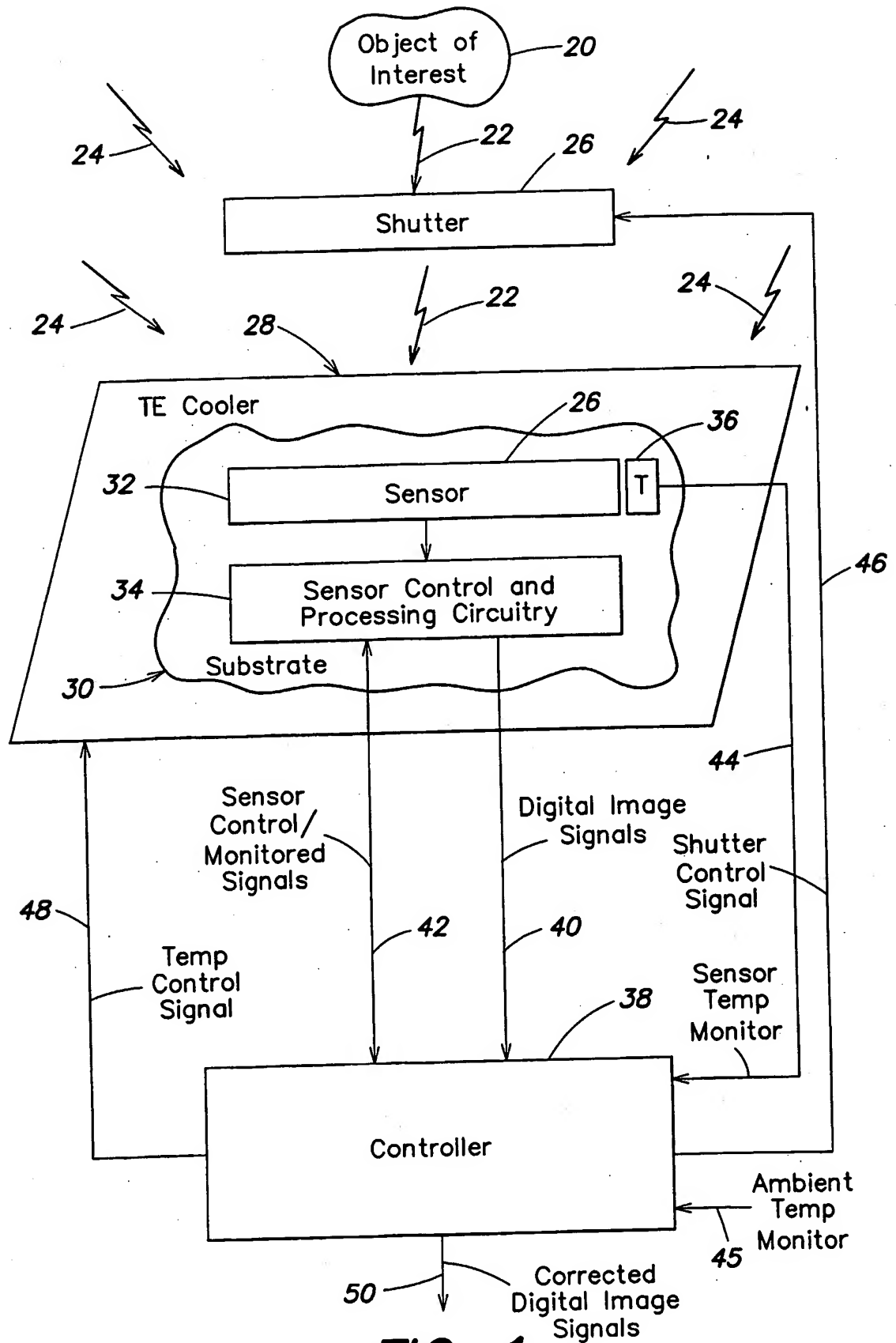


FIG. 1 Signals
SUBSTITUTE SHEET (RULE 26)

SUBSTITUTE SHEET (RULE 26)

2/11

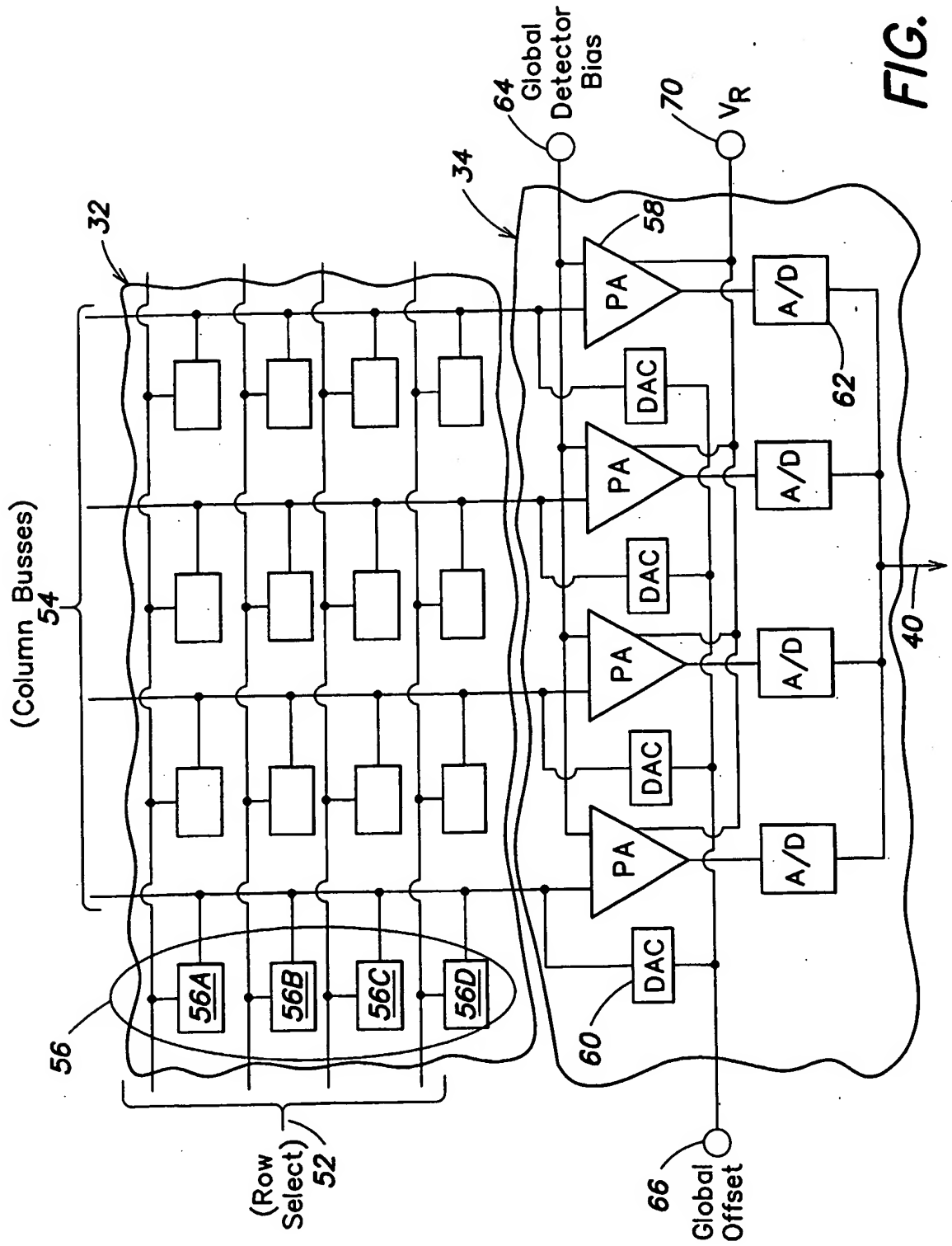


FIG. 2

SUBSTITUTE SHEET (RULE 26)

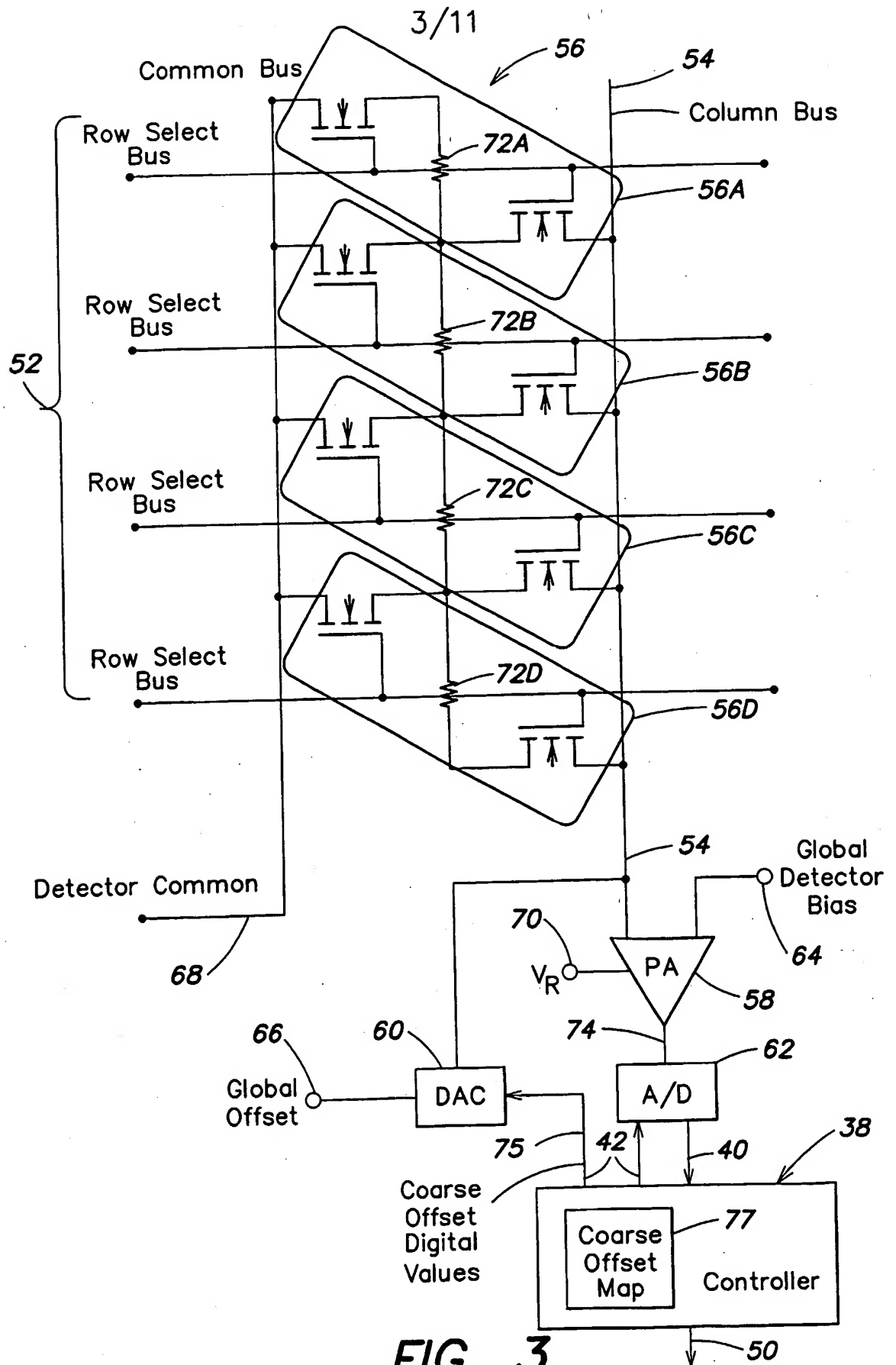


FIG. 3
SUBSTITUTE SHEET (RULE 26)

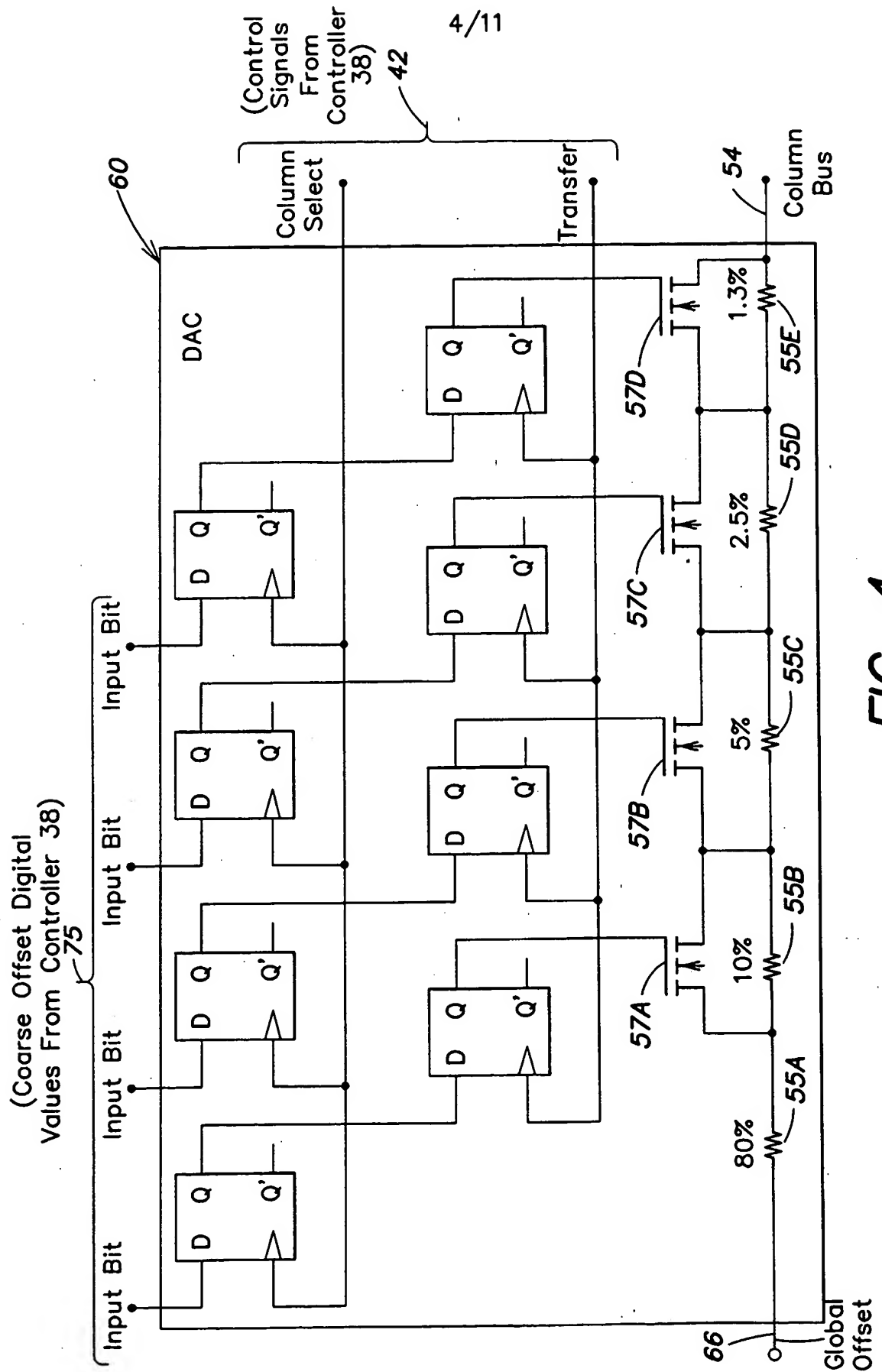
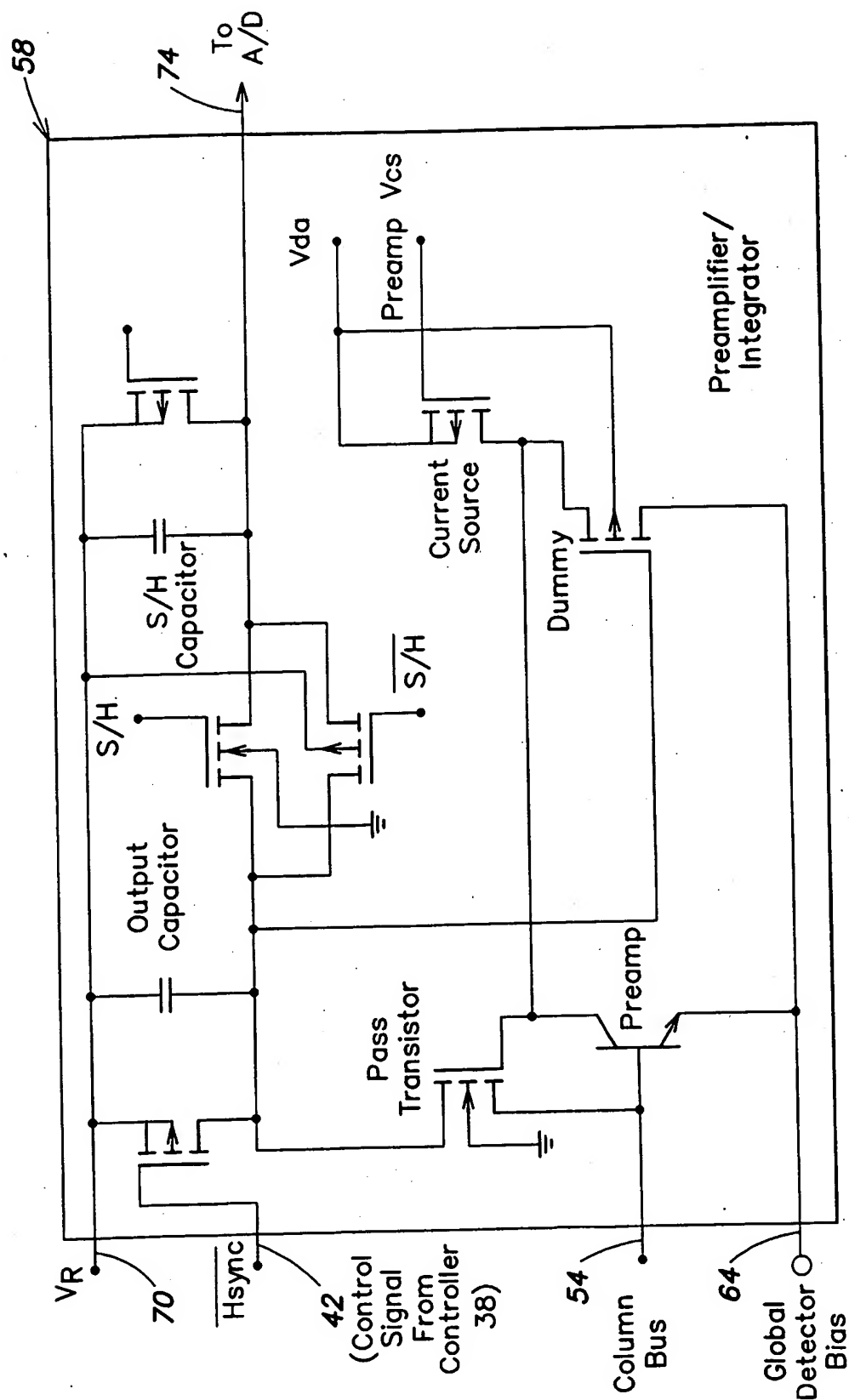


FIG. 4

SUBSTITUTE SHEET (RULE 26)

5/11



SUBSTITUTE SHEET (RULE 26)

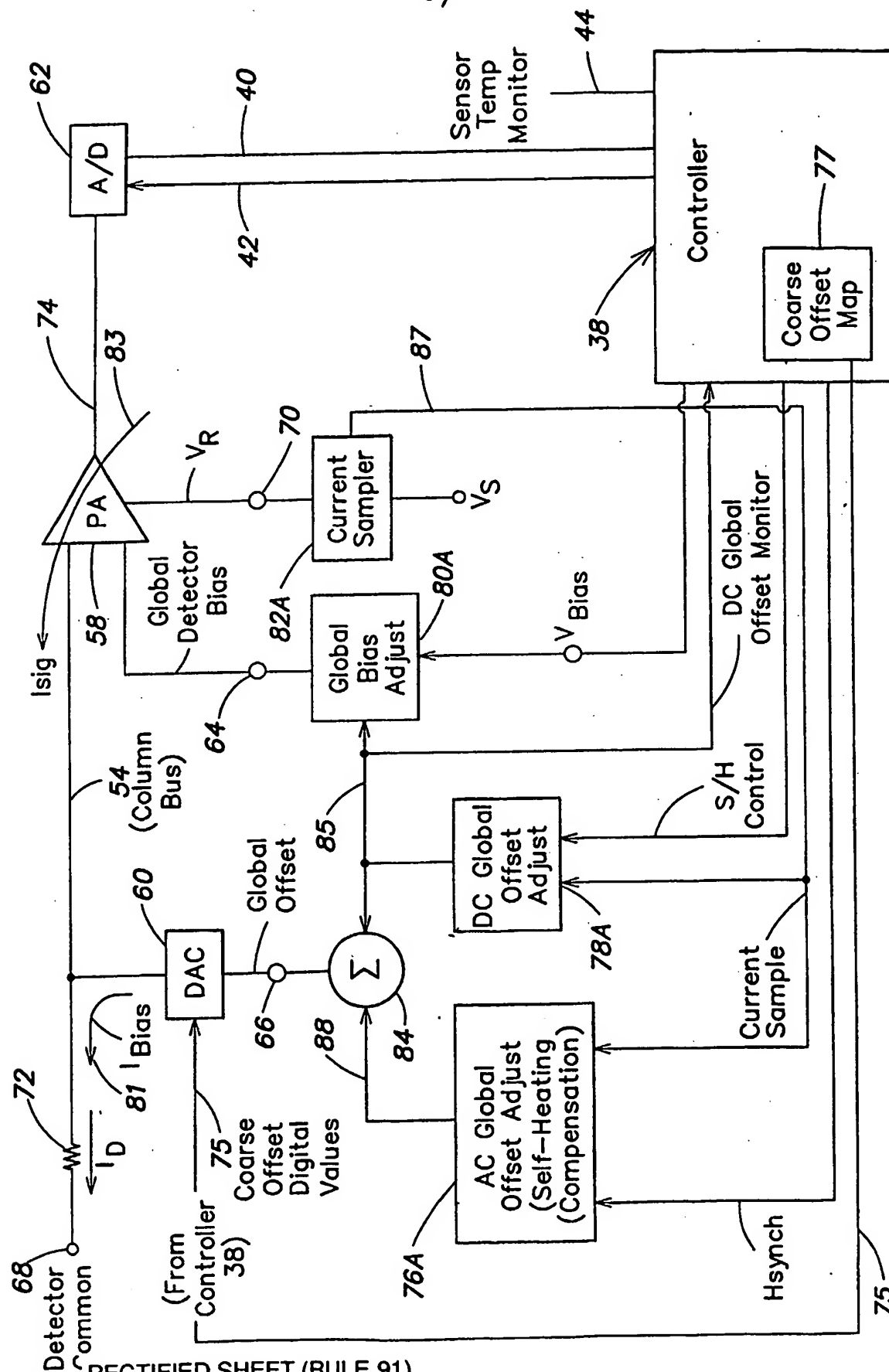


FIG. 6

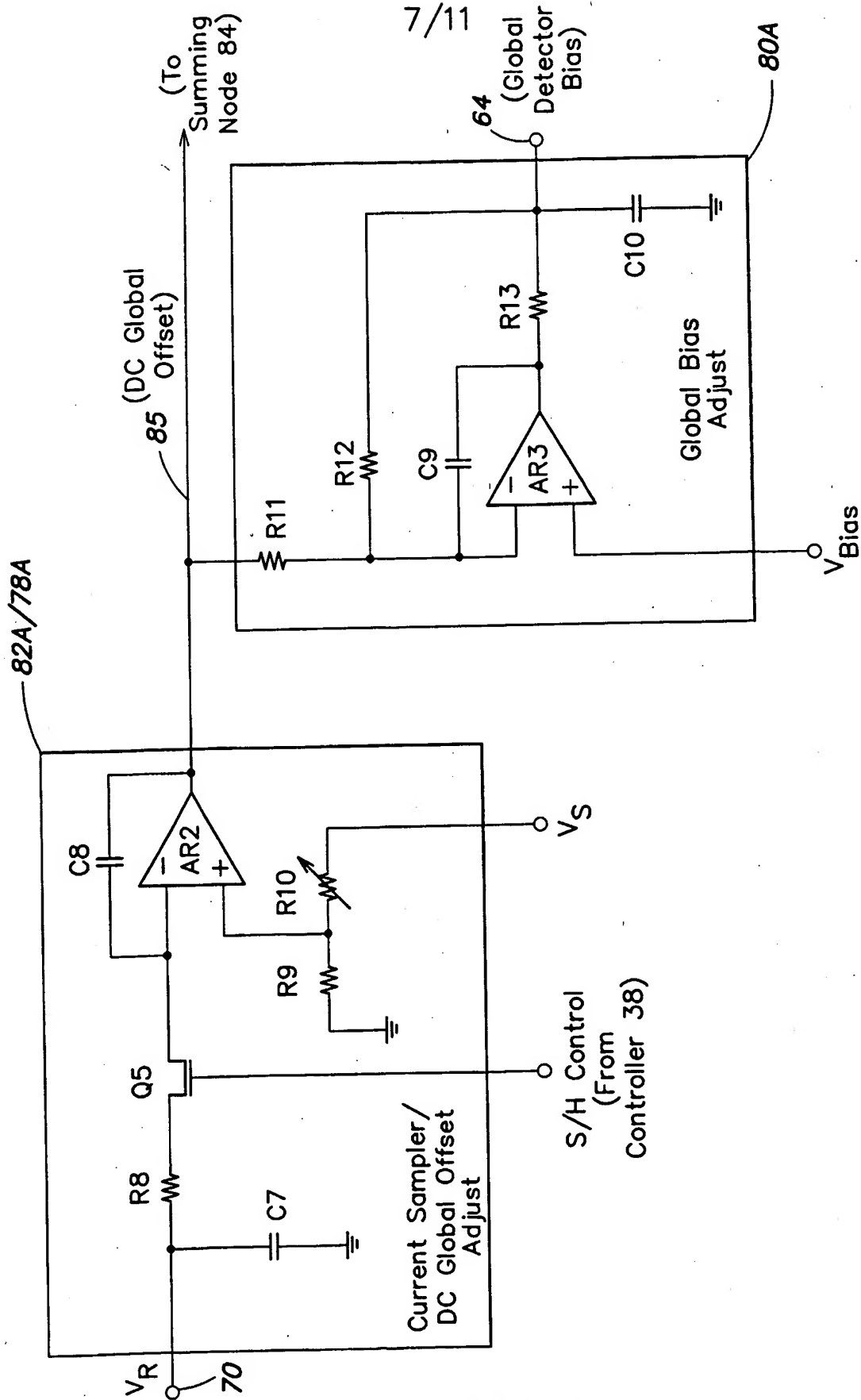


FIG. 7

SUBSTITUTE SHEET (RULE 26)

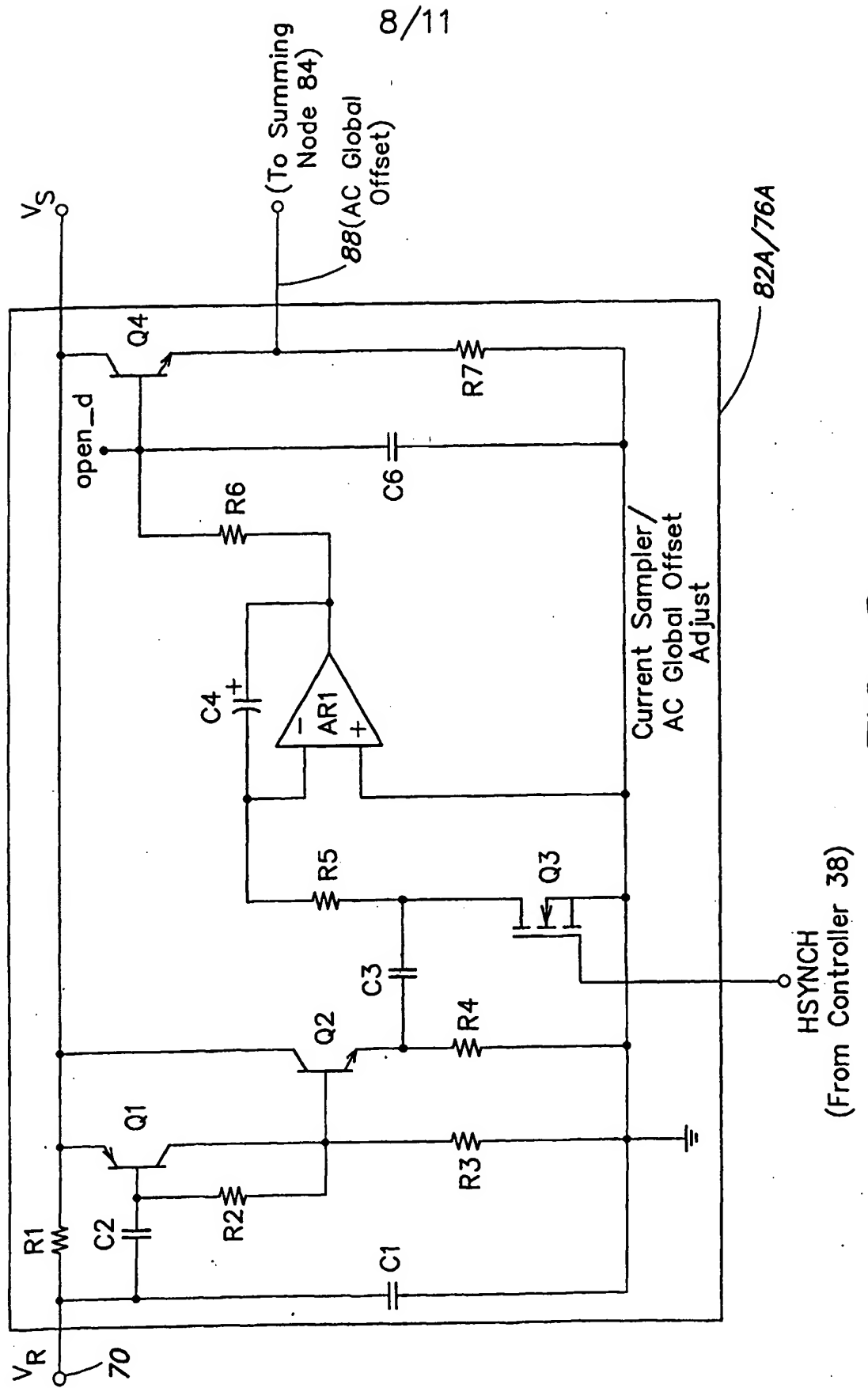


FIG. 8

RECTIFIED SHEET (RULE 91)

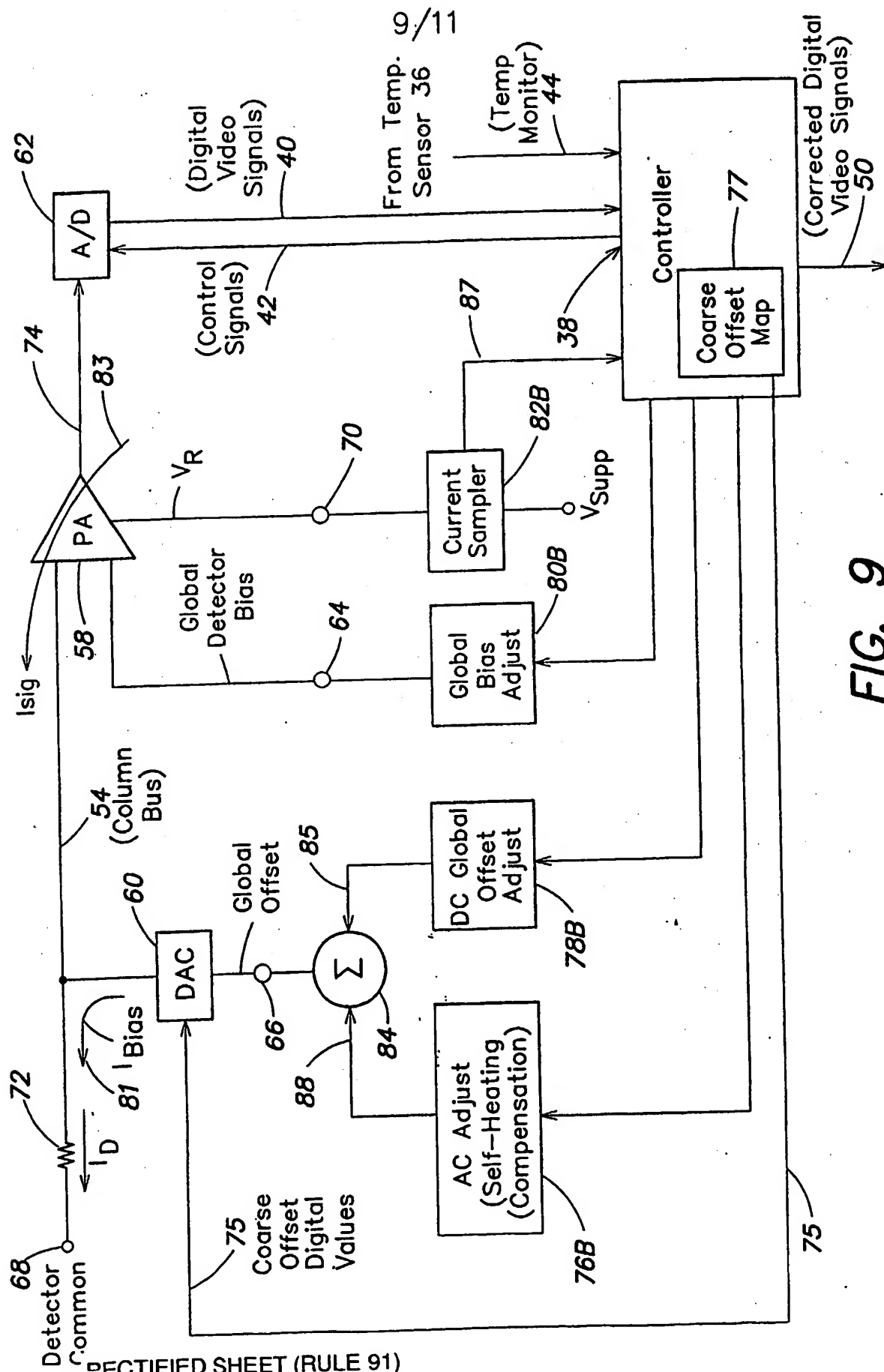


FIG. 9

10/11

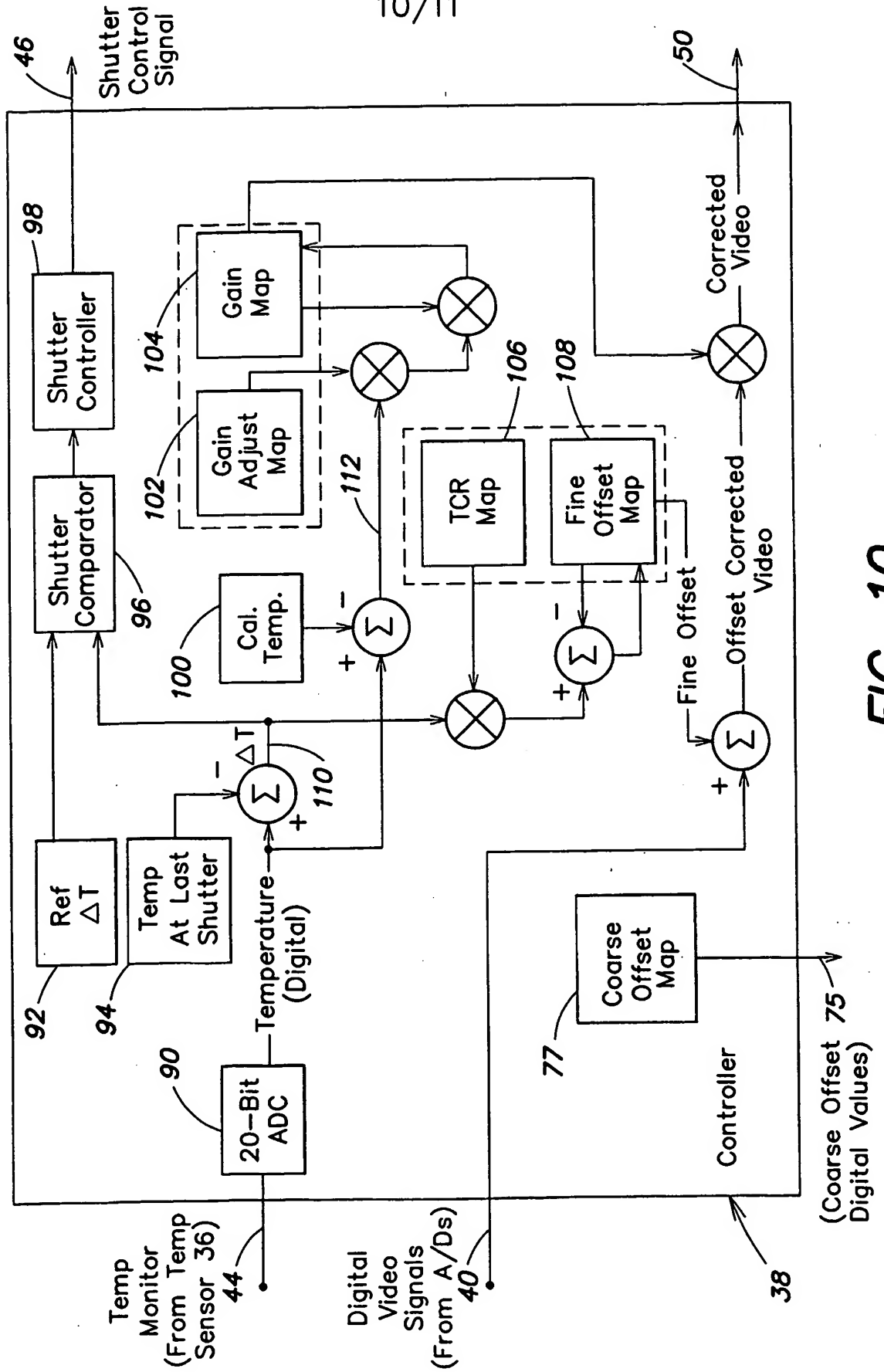


FIG. 10

11/11

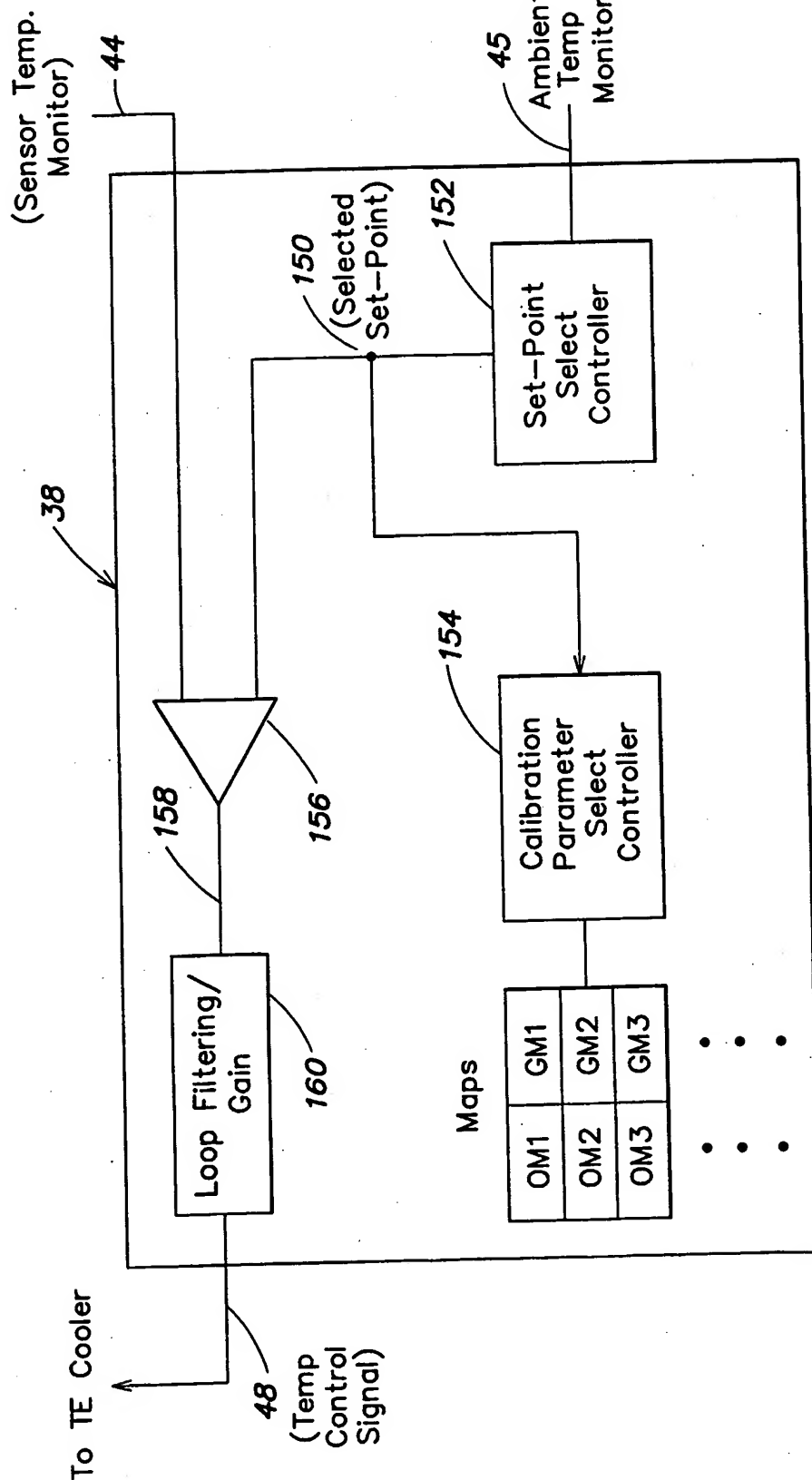


FIG. 11

INTERNATIONAL SEARCH REPORT

International Application No.

PCT/US 01/13612

A. CLASSIFICATION OF SUBJECT MATTER
IPC 7 G01J5/20

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHEDMinimum documentation searched (classification system followed by classification symbols)
IPC 7 G01J

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

EPO-Internal

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X A X	WO 98 35212 A (INDIGO SYSTEMS CORP) 13 August 1998 (1998-08-13) page 16, line 2 - page 19, line 16; figures page 18, line 25 - line 27 page 18, line 28 - line 31 -----	1,4-6, 9-12 3,8 2,7

☐ Further documents are listed in the continuation of box C.☒ Patent family members are listed in annex.

* Special categories of cited documents:

- *A* document defining the general state of the art which is not considered to be of particular relevance
- *E* earlier document but published on or after the international filing date
- *L* document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)
- *O* document referring to an oral disclosure, use, exhibition or other means
- *P* document published prior to the international filing date but later than the priority date claimed

- *T* later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention
- *X* document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone
- *Y* document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art.
- *G* document member of the same patent family

Date of the actual completion of the international search

21 December 2001

Date of mailing of the international search report

07/01/2002

Name and mailing address of the ISA

European Patent Office, P.B. 5818 Patentlaan 2
NL - 2280 HV Rijswijk
Tel. (+31-70) 340-2040, Tx. 31 651 epo nl,
Fax: (+31-70) 340-3016

Authorized officer

Ramboer, P

INTERNATIONAL SEARCH REPORT

Information on patent family members

International Application No
PCT/US 01/13612

Patent document cited in search report		Publication date		Patent family member(s)	Publication date
WO 9835212	A	13-08-1998	US	5756999 A	26-05-1998
			US	6028309 A	22-02-2000
			AU	6263498 A	26-08-1998
			EP	1007920 A1	14-06-2000
			WO	9835212 A1	13-08-1998

Form PCT/ISA/210 (patent family annex) (July 1992)